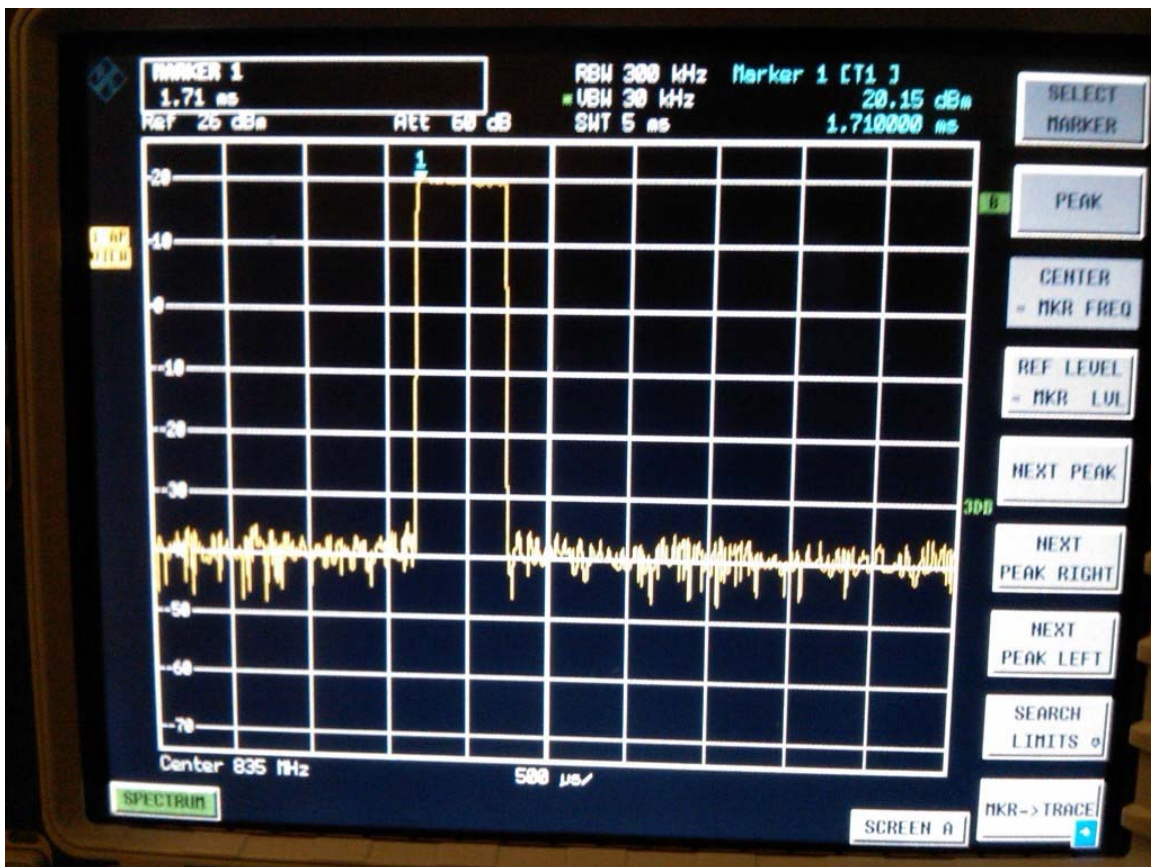

	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>1 (187)</b>
	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A RTS-2580-1106-36</b>

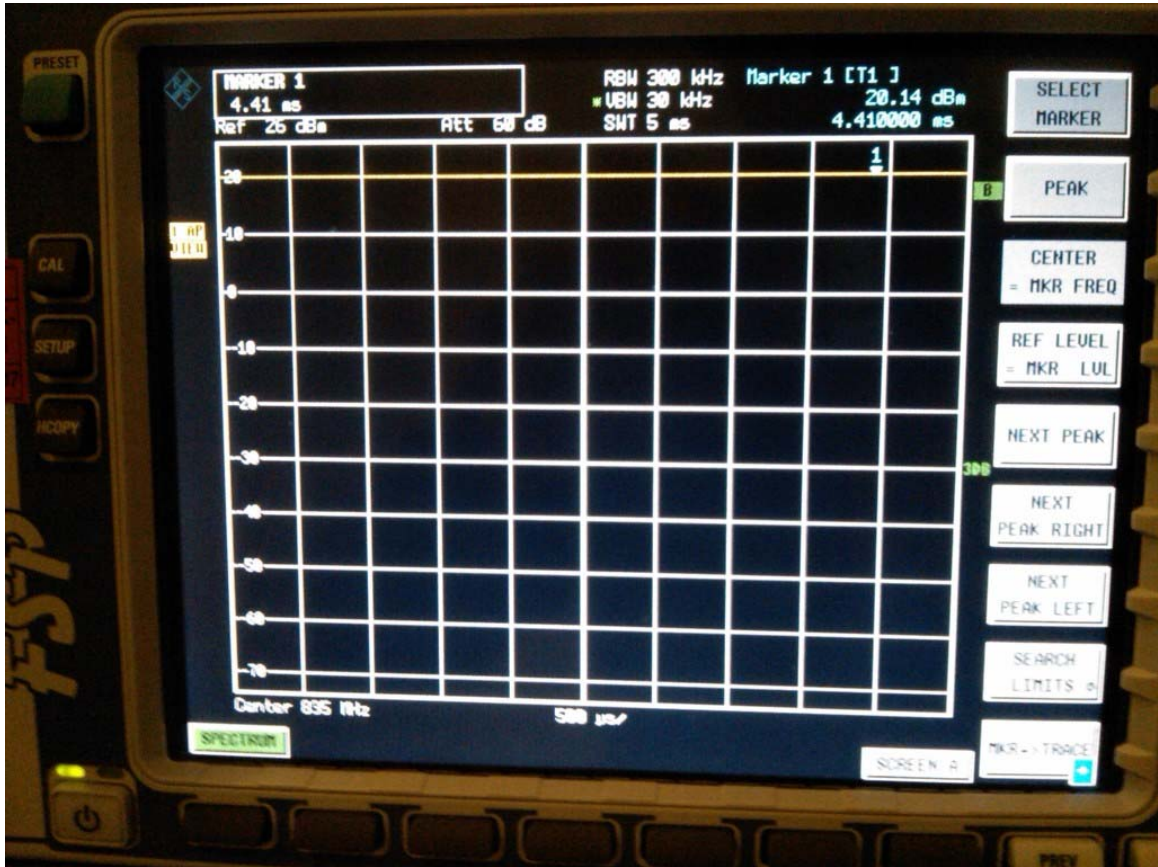
## Annex A: Measurement data and plots

### A.1 Spectrum analyser plots: GSM/CDMA/UMTS, CW, 80%AM, signals




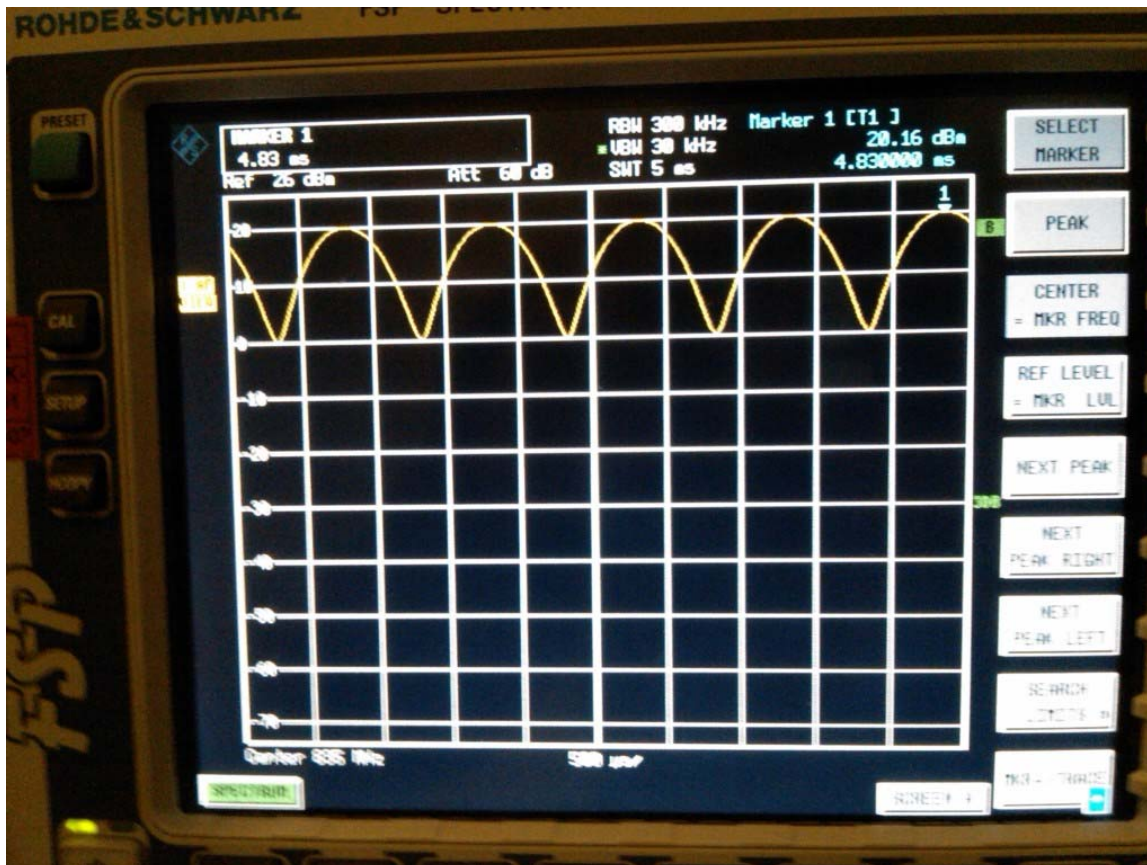
GSM 835 MHz

	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>2 (187)</b>
	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A RTS-2580-1106-36</b>




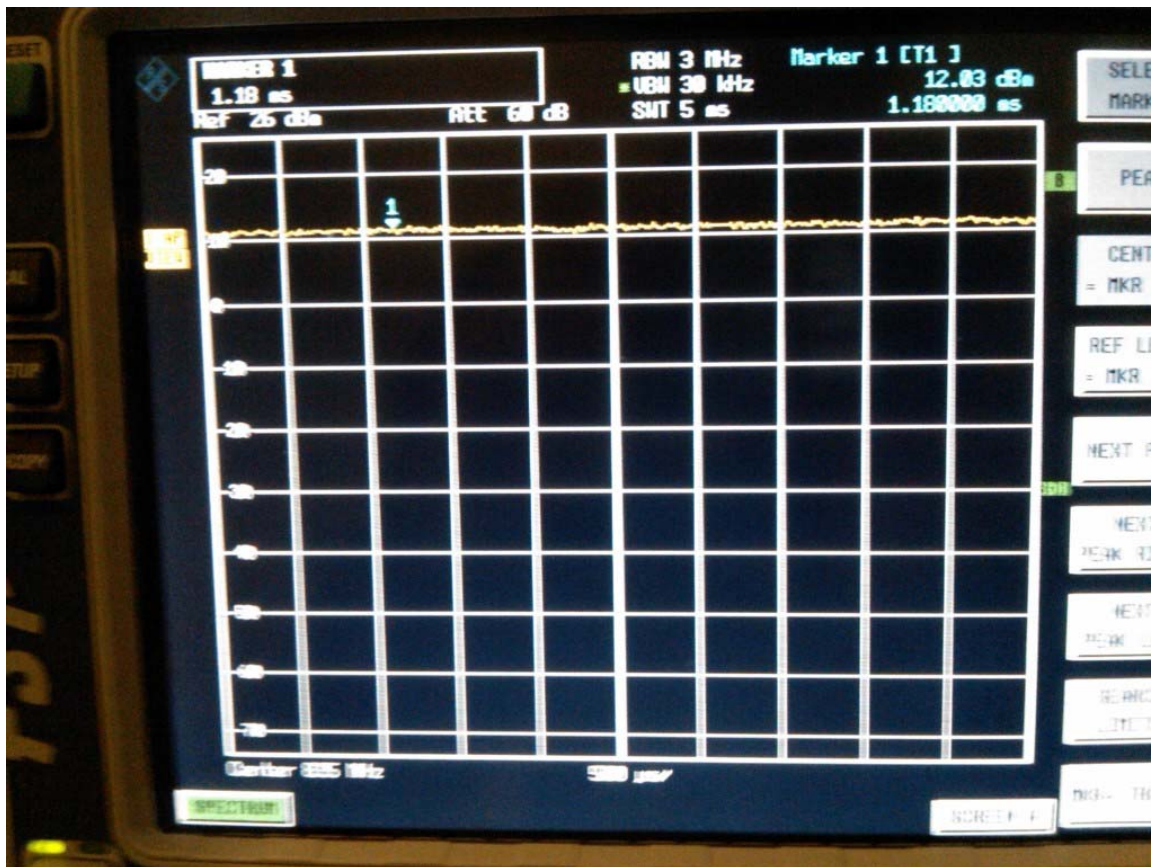
CW 835 MHz

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	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A RTS-2580-1106-36</b>




AM 80% 835 MHz

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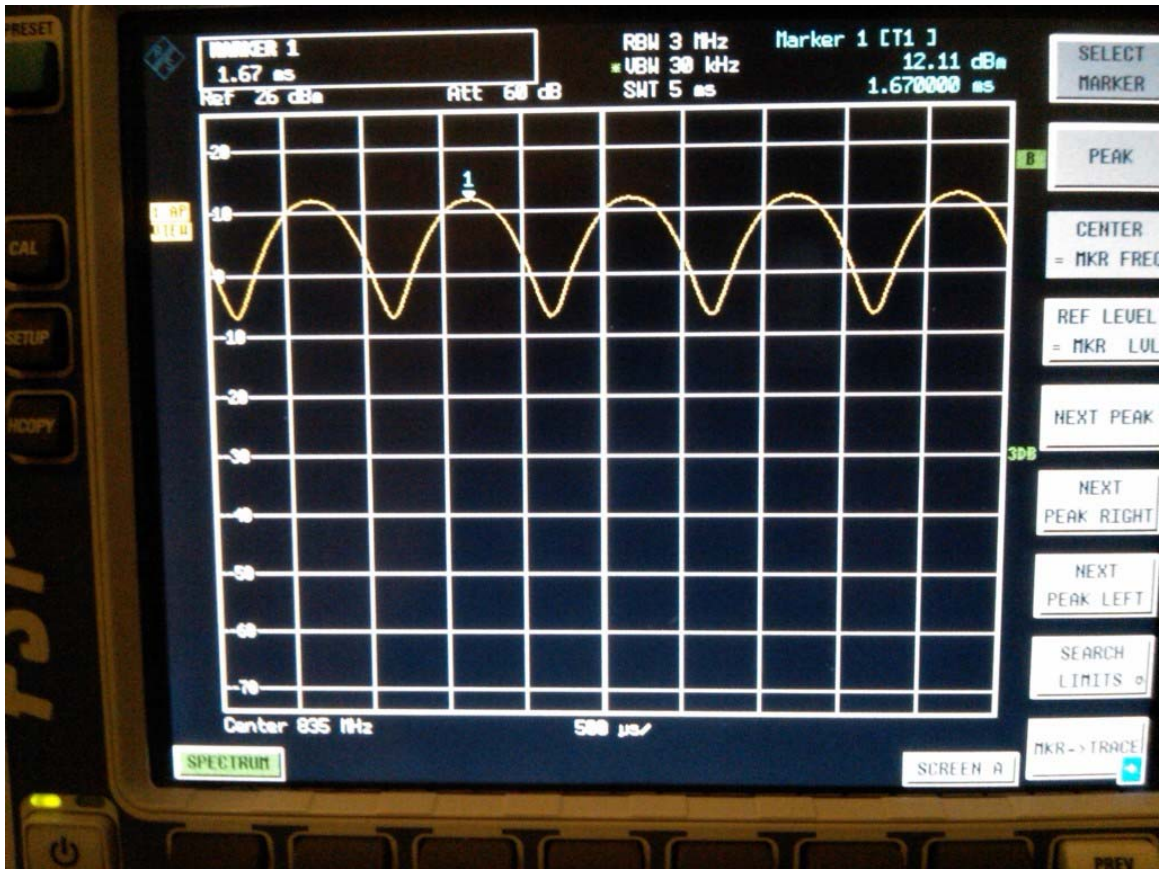
CDMA 835 MHz

	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>5 (187)</b>
	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A RTS-2580-1106-36</b>




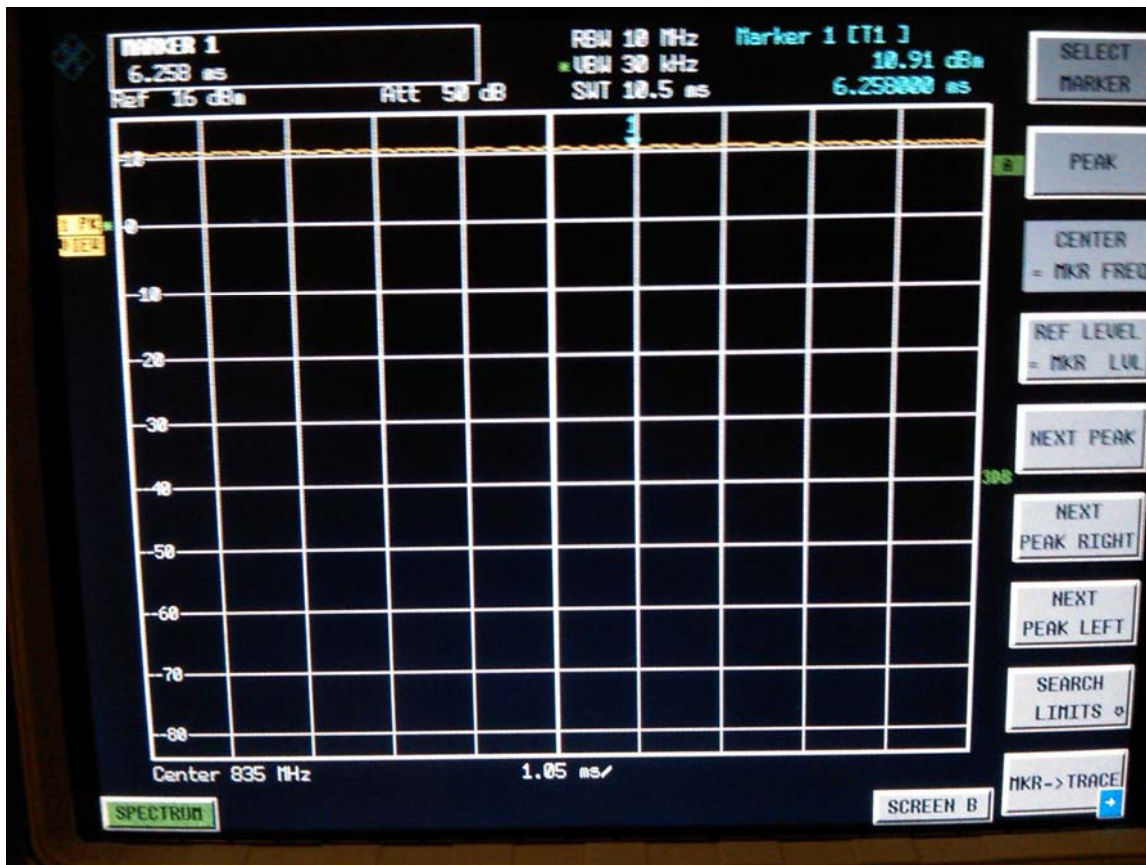
CW 835 MHz

	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>6 (187)</b>
	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A RTS-2580-1106-36</b>




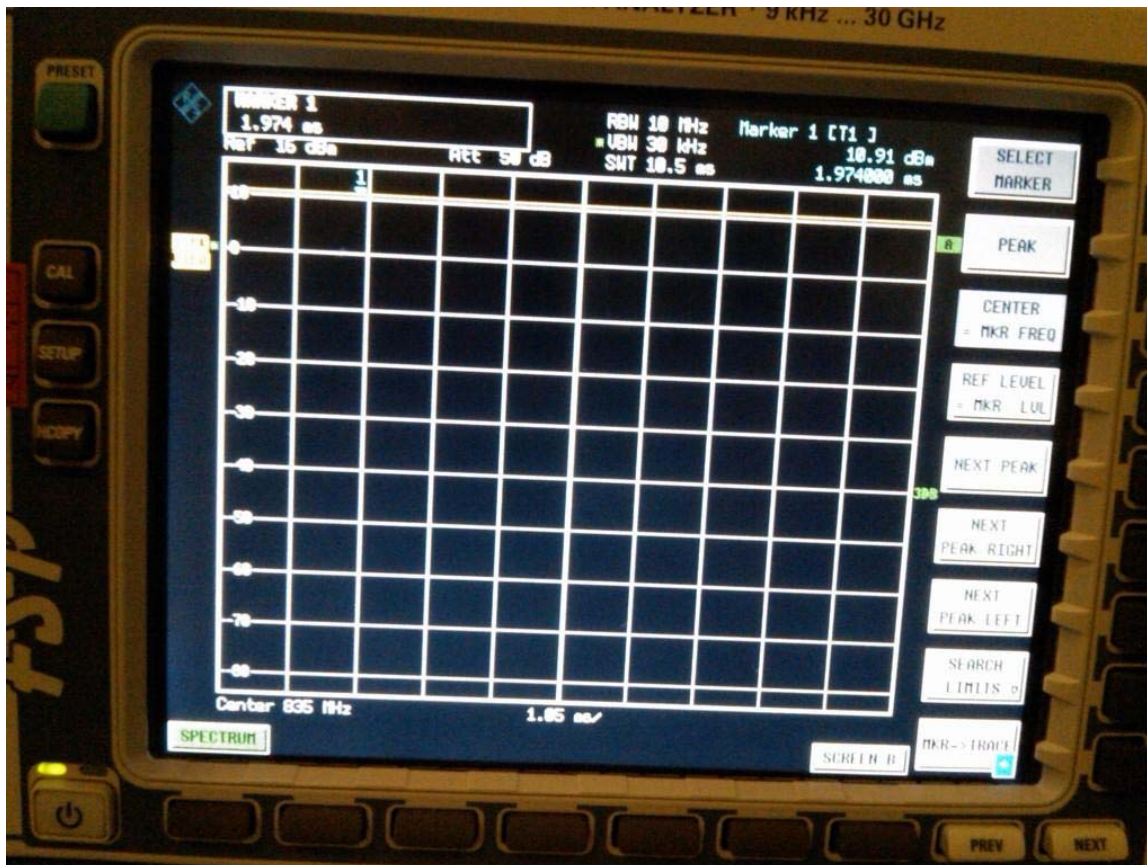
**AM 80% 835 MHz**

	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>7 (187)</b>
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UMTS 835 MHz

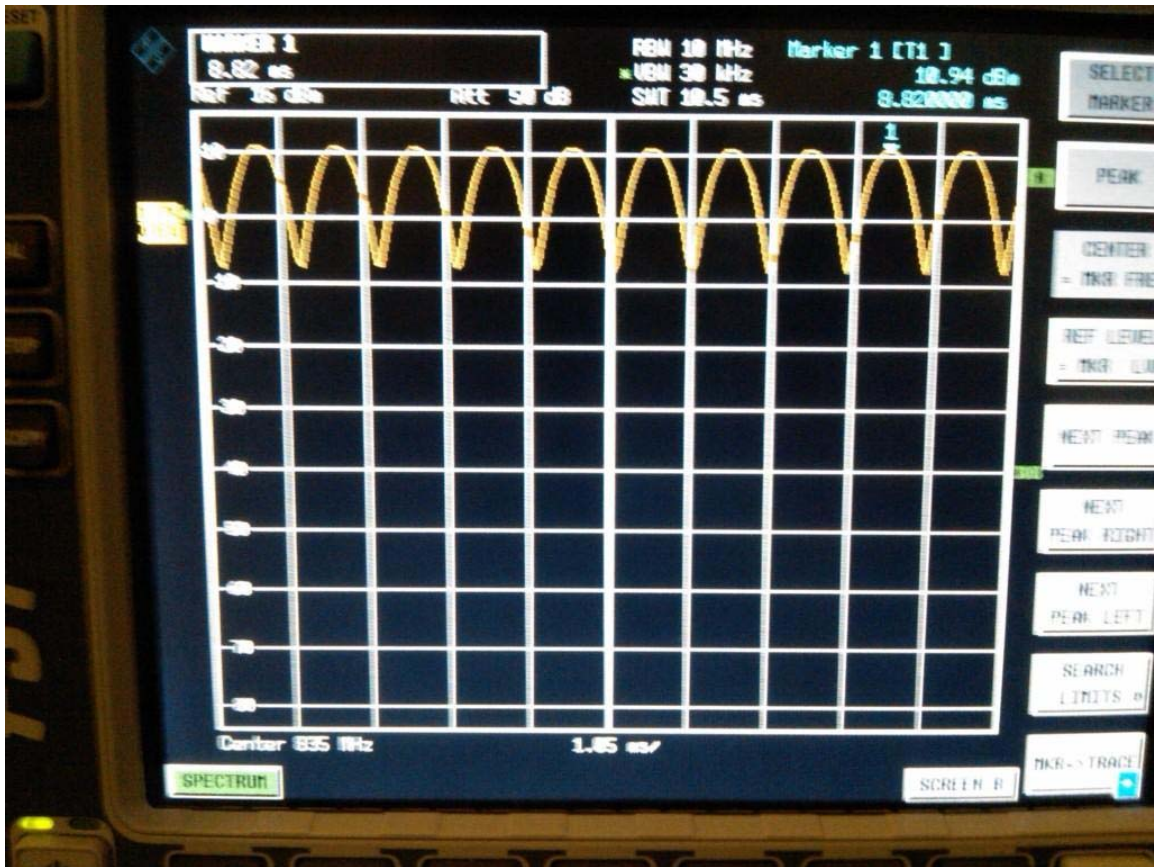
	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>8 (187)</b>
	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A RTS-2580-1106-36</b>




CW 835 MHz

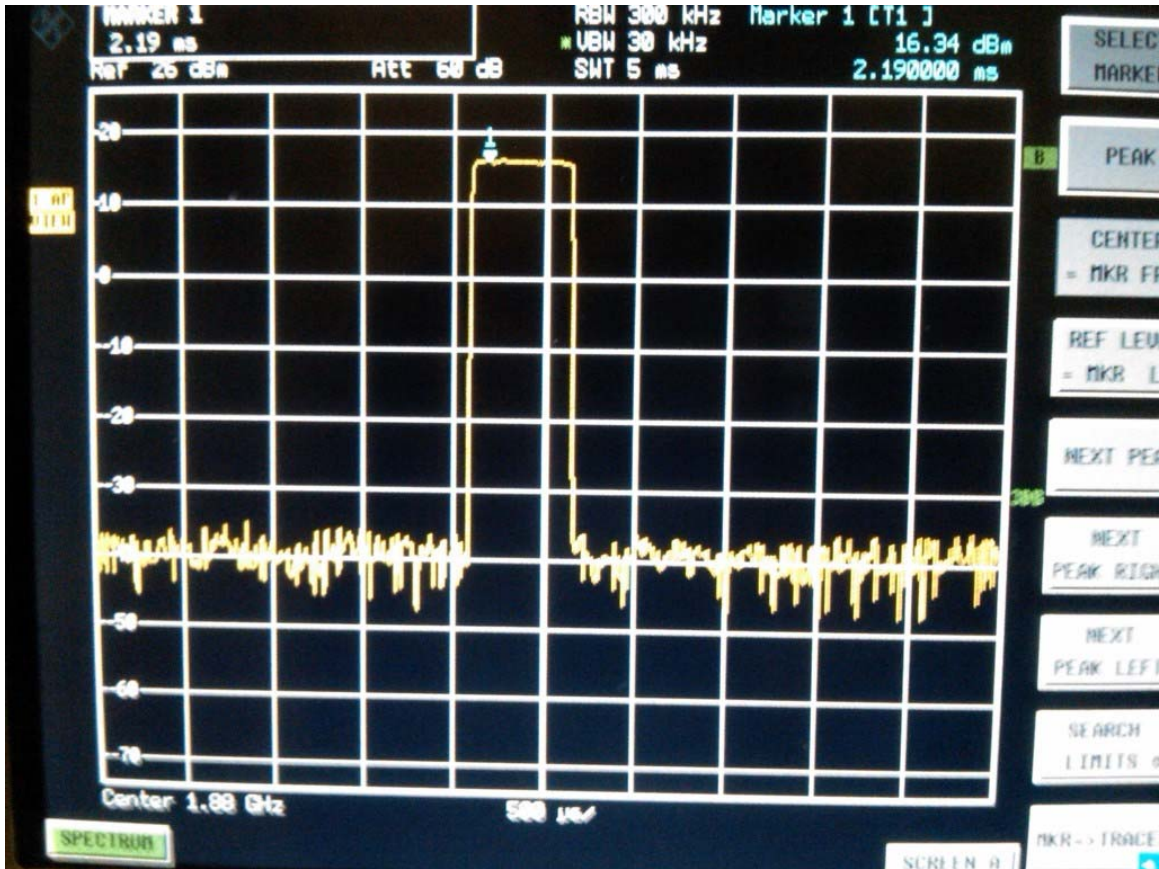


	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>9 (187)</b>
	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A RTS-2580-1106-36</b>



**AM 80% 835 MHz**

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**GSM 1880 MHz**



Document  
**Annex A to Hearing Aid Compatibility RF Emissions Test  
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RDU71CW/RDE71UW**

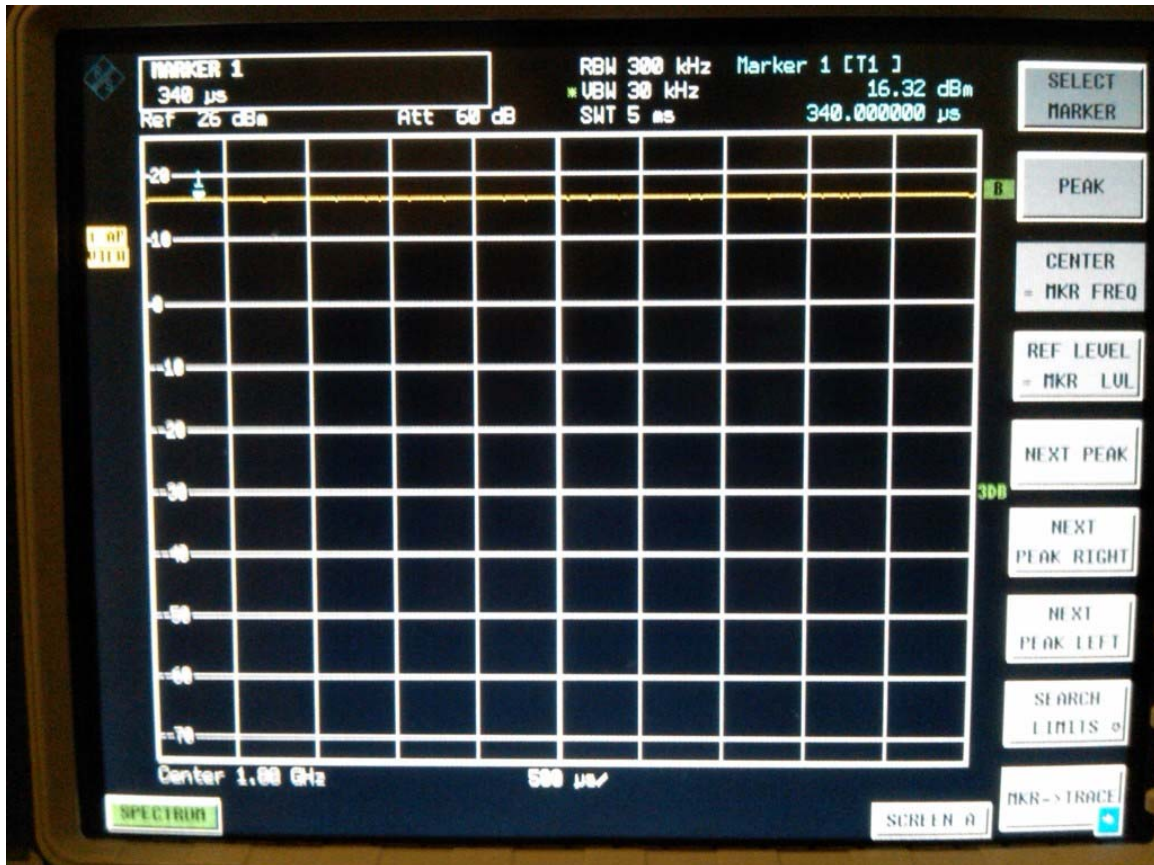
Page  
**11 (187)**

Author Data  
**Daoud Attayi**


Dates of Test  
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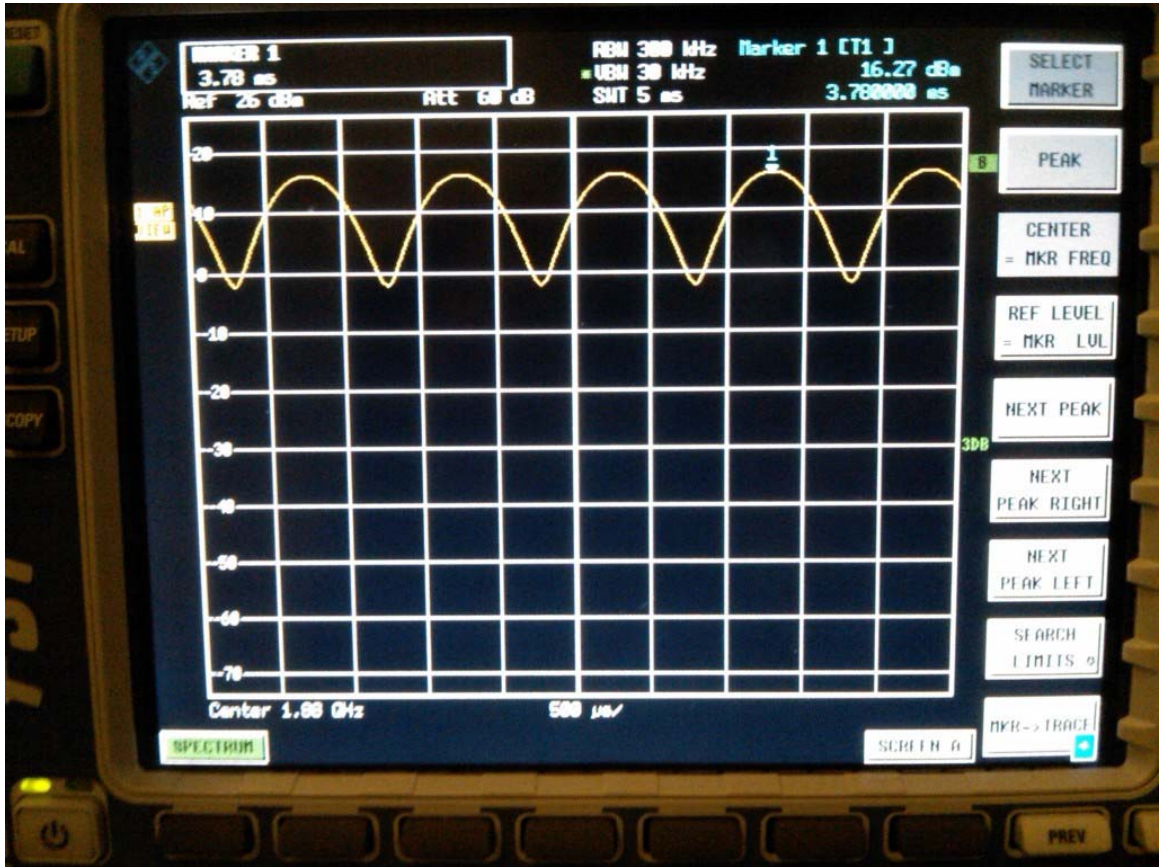
Report No  
**RTS-3933-1104-55A  
RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
L6ARDE70UW**




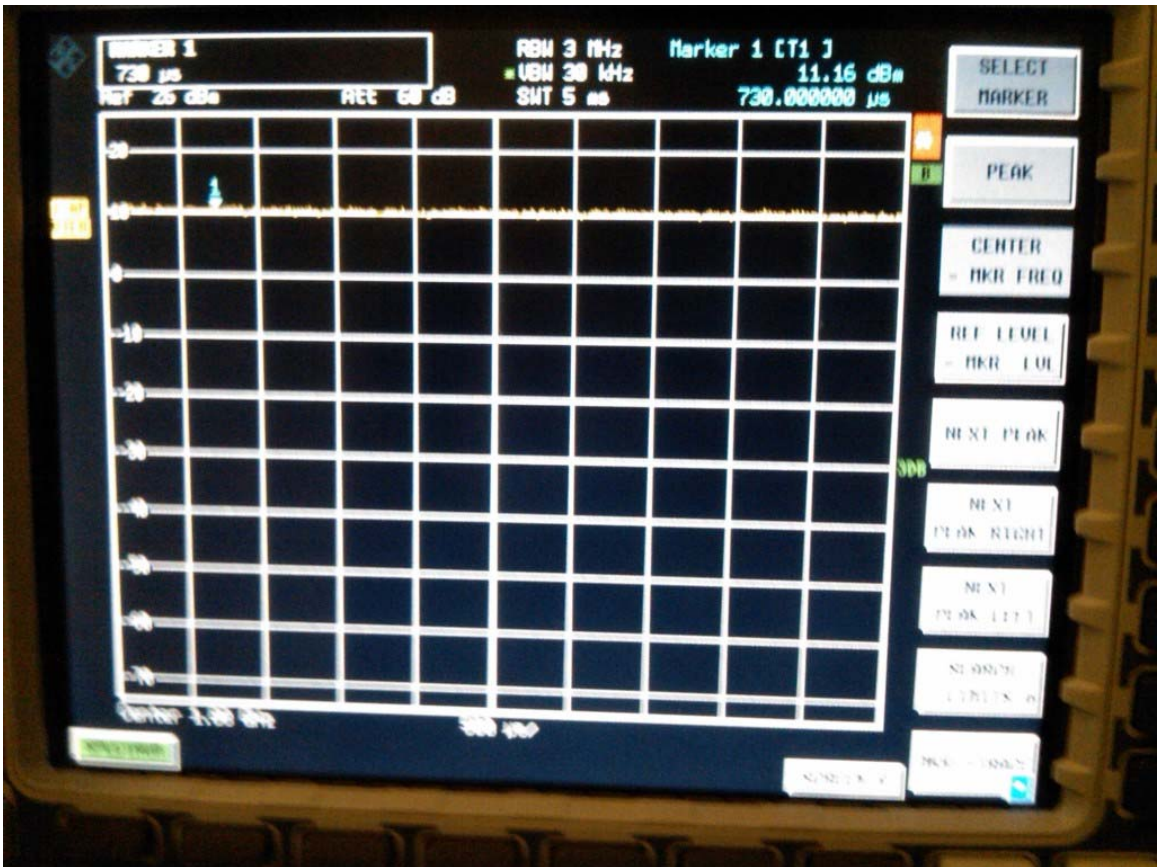
**CW 1880 MHz**

	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>12 (187)</b>
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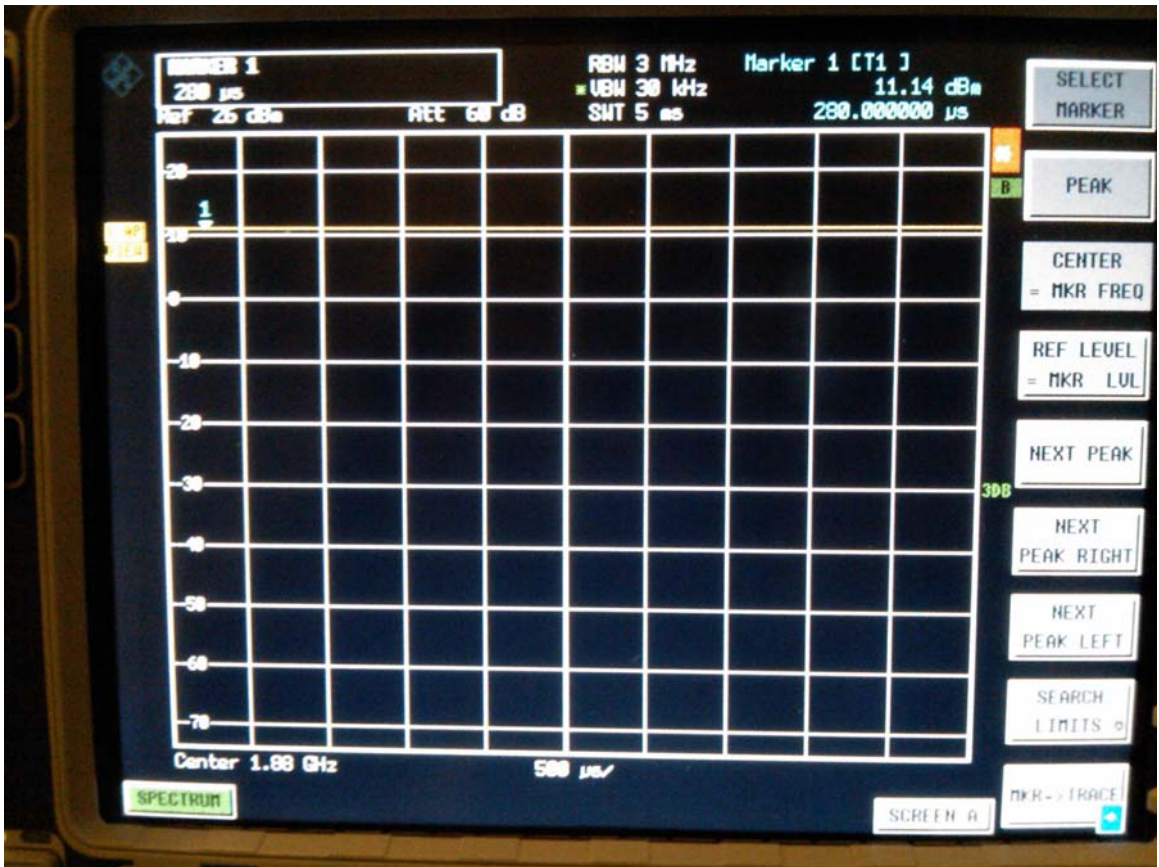
**AM 80 % 1880 MHz**

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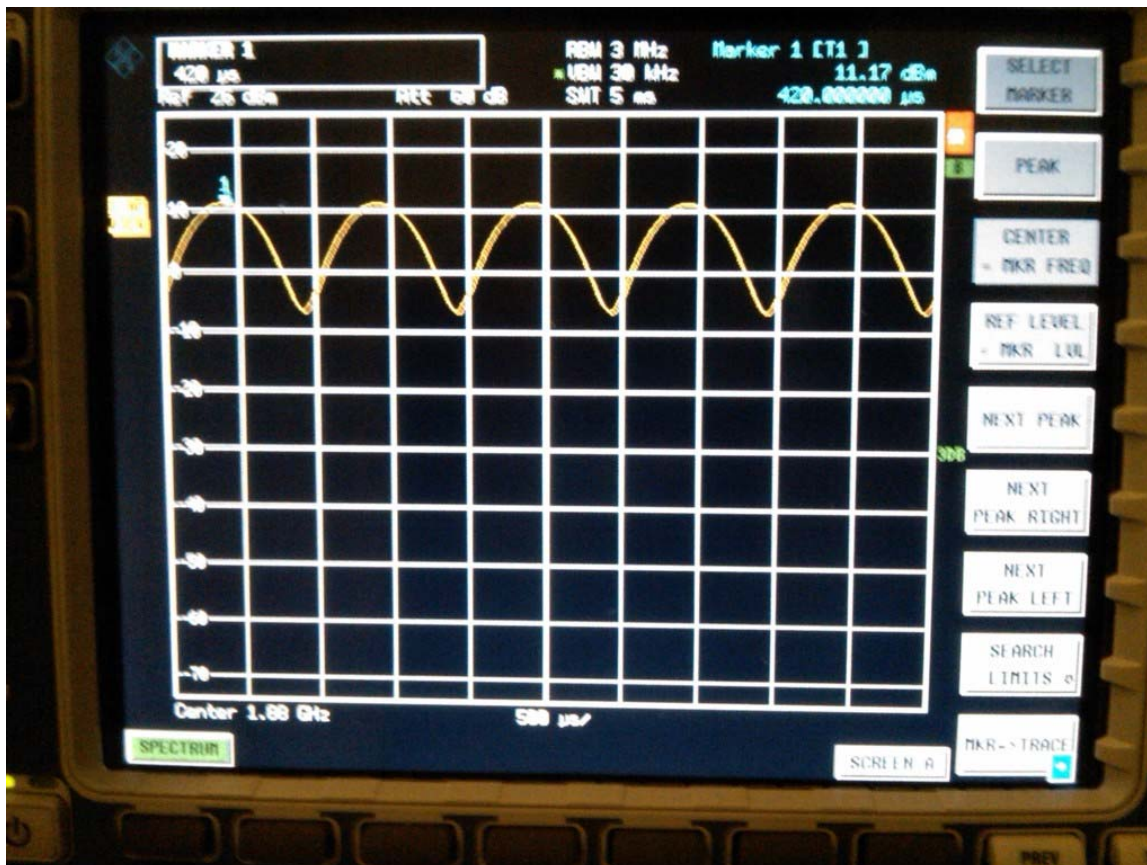
CDMA 1880 MHz

	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>14 (187)</b>
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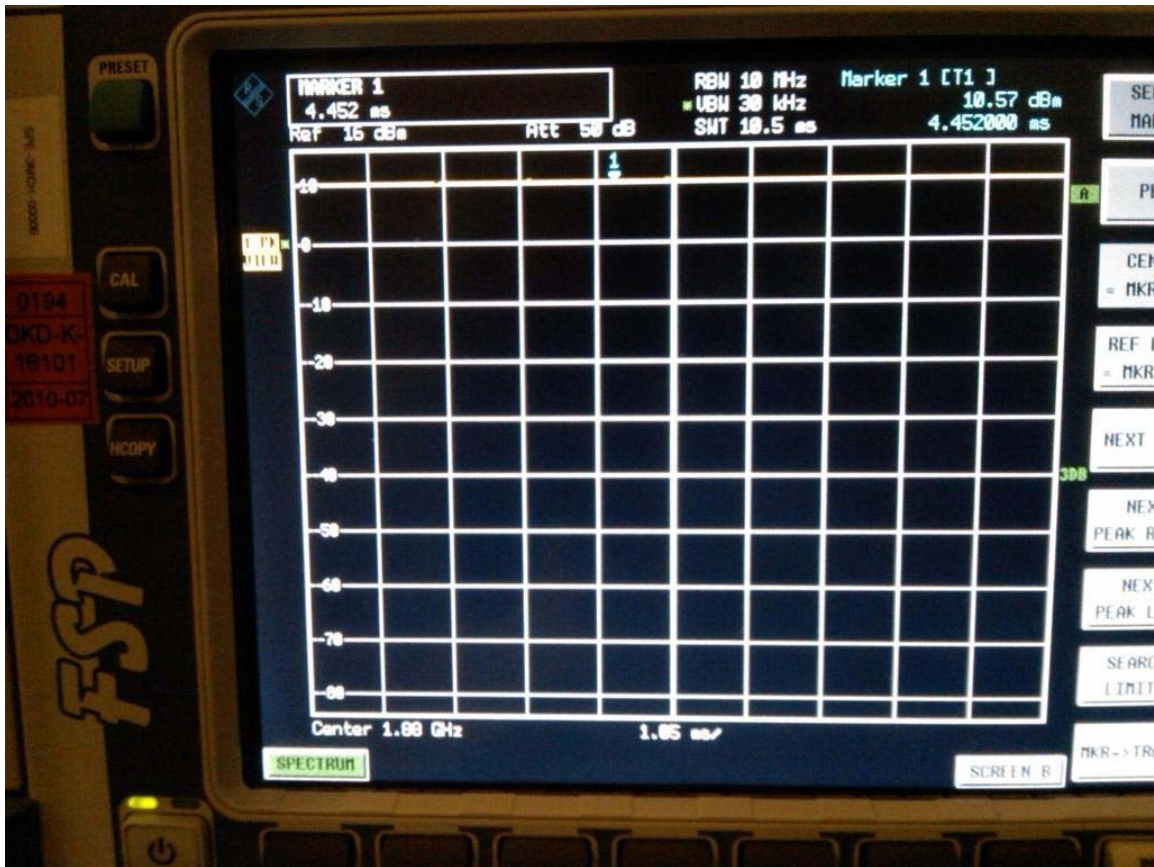
CW 1880 MHz

	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>15 (187)</b>
	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A RTS-2580-1106-36</b>




**AM 80 % 1880 MHz**

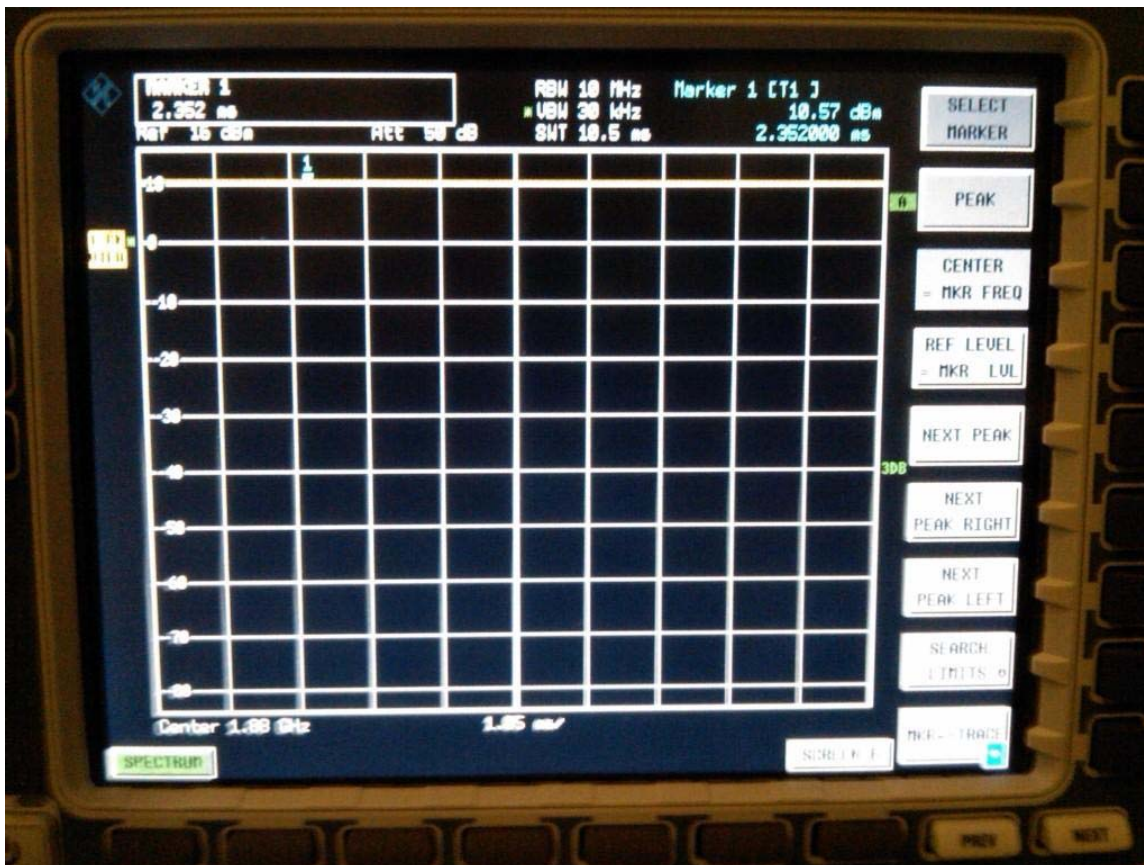
	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>16 (187)</b>
	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A RTS-2580-1106-36</b>




UMTS 1880 MHz

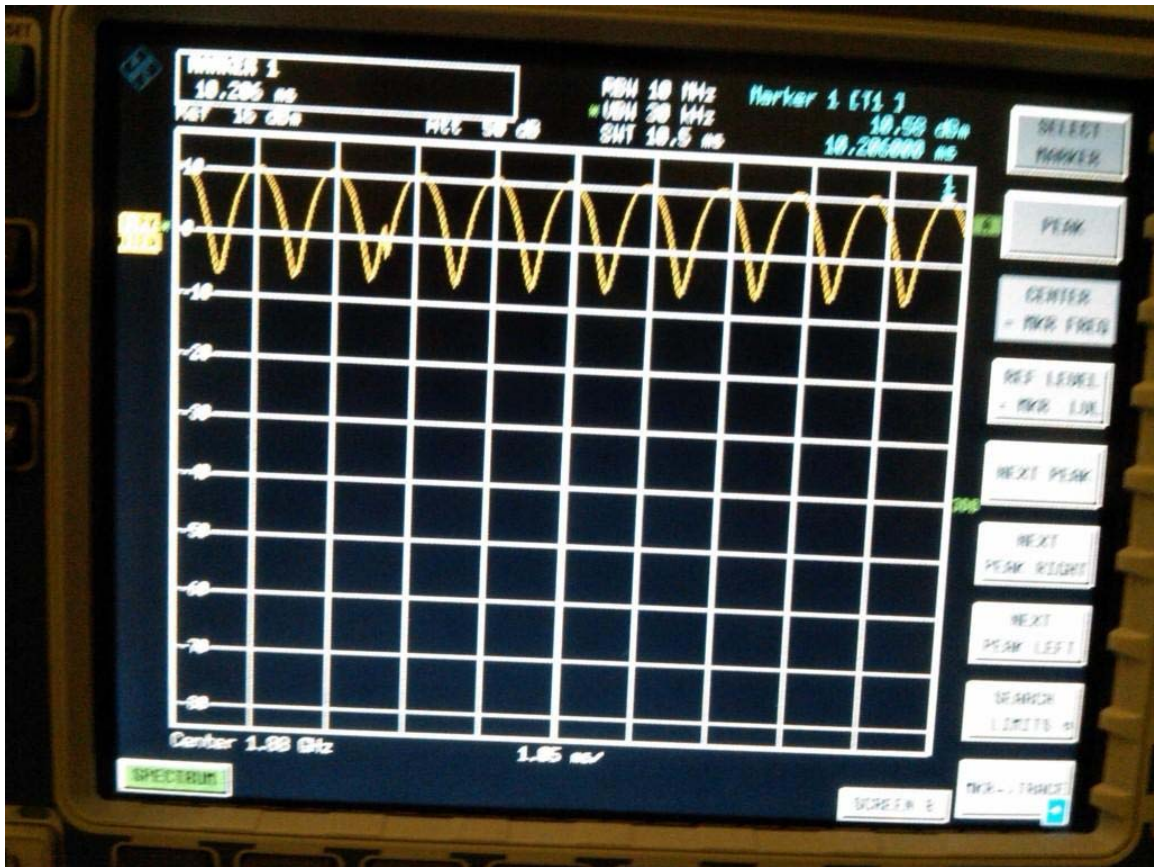


	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>17 (187)</b>
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**CW 1880 MHz**


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**AM 80 % 1880 MHz**

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## A.2 Dipole validation and probe modulation factor plots

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Date/Time: 3/22/2011 3:37:27 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_validation\_835 MHz**

**DUT: HAC-Dipole 835 MHz; Type: D835V3;**

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x361x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 160.2 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 119.1 V/m; Power Drift = 0.28 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>154.3 M4</b>	Grid 2 <b>160.2 M4</b>	Grid 3 <b>156.7 M4</b>
Grid 4 <b>85.253 M4</b>	Grid 5 <b>88.903 M4</b>	Grid 6 <b>87.202 M4</b>
Grid 7 <b>155.3 M4</b>	Grid 8 <b>158.9 M4</b>	Grid 9 <b>155.3 M4</b>

**Cursor:**

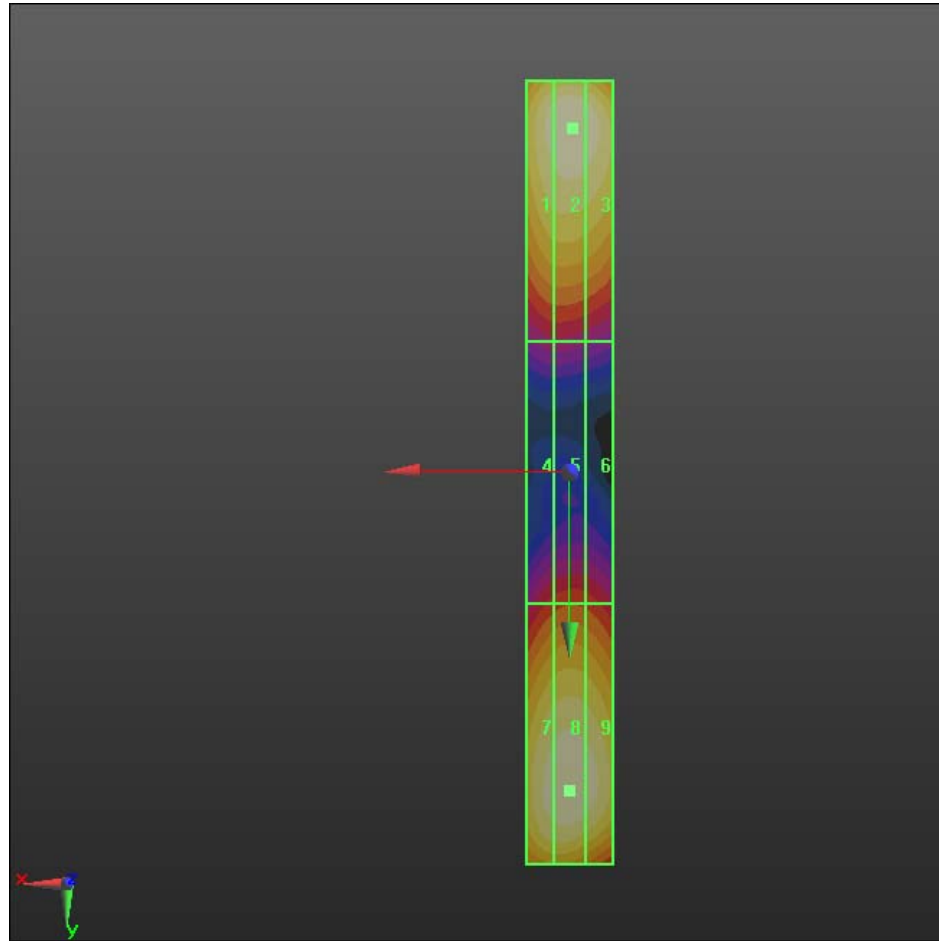
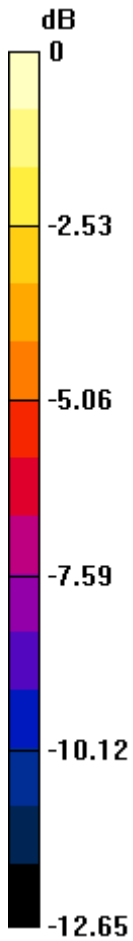
Total = 160.2 V/m  
E Category: M4  
Location: -0.5, -79, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 160.2V/m

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Date/Time: 3/22/2011 2:40:53 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_PMF\_GSM\_835 MHz**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: GSM 850;; Frequency: 835 MHz;Communication System PAR: 9.191 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x361x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 54.142 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 38.642 V/m; Power Drift = -0.06 dB

**Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

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Peak E-field in V/m

Grid 1 <b>51.408 M4</b>	Grid 2 <b>54.142 M4</b>	Grid 3 <b>52.509 M4</b>
Grid 4 <b>27.621 M4</b>	Grid 5 <b>27.841 M4</b>	Grid 6 <b>27.144 M4</b>
Grid 7 <b>49.045 M4</b>	Grid 8 <b>49.106 M4</b>	Grid 9 <b>47.011 M4</b>

**Cursor:**

Total = 54.142 V/m  
E Category: M4  
Location: -0.5, -79.5, 4.7 mm

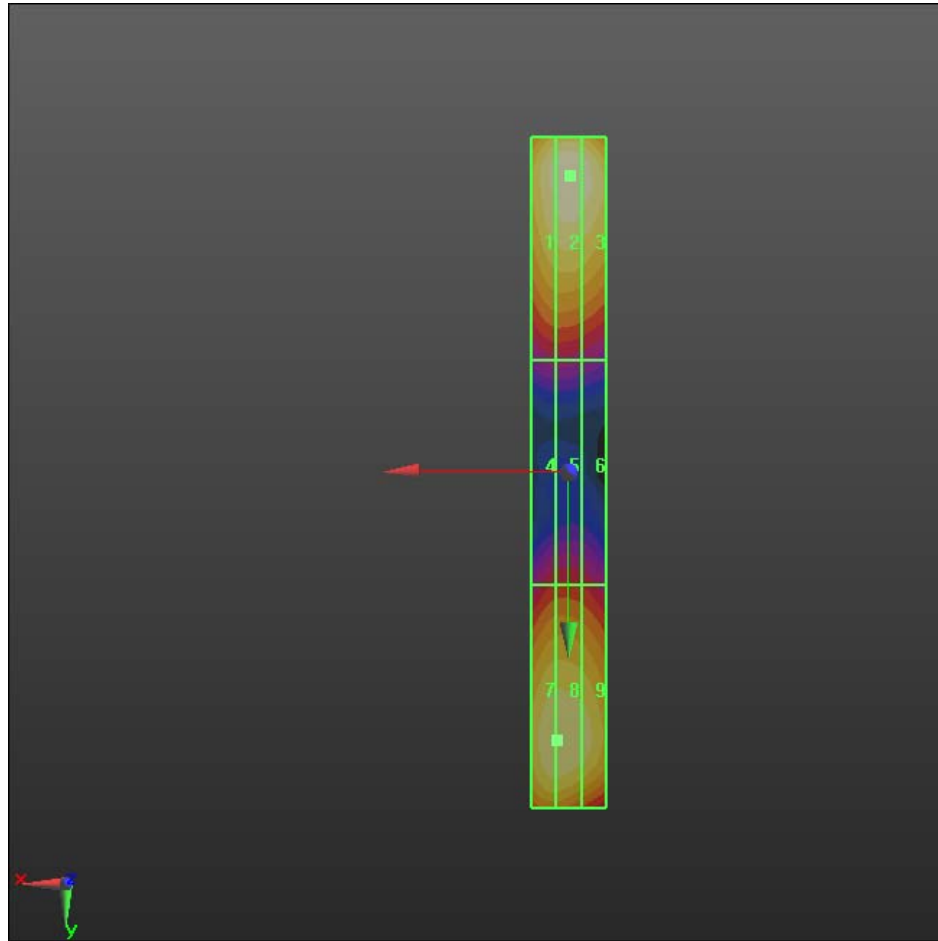
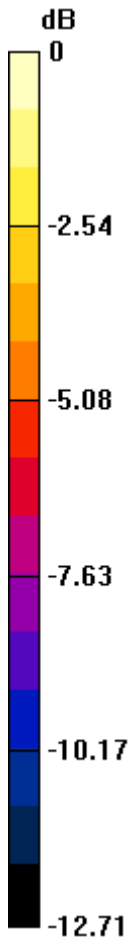


Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 54.140V/m

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Date/Time: 3/22/2011 3:01:22 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_PMF\_CW835 MHz\_GSM**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe:
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x361x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 159.3 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 120.6 V/m; Power Drift = -0.10 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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	Author Data <b>Daoud Attayi</b>	Dates of Test <b>Mar. 22-23, Apr. 28, 2011</b>	Report No <b>RTS-3933-1104-55A</b> <b>RTS-2580-1106-36</b>

Peak E-field in V/m

Grid 1 <b>153.1 M4</b>	Grid 2 <b>159.3 M4</b>	Grid 3 <b>154.5 M4</b>
Grid 4 <b>8066 M4</b>	Grid 5 <b>86.943 M4</b>	Grid 6 <b>84.863 M4</b>
Grid 7 <b>153.2 M4</b>	Grid 8 <b>154.9 M4</b>	Grid 9 <b>151.1 M4</b>

**Cursor:**

Total = 159.3 V/m

E Category: M4

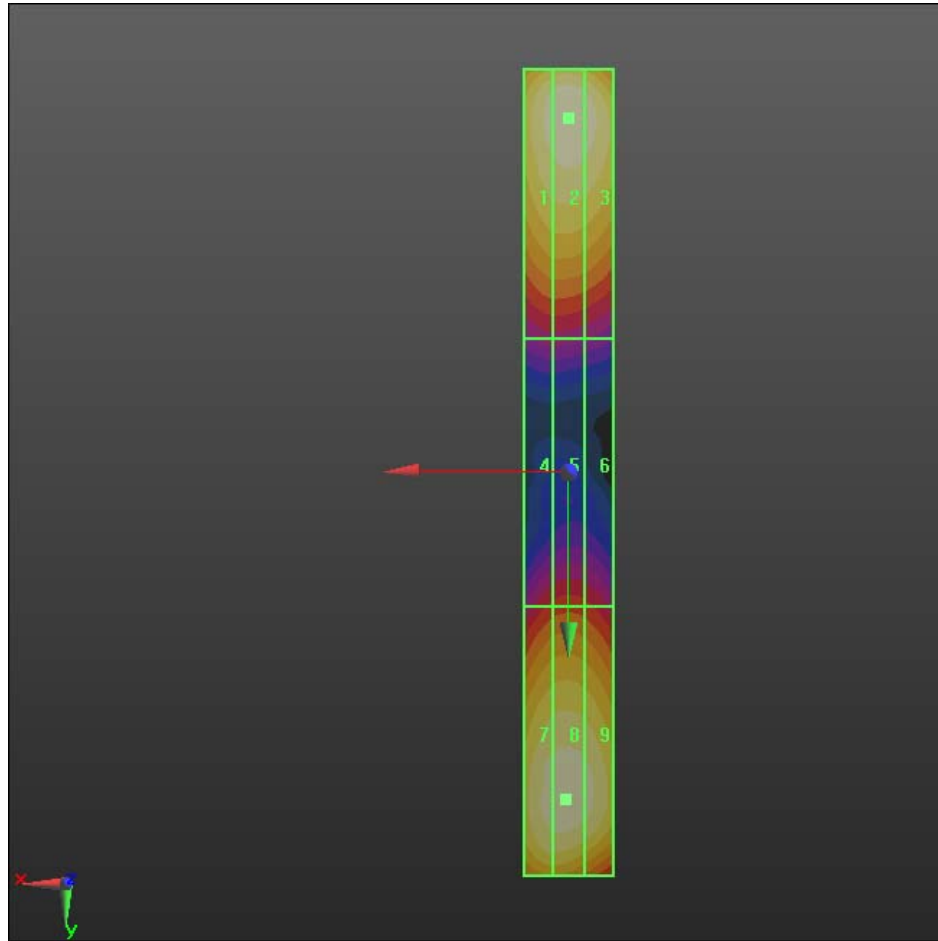
Location: 0, -79, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 159.3V/m

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Date/Time: 3/22/2011 3:09:37 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_PMF\_AM80%835 MHz\_GSM**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**


Communication System: AM 80%; Communication System Band: D835 (835.0 MHz);  
 Frequency: 835 MHz; Communication System PAR: 0 dB  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
 Phantom section: RF Section  
 Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x361x1):** Measurement grid: dx=5mm, dy=5mm  
 Maximum value of peak Total field = 99.820 V/m  
 Probe Modulation Factor = 1.000  
 Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 74.981 V/m; Power Drift = -0.17 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>96.553 M4</b>	Grid 2 <b>99.820 M4</b>	Grid 3 <b>97.313 M4</b>
Grid 4 <b>54.091 M4</b>	Grid 5 <b>55.431 M4</b>	Grid 6 <b>53.882 M4</b>
Grid 7 <b>95.955 M4</b>	Grid 8 <b>97.176 M4</b>	Grid 9 <b>95.117 M4</b>

**Cursor:**

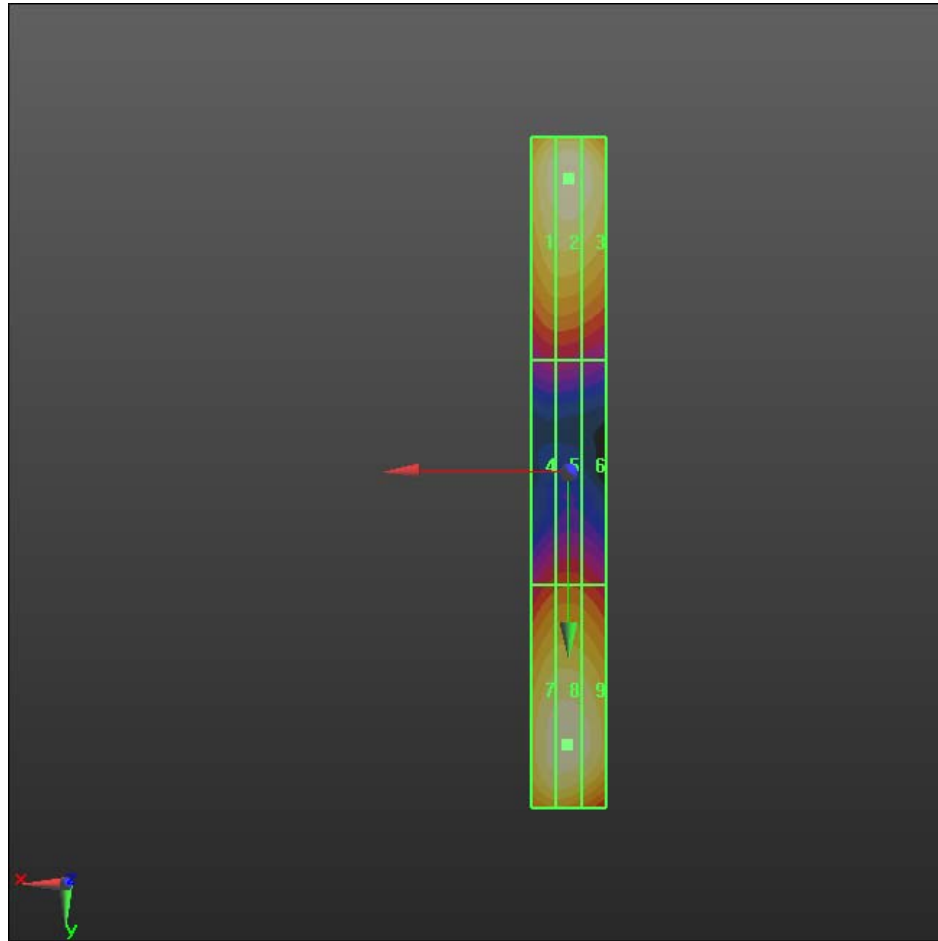
Total = 99.821 V/m  
E Category: M4  
Location: 0, -79, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 99.820V/m

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Date/Time: 3/22/2011 2:51:34 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_PMF\_CDMA\_835 MHz**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: CDMA 800; Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)


DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x361x1):** Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 63.653 V/m  
Probe Modulation Factor = 1.000  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 45.492 V/m; Power Drift = 0.04 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**



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Peak E-field in V/m

Grid 1 <b>60.457 M4</b>	Grid 2 <b>63.653 M4</b>	Grid 3 <b>62.702 M4</b>
Grid 4 <b>32.119 M4</b>	Grid 5 <b>32.806 M4</b>	Grid 6 <b>32.009 M4</b>
Grid 7 <b>57.694 M4</b>	Grid 8 <b>58.081 M4</b>	Grid 9 <b>56.094 M4</b>

**Cursor:**

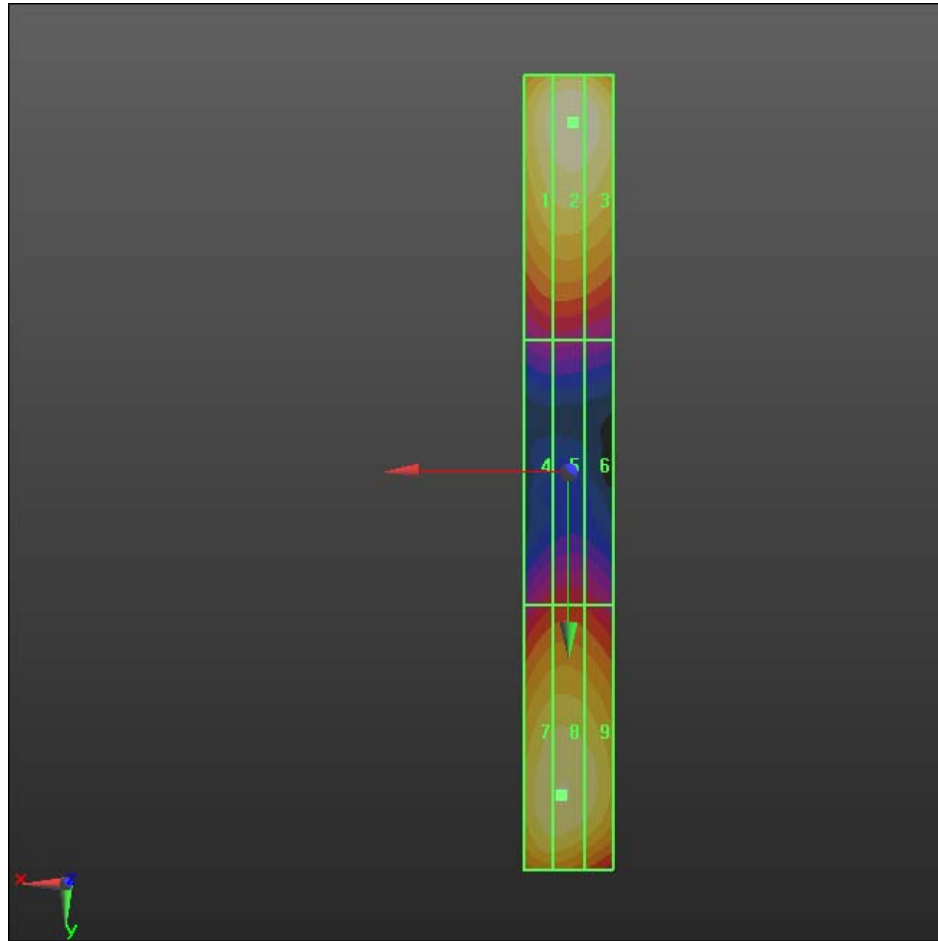
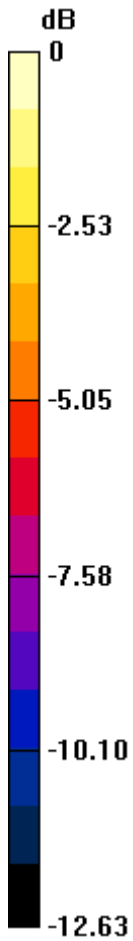
Total = 63.653 V/m  
E Category: M4  
Location: -1, -79, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
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 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 63.650V/m

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Date/Time: 3/22/2011 3:23:33 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_PMF\_CW835 MHz\_CDMA**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x361x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 62.994 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 48.064 V/m; Power Drift = 0.07 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>60.423 M4</b>	Grid 2 <b>62.994 M4</b>	Grid 3 <b>61.497 M4</b>
Grid 4 <b>33.852 M4</b>	Grid 5 <b>34.972 M4</b>	Grid 6 <b>34.054 M4</b>
Grid 7 <b>60.979 M4</b>	Grid 8 <b>62.079 M4</b>	Grid 9 <b>60.453 M4</b>

**Cursor:**

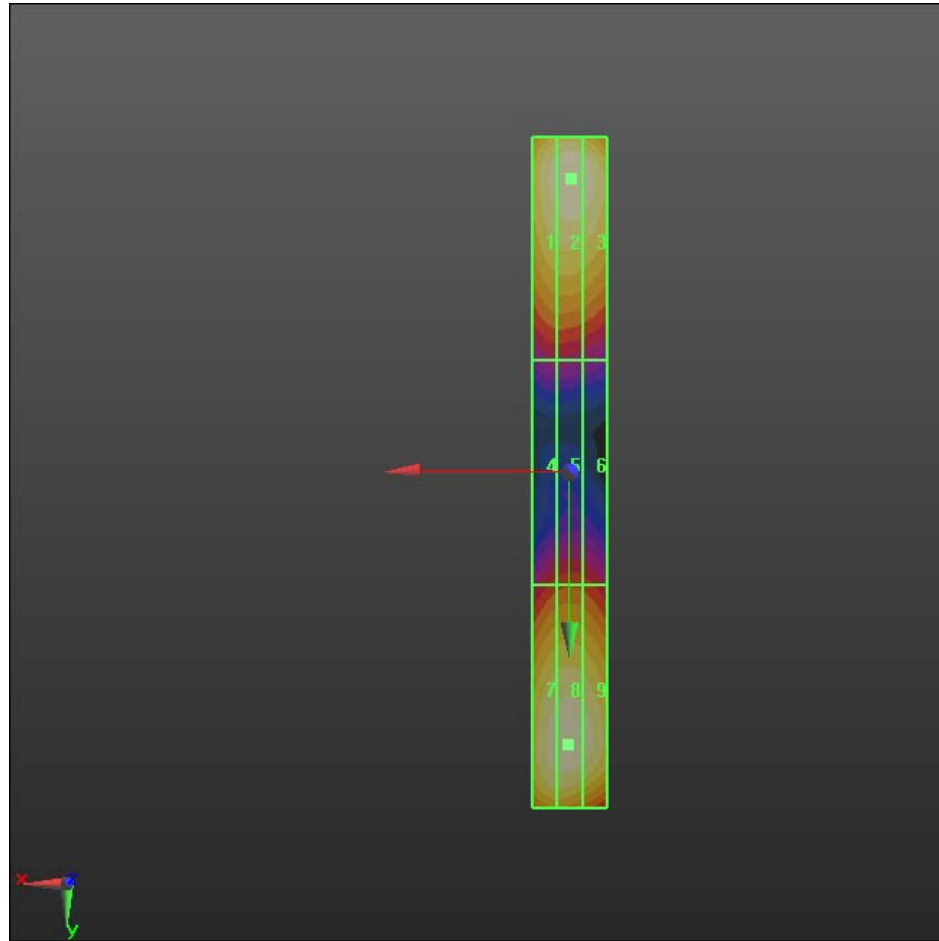
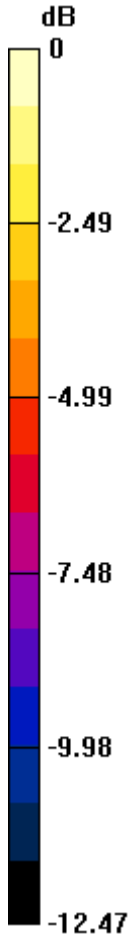
Total = 62.994 V/m  
E Category: M4  
Location: -0.5, -79, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
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FCC ID  
**L6ARDU70CW  
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0 dB = 62.990V/m

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Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_PMF\_AM80%835 MHz\_CDMA**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**


Communication System: AM 80%; Communication System Band: D835 (835.0 MHz);  
Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x361x1):** Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 40.248 V/m  
Probe Modulation Factor = 1.000  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 30.394 V/m; Power Drift = 0.02 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>38.736 M4</b>	Grid 2 <b>40.248 M4</b>	Grid 3 <b>39.607 M4</b>
Grid 4 <b>21.813 M4</b>	Grid 5 <b>22.486 M4</b>	Grid 6 <b>21.734 M4</b>
Grid 7 <b>38.792 M4</b>	Grid 8 <b>39.696 M4</b>	Grid 9 <b>38.886 M4</b>

**Cursor:**

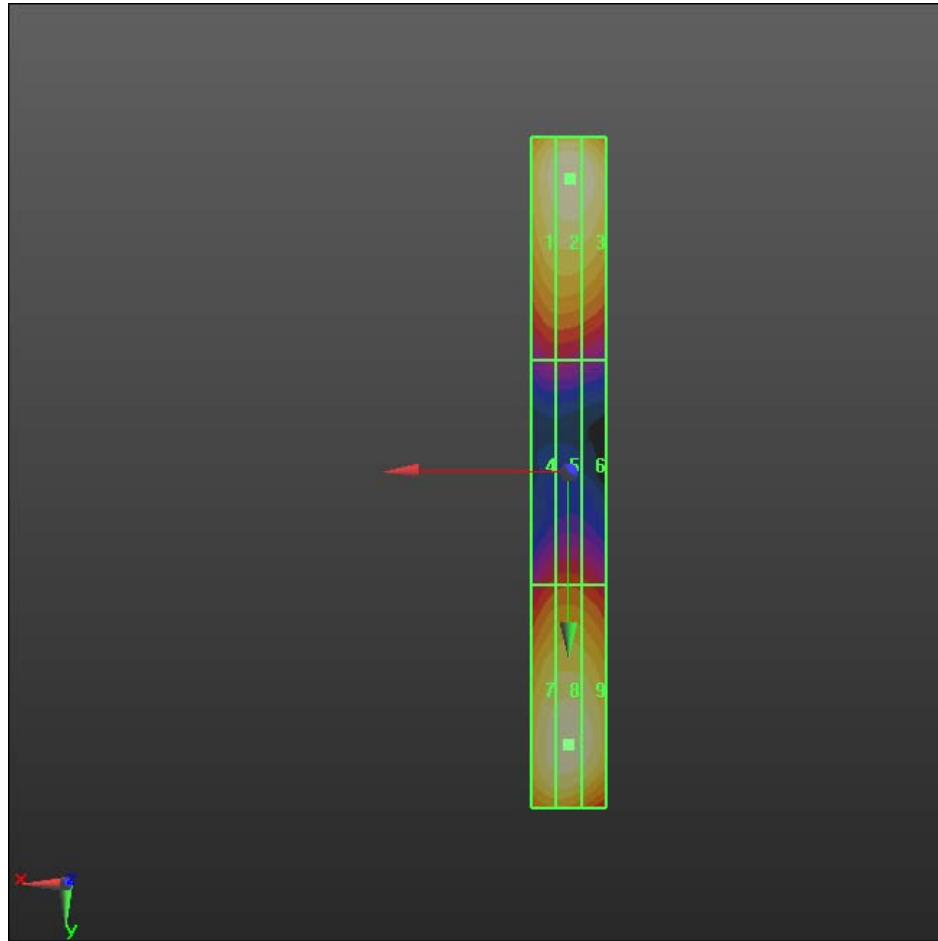
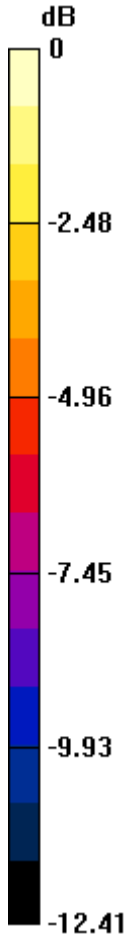
Total = 40.248 V/m  
E Category: M4  
Location: -0.5, -79, 4.7 mm

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**


Report No  
**RTS-3933-1104-55A  
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FCC ID  
**L6ARDU70CW  
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0 dB = 40.250V/m



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Date/Time: 3/22/2011 4:50:23 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_validation\_1880 MHz**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**


Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 133.2 V/m  
Probe Modulation Factor = 1.000  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 124.8 V/m; Power Drift = -0.0086 dB  
**Hearing Aid Near-Field Category: M2 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>130.6 M2</b>	Grid 2 <b>133.2 M2</b>	Grid 3 <b>126.2 M2</b>
Grid 4 <b>83.013 M3</b>	Grid 5 <b>87.500 M3</b>	Grid 6 <b>86.528 M3</b>
Grid 7 <b>121.2 M2</b>	Grid 8 <b>124.7 M2</b>	Grid 9 <b>122.2 M2</b>

**Cursor:**

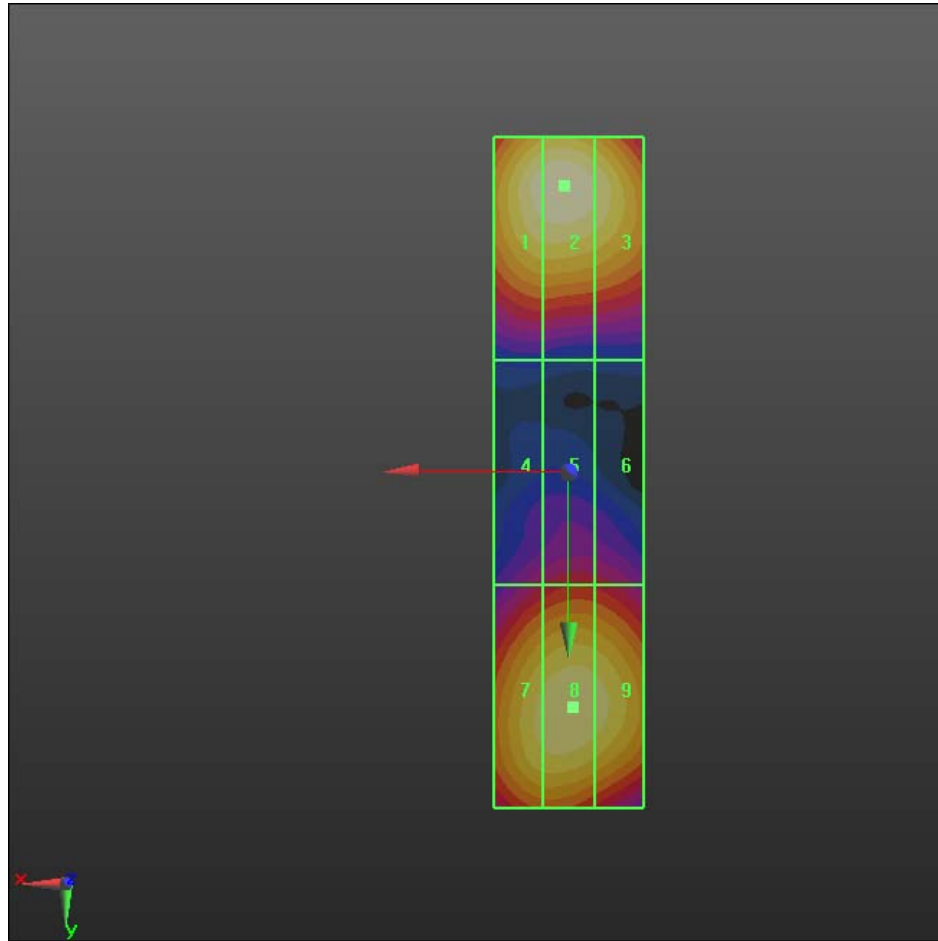
Total = 133.2 V/m  
E Category: M2  
Location: 0.5, -38.5, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 133.2V/m

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Date/Time: 3/22/2011 4:54:49 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_PMF\_GSM\_1880 MHz\_R2**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: GSM 1900; Frequency: 1880 MHz; Communication System PAR: 9.191 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 27.663 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 25.374 V/m; Power Drift = 0.02 dB

**Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

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Peak E-field in V/m

Grid 1 <b>27.050 M4</b>	Grid 2 <b>27.663 M4</b>	Grid 3 <b>26.052 M4</b>
Grid 4 <b>17.031 M4</b>	Grid 5 <b>18.013 M4</b>	Grid 6 <b>17.833 M4</b>
Grid 7 <b>2036 M4</b>	Grid 8 <b>25.539 M4</b>	Grid 9 <b>25.116 M4</b>

**Cursor:**

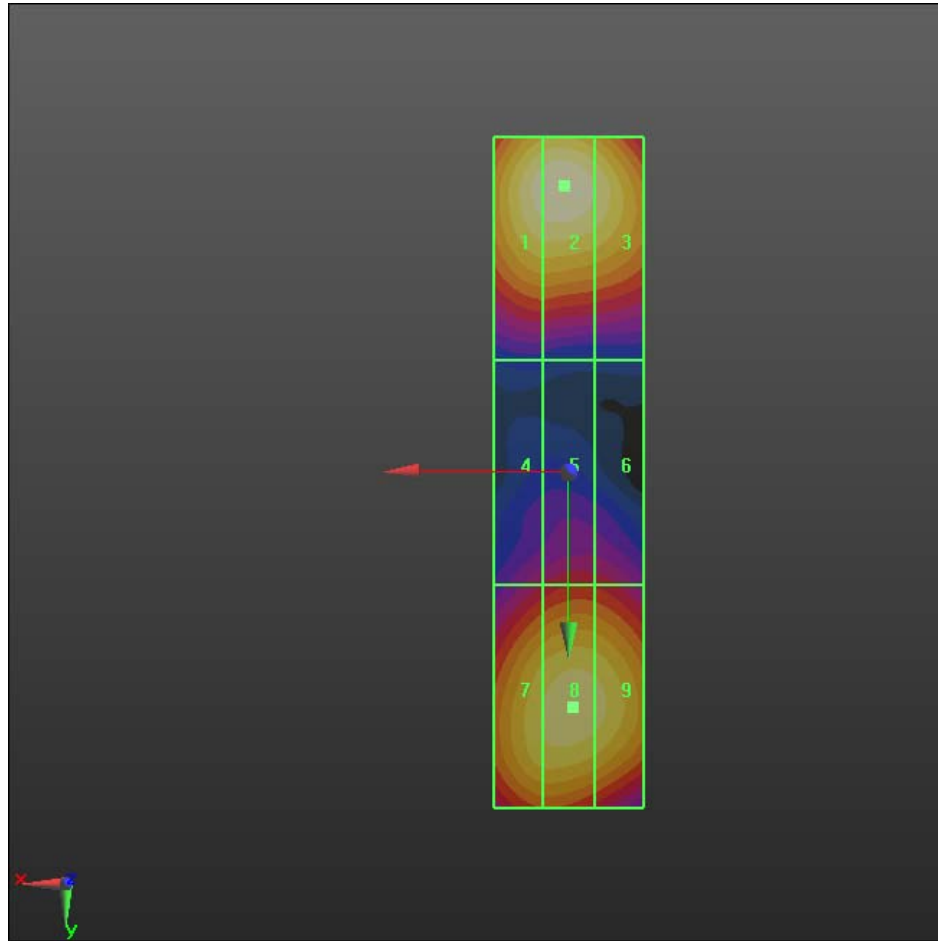
Total = 27.663 V/m  
E Category: M4  
Location: 0.5, -38.5, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 27.660V/m

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Date/Time: 3/23/2011 12:08:40 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_PMF\_CW1880 MHz\_GSM**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 82.216 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 78.932 V/m; Power Drift = 0.0039 dB

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**



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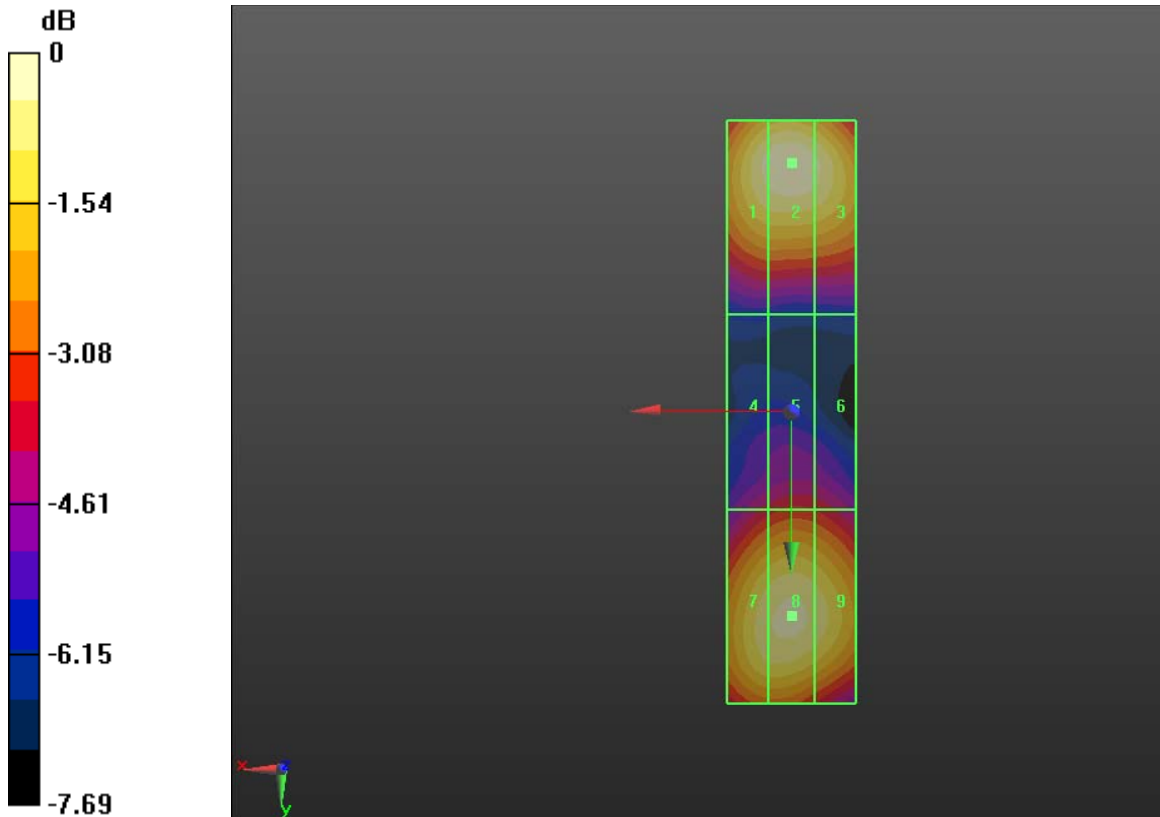
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak E-field in V/m

Grid 1 <b>79.692 M3</b>	Grid 2 <b>82.216 M3</b>	Grid 3 <b>79.228 M3</b>
Grid 4 <b>52.849 M4</b>	Grid 5 <b>55.292 M4</b>	Grid 6 <b>54.232 M4</b>
Grid 7 <b>76.960 M3</b>	Grid 8 <b>78.815 M3</b>	Grid 9 <b>76.489 M3</b>


**Cursor:**

Total = 82.216 V/m  
 E Category: M3  
 Location: 0, -38.5, 4.7 mm



0 dB = 82.220V/m



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Date/Time: 3/22/2011 4:12:07 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_PMF\_AM80%1880 MHz\_GSM**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: AM 80%; Communication System Band: D1900 (1900.0 MHz);  
Frequency: 1880 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 53.337 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 49.939 V/m; Power Drift = -0.09 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>52.377 M4</b>	Grid 2 <b>53.337 M4</b>	Grid 3 <b>50.671 M4</b>
Grid 4 <b>3062 M4</b>	Grid 5 <b>35.058 M4</b>	Grid 6 <b>3043 M4</b>
Grid 7 <b>48.429 M4</b>	Grid 8 <b>49.374 M4</b>	Grid 9 <b>48.243 M4</b>

**Cursor:**

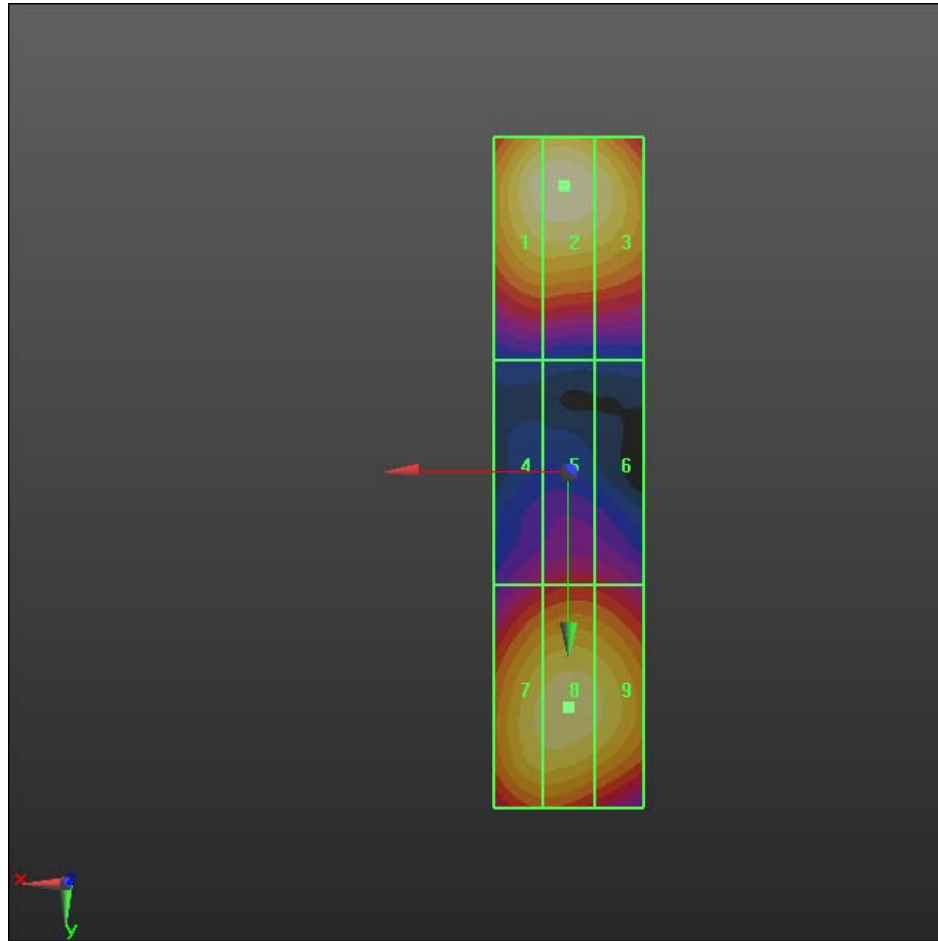
Total = 53.337 V/m  
E Category: M4  
Location: 0.5, -38.5, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
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 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
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0 dB = 53.340V/m

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Date/Time: 3/22/2011 3:54:49 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_PMF\_CDMA\_1880 MHz**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Communication System

PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 43.150 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 40.108 V/m; Power Drift = -0.01 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>41.912 M4</b>	Grid 2 <b>43.150 M4</b>	Grid 3 <b>40.971 M4</b>
Grid 4 <b>26.905 M4</b>	Grid 5 <b>28.223 M4</b>	Grid 6 <b>27.711 M4</b>
Grid 7 <b>39.111 M4</b>	Grid 8 <b>40.205 M4</b>	Grid 9 <b>39.292 M4</b>

**Cursor:**

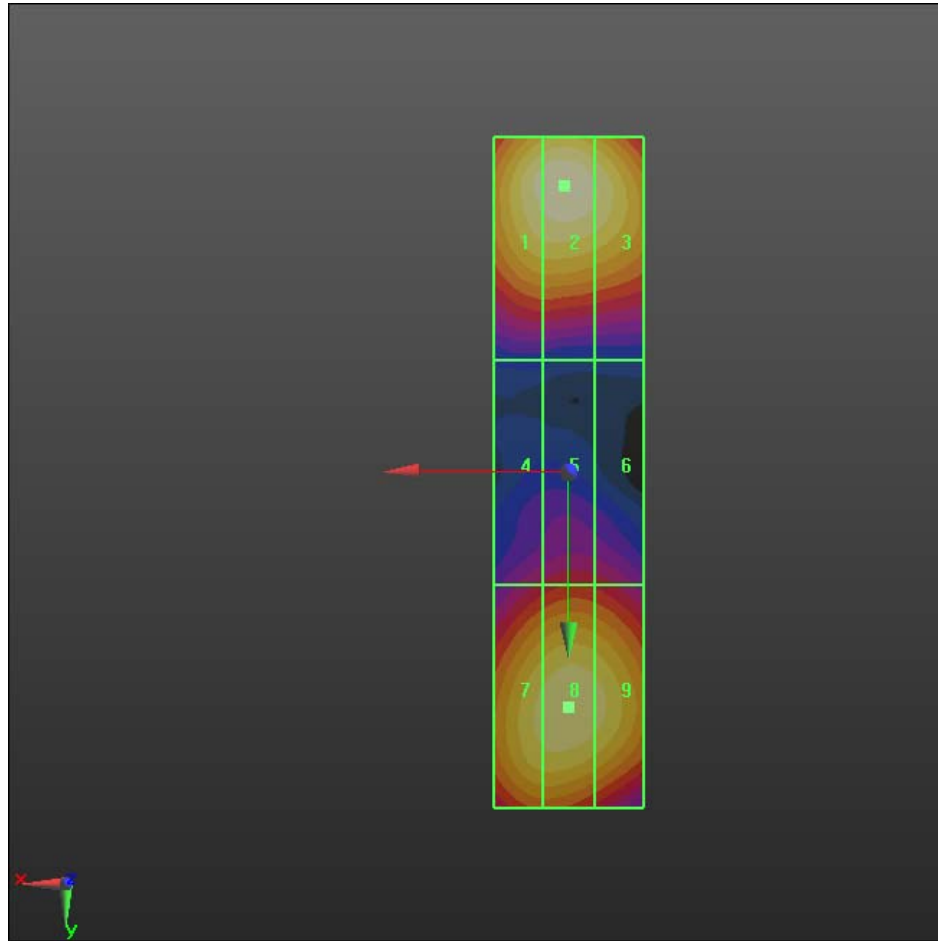
Total = 43.150 V/m  
E Category: M4  
Location: 0.5, -38.5, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 43.150V/m

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Date/Time: 3/23/2011 12:23:00 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_PMF\_CW1880 MHz\_CDMA\_**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 45.598 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 43.399 V/m; Power Drift = 0.03 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

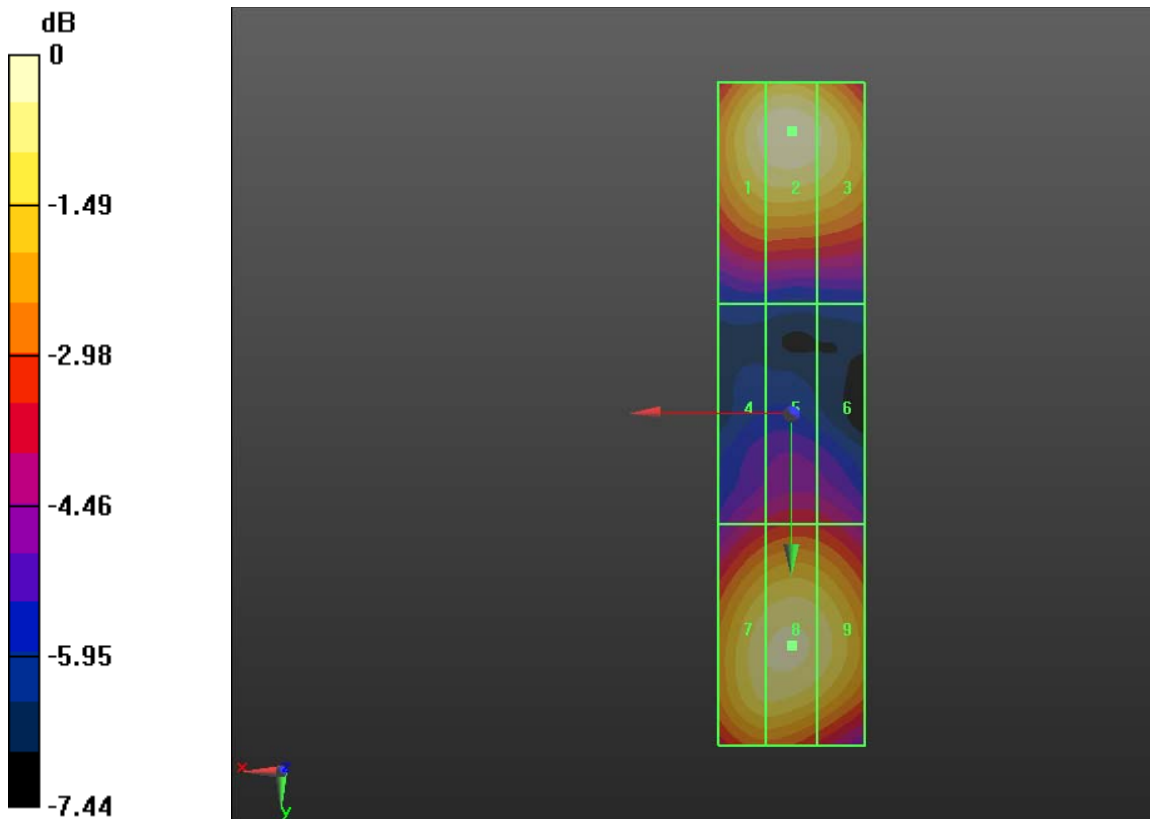
	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>56 (187)</b>
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Peak E-field in V/m

Grid 1 <b>44.340 M4</b>	Grid 2 <b>45.598 M4</b>	Grid 3 <b>43.792 M4</b>
Grid 4 <b>29.598 M4</b>	Grid 5 <b>30.871 M4</b>	Grid 6 <b>30.339 M4</b>
Grid 7 <b>42.981 M4</b>	Grid 8 <b>43.734 M4</b>	Grid 9 <b>42.515 M4</b>


Cursor:

Total = 45.598 V/m  
 E Category: M4  
 Location: 0, -38.5, 4.7 mm



0 dB = 45.600V/m



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Date/Time: 3/22/2011 4:34:04 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_PMF\_AM80%1880 MHz\_CDMA**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: AM 80%; Communication System Band: D1900 (1900.0 MHz);  
Frequency: 1880 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 30.486 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 28.158 V/m; Power Drift = 0.06 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

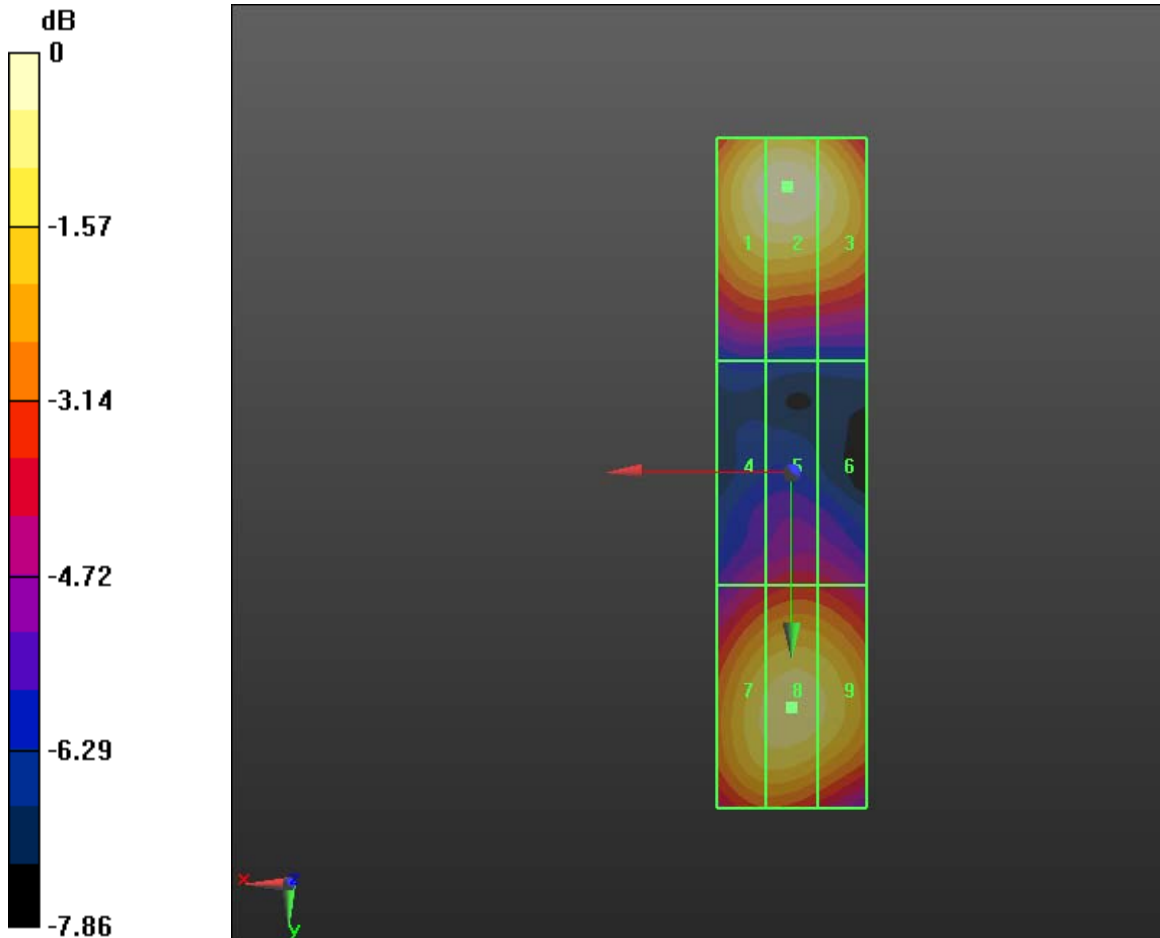
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak E-field in V/m


Grid 1 <b>29.713 M4</b>	Grid 2 <b>30.486 M4</b>	Grid 3 <b>29.090 M4</b>
Grid 4 <b>18.962 M4</b>	Grid 5 <b>19.986 M4</b>	Grid 6 <b>19.699 M4</b>
Grid 7 <b>27.492 M4</b>	Grid 8 <b>28.197 M4</b>	Grid 9 <b>27.513 M4</b>

**Cursor:**

Total = 30.486 V/m  
 E Category: M4  
 Location: 0.5, -38.5, 4.7 mm



0 dB = 30.490V/m

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Date/Time: 3/23/2011 3:19:30 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_validation\_835 MHz**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.475 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.514 A/m; Power Drift = -0.08 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

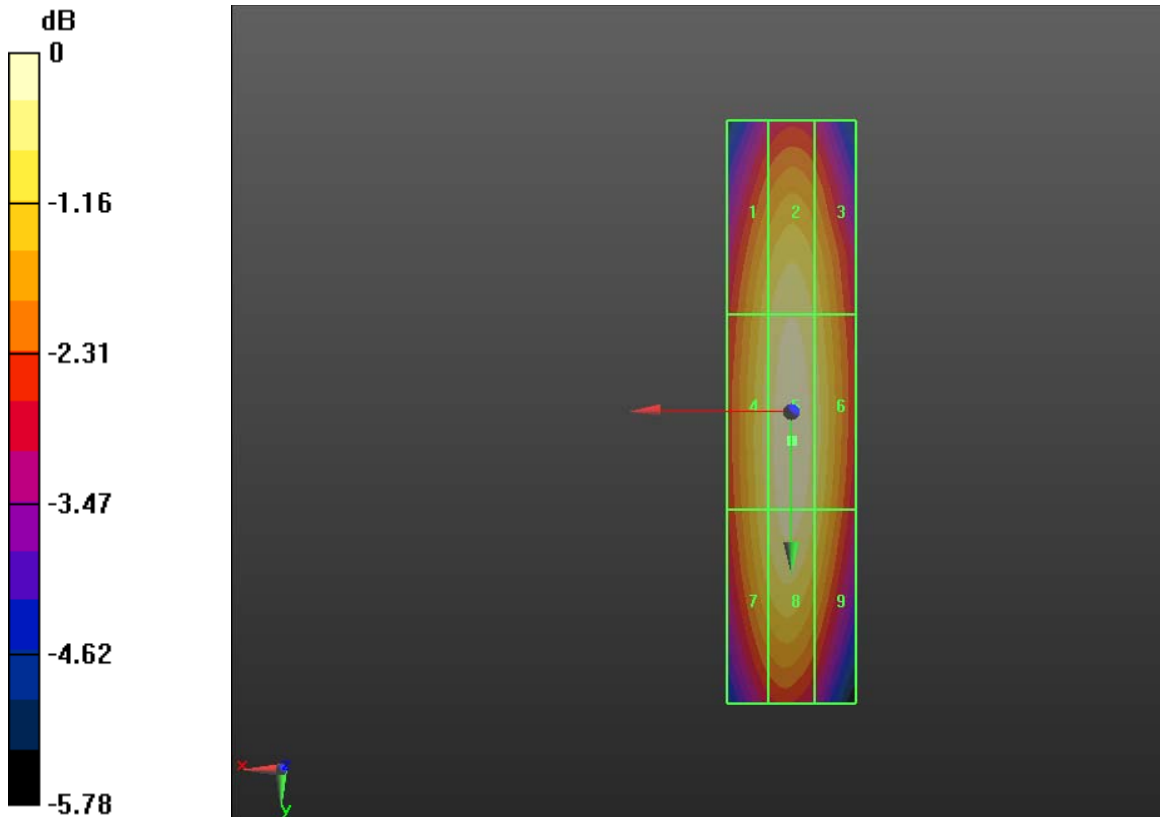
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.437 M4</b>	Grid 2 <b>0.459 M4</b>	Grid 3 <b>0.437 M4</b>
Grid 4 <b>0.453 M4</b>	Grid 5 <b>0.475 M4</b>	Grid 6 <b>0.453 M4</b>
Grid 7 <b>0.447 M4</b>	Grid 8 <b>0.469 M4</b>	Grid 9 <b>0.442 M4</b>

**Cursor:**

Total = 0.475 A/m  
 H Category: M4  
 Location: 0, 4.5, 4.7 mm



0 dB = 0.480A/m

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Date/Time: 3/23/2011 3:06:50 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_PMF\_GSM\_835 MHz**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: GSM 850; Frequency: 835 MHz; Communication System PAR: 9.191 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.168 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.173 A/m; Power Drift = 0.43 dB

**Hearing Aid Near-Field Category: M4 (AWF -5 dB)**



Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
RTS-2580-1106-36**

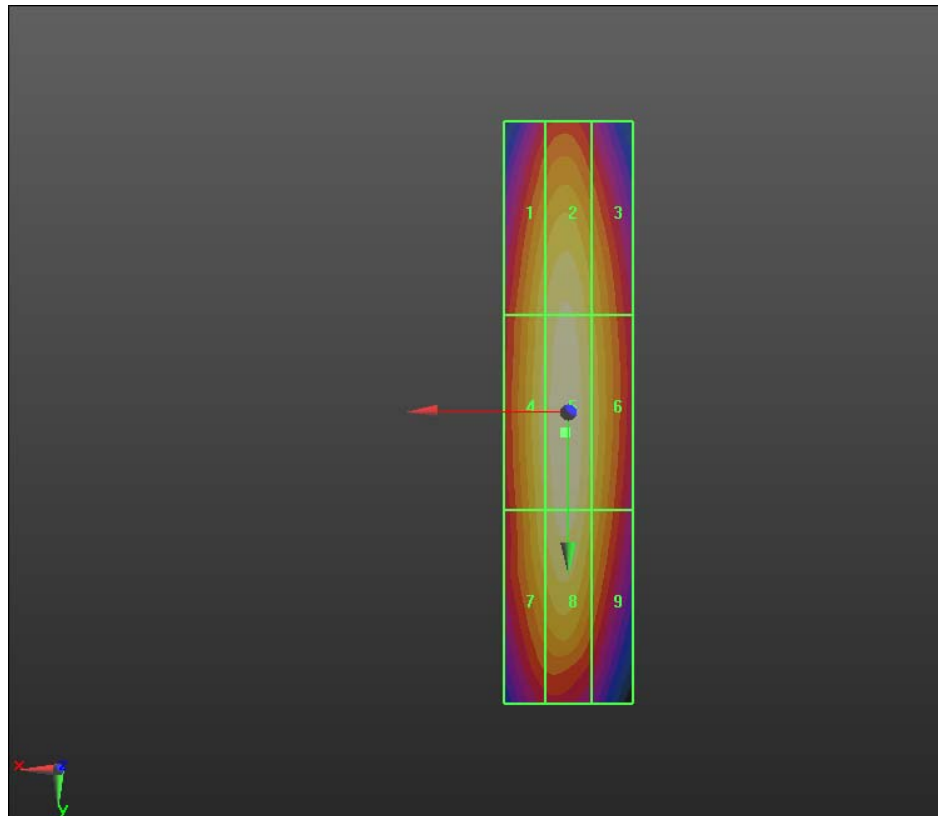
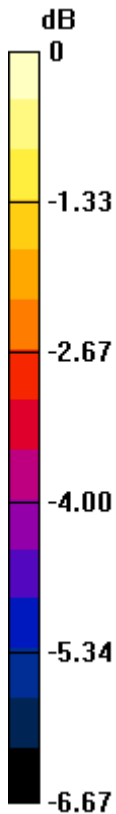
FCC ID  
**L6ARDU70CW  
L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.154 M4</b>	Grid 2 <b>0.163 M4</b>	Grid 3 <b>0.148 M4</b>
Grid 4 <b>0.159 M4</b>	Grid 5 <b>0.168 M4</b>	Grid 6 <b>0.153 M4</b>
Grid 7 <b>0.155 M4</b>	Grid 8 <b>0.165 M4</b>	Grid 9 <b>0.148 M4</b>

**Cursor:**

Total = 0.168 A/m  
H Category: M4  
Location: 0.5, 3, 4.7 mm



0 dB = 0.170A/m

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Date/Time: 3/23/2011 3:23:34 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_PMF\_CW835 MHz\_GSM**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.482 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.503 A/m; Power Drift = -0.00099 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

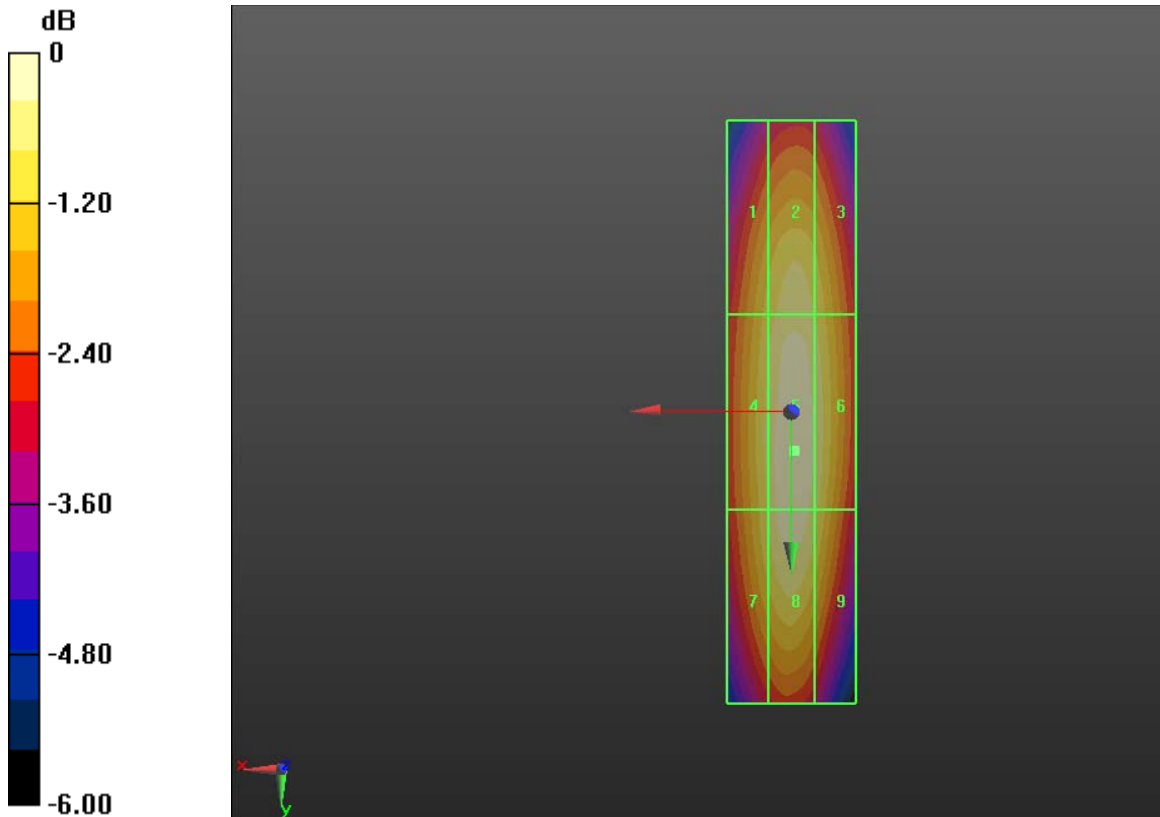
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak H-field in A/m

Grid 1 <b>0.429 M4</b>	Grid 2 <b>0.450 M4</b>	Grid 3 <b>0.439 M4</b>
Grid 4 <b>0.449 M4</b>	Grid 5 <b>0.482 M4</b>	Grid 6 <b>0.458 M4</b>
Grid 7 <b>0.441 M4</b>	Grid 8 <b>0.475 M4</b>	Grid 9 <b>0.448 M4</b>


**Cursor:**

Total = 0.482 A/m  
 H Category: M4  
 Location: -0.5, 6, 4.7 mm



0 dB = 0.480A/m



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Date/Time: 3/23/2011 3:34:08 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_PMF\_AM80%835 MHz\_GSM**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: AM 80%; Communication System Band: D835 (835.0 MHz);  
Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x181x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.302 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.326 A/m; Power Drift = -0.16 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

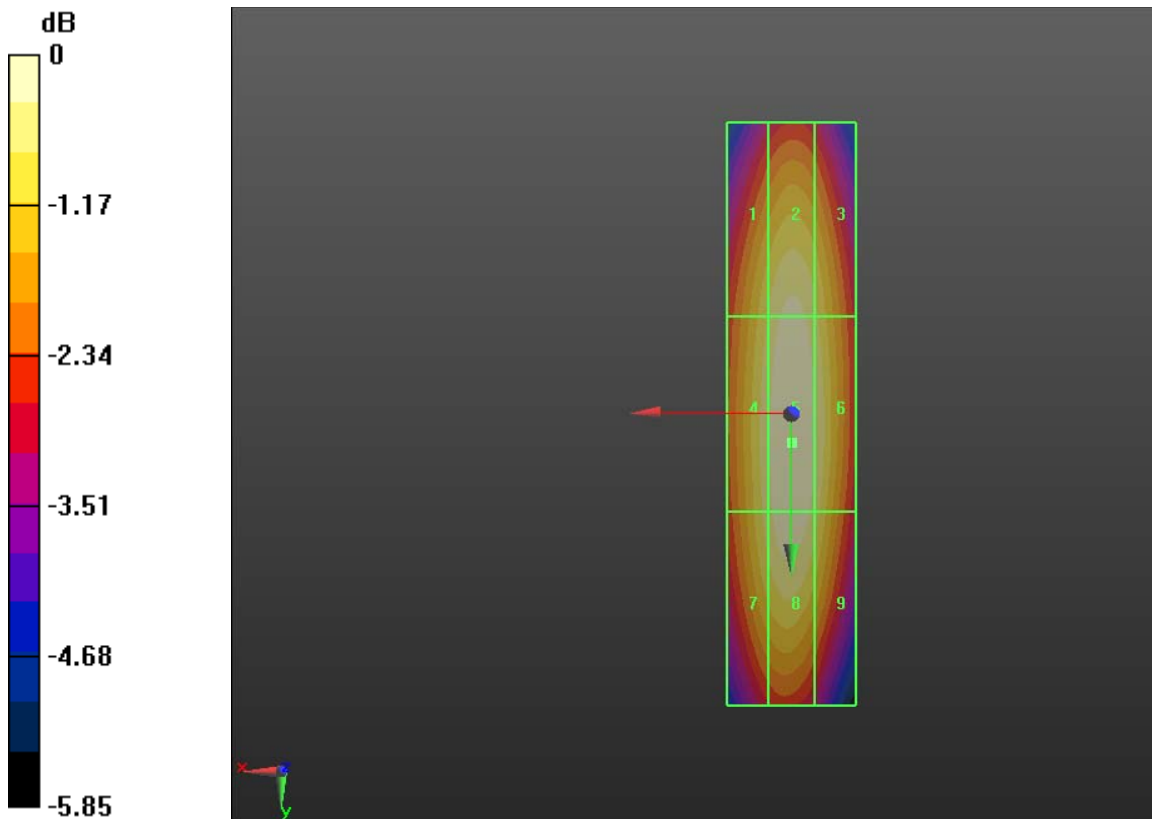
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Peak H-field in A/m


Grid 1 <b>0.276 M4</b>	Grid 2 <b>0.292 M4</b>	Grid 3 <b>0.279 M4</b>
Grid 4 <b>0.286 M4</b>	Grid 5 <b>0.302 M4</b>	Grid 6 <b>0.289 M4</b>
Grid 7 <b>0.283 M4</b>	Grid 8 <b>0.299 M4</b>	Grid 9 <b>0.281 M4</b>

**Cursor:**

Total = 0.302 A/m  
 H Category: M4  
 Location: 0, 4.5, 4.7 mm



0 dB = 0.300A/m

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Date/Time: 3/23/2011 3:11:51 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_PMF\_CDMA\_835 MHz**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: CDMA 800;; Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.183 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.196 A/m; Power Drift = 0.01 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

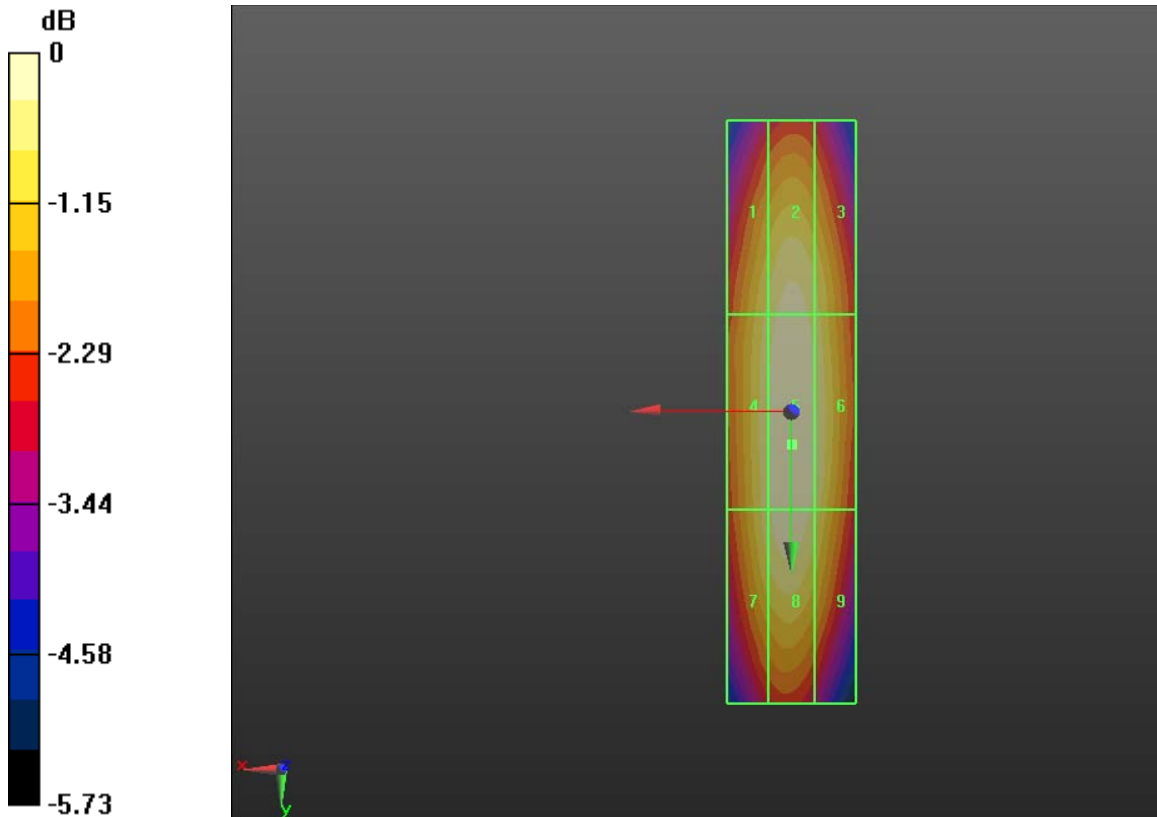
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.168 M4</b>	Grid 2 <b>0.176 M4</b>	Grid 3 <b>0.169 M4</b>
Grid 4 <b>0.173 M4</b>	Grid 5 <b>0.183 M4</b>	Grid 6 <b>0.175 M4</b>
Grid 7 <b>0.171 M4</b>	Grid 8 <b>0.180 M4</b>	Grid 9 <b>0.169 M4</b>

**Cursor:**

Total = 0.183 A/m  
 H Category: M4  
 Location: 0, 5, 4.7 mm



0 dB = 0.180A/m

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Date/Time: 3/23/2011 3:28:48 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_PMF\_CW835 MHz\_CDMA**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.191 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.202 A/m; Power Drift = -0.03 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

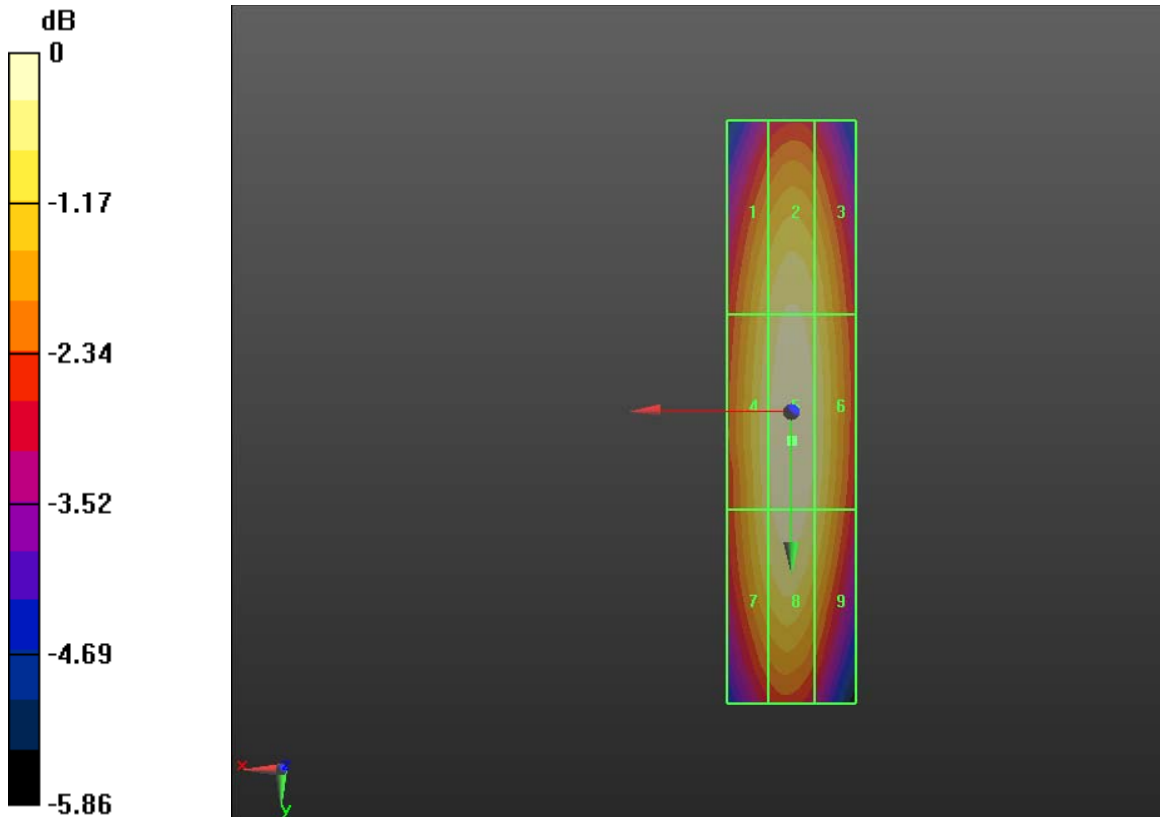
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.175 M4</b>	Grid 2 <b>0.183 M4</b>	Grid 3 <b>0.176 M4</b>
Grid 4 <b>0.182 M4</b>	Grid 5 <b>0.191 M4</b>	Grid 6 <b>0.182 M4</b>
Grid 7 <b>0.179 M4</b>	Grid 8 <b>0.187 M4</b>	Grid 9 <b>0.178 M4</b>

**Cursor:**

Total = 0.191 A/m  
 H Category: M4  
 Location: 0, 4.5, 4.7 mm



0 dB = 0.190A/m

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Date/Time: 3/23/2011 3:38:43 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_PMF\_AM80%835 MHz\_CDMA**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: AM 80%; Communication System Band: D835 (835.0 MHz);  
Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.121 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.129 A/m; Power Drift = -0.09 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A**  
**RTS-2580-1106-36**

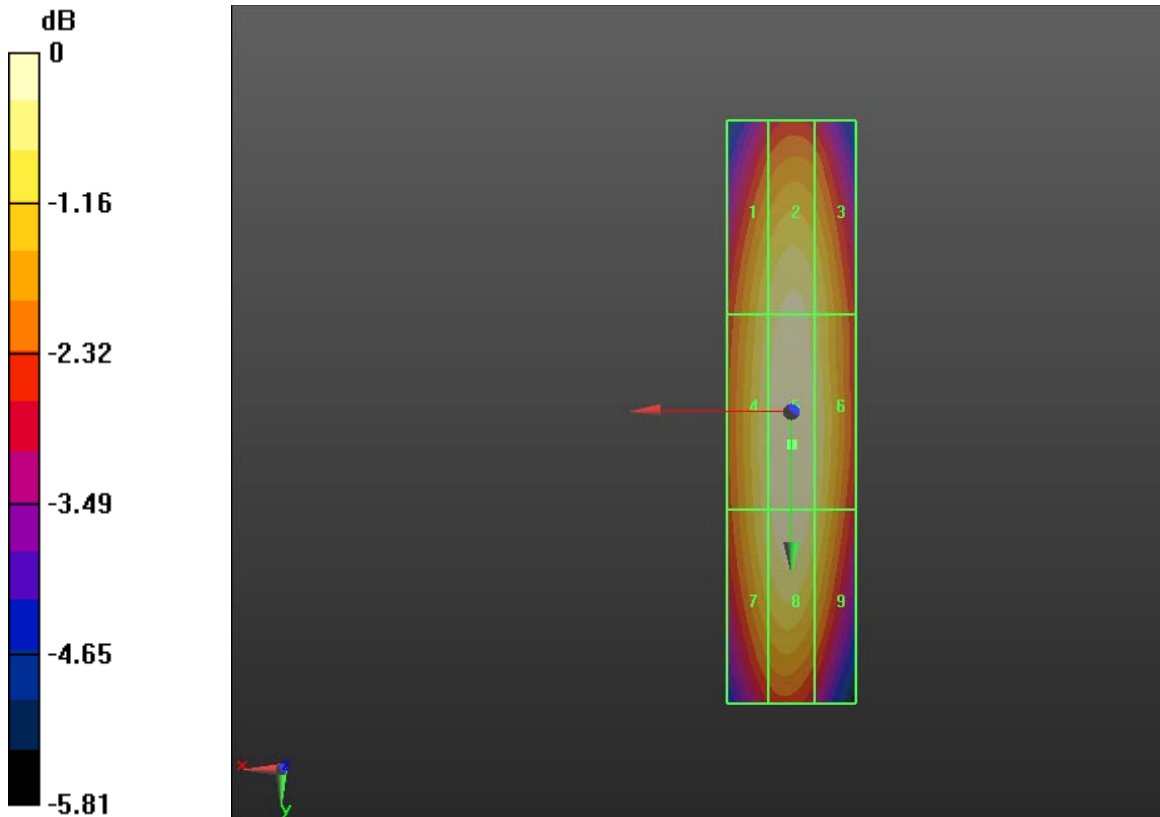
FCC ID  
**L6ARDU70CW**  
**L6ARDE70UW**

Peak H-field in A/m

Grid 1 <b>0.111 M4</b>	Grid 2 <b>0.117 M4</b>	Grid 3 <b>0.113 M4</b>
Grid 4 <b>0.115 M4</b>	Grid 5 <b>0.121 M4</b>	Grid 6 <b>0.116 M4</b>
Grid 7 <b>0.114 M4</b>	Grid 8 <b>0.120 M4</b>	Grid 9 <b>0.113 M4</b>


**Cursor:**

Total = 0.121 A/m  
H Category: M4  
Location: 0, 5, 4.7 mm



0 dB = 0.120A/m



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Date/Time: 3/23/2011 12:47:34 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_validation\_1880 MHz**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.451 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.479 A/m; Power Drift = -0.02 dB

**Hearing Aid Near-Field Category: M2 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

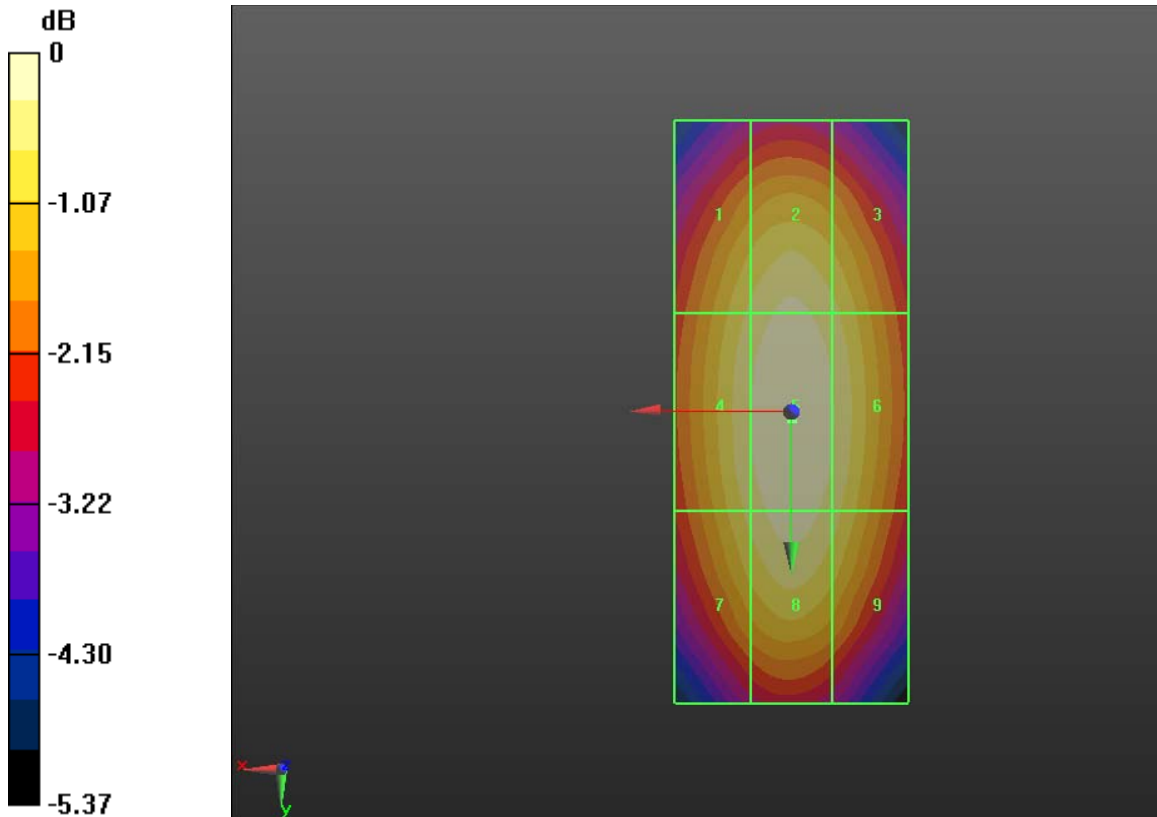
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.419 M2</b>	Grid 2 <b>0.436 M2</b>	Grid 3 <b>0.420 M2</b>
Grid 4 <b>0.432 M2</b>	Grid 5 <b>0.451 M2</b>	Grid 6 <b>0.434 M2</b>
Grid 7 <b>0.421 M2</b>	Grid 8 <b>0.442 M2</b>	Grid 9 <b>0.423 M2</b>

**Cursor:**

Total = 0.451 A/m  
 H Category: M2  
 Location: 0, 0.5, 4.7 mm



0 dB = 0.450A/m

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Date/Time: 3/23/2011 1:03:25 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_PMF\_GSM\_1880 MHz**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: GSM 1900; Frequency: 1880 MHz; Communication System PAR: 9.191 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.099 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.105 A/m; Power Drift = 0.04 dB

**Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

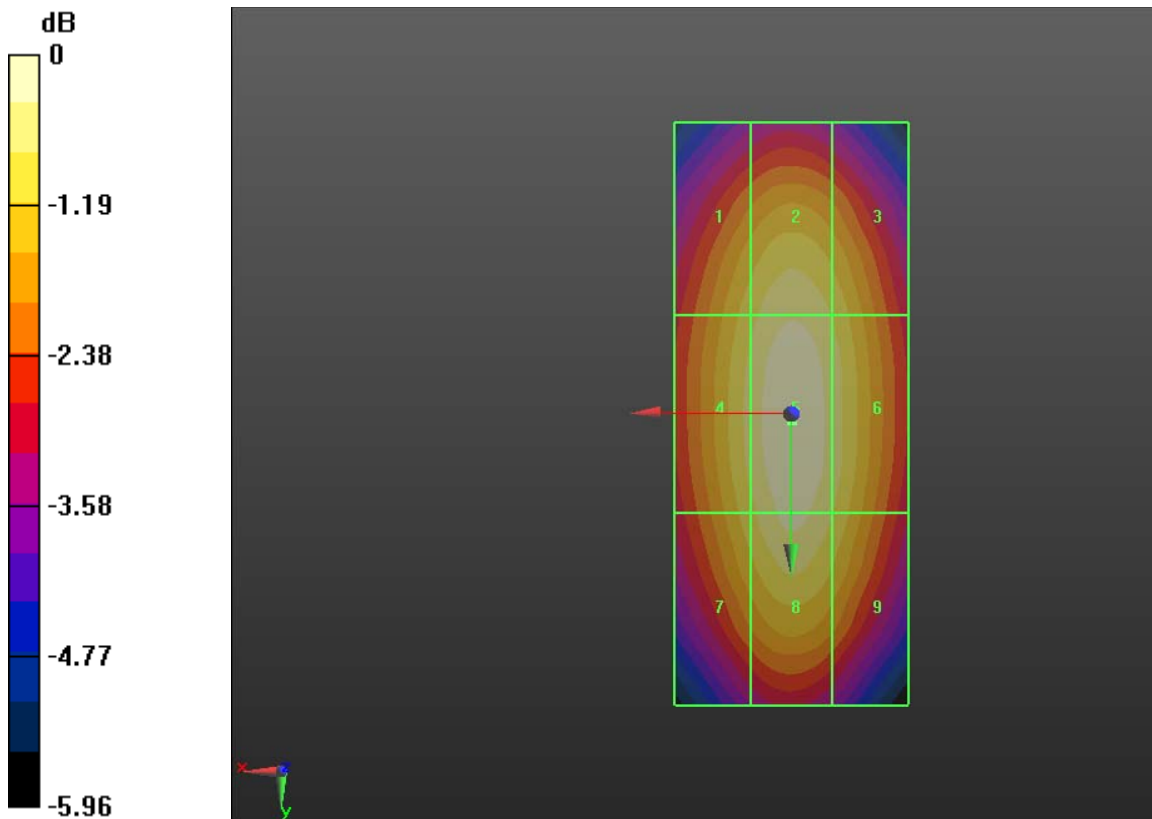
	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>76 (187)</b>
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Peak H-field in A/m


Grid 1 <b>0.090 M4</b>	Grid 2 <b>0.095 M4</b>	Grid 3 <b>0.091 M4</b>
Grid 4 <b>0.093 M4</b>	Grid 5 <b>0.099 M4</b>	Grid 6 <b>0.094 M4</b>
Grid 7 <b>0.090 M4</b>	Grid 8 <b>0.097 M4</b>	Grid 9 <b>0.091 M4</b>

**Cursor:**

Total = 0.099 A/m  
 H Category: M4  
 Location: 0, 0.5, 4.7 mm



0 dB = 0.100A/m

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Date/Time: 3/23/2011 12:41:56 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_PMF\_CW1880 MHz\_GSM**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.284 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.302 A/m; Power Drift = -0.03 dB

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

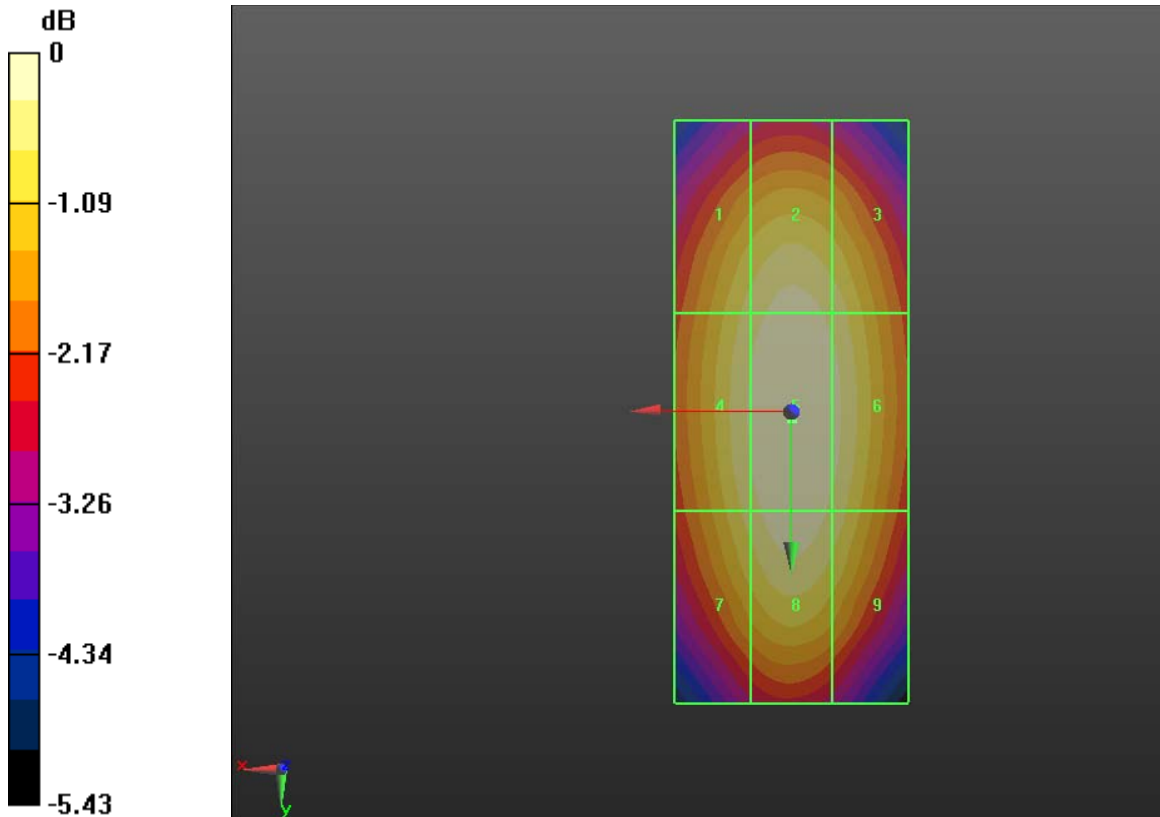
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.263 M3</b>	Grid 2 <b>0.274 M3</b>	Grid 3 <b>0.265 M3</b>
Grid 4 <b>0.271 M3</b>	Grid 5 <b>0.284 M3</b>	Grid 6 <b>0.274 M3</b>
Grid 7 <b>0.263 M3</b>	Grid 8 <b>0.278 M3</b>	Grid 9 <b>0.266 M3</b>

**Cursor:**

Total = 0.284 A/m  
 H Category: M3  
 Location: 0, 0.5, 4.7 mm



0 dB = 0.280A/m

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Date/Time: 3/23/2011 12:51:39 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_PMF\_AM80%1880 MHz\_GSM**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: AM 80%; Communication System Band: D1900 (1900.0 MHz);  
Frequency: 1880 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: TCoil Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.184 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

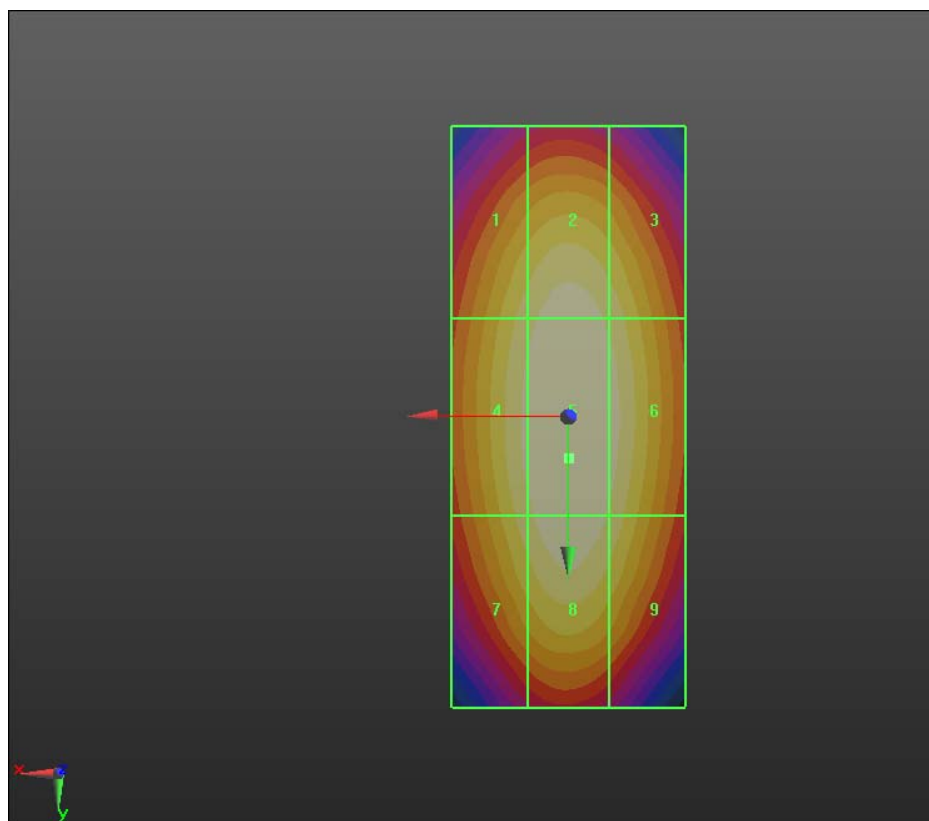
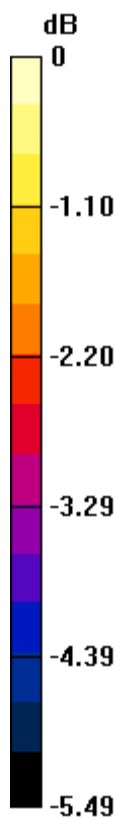
Reference Value = 0.196 A/m; Power Drift = -0.02 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak H-field in A/m

Grid 1 <b>0.170 M4</b>	Grid 2 <b>0.178 M4</b>	Grid 3 <b>0.171 M4</b>
Grid 4 <b>0.175 M4</b>	Grid 5 <b>0.184 M4</b>	Grid 6 <b>0.177 M4</b>
Grid 7 <b>0.170 M4</b>	Grid 8 <b>0.180 M4</b>	Grid 9 <b>0.172 M4</b>



0 dB = 0.180A/m



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Date/Time: 3/23/2011 1:10:44 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_PMF\_CDMA\_1880 MHz**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: CDMA 1900; Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.154 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.165 A/m; Power Drift = -0.02 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A**  
**RTS-2580-1106-36**

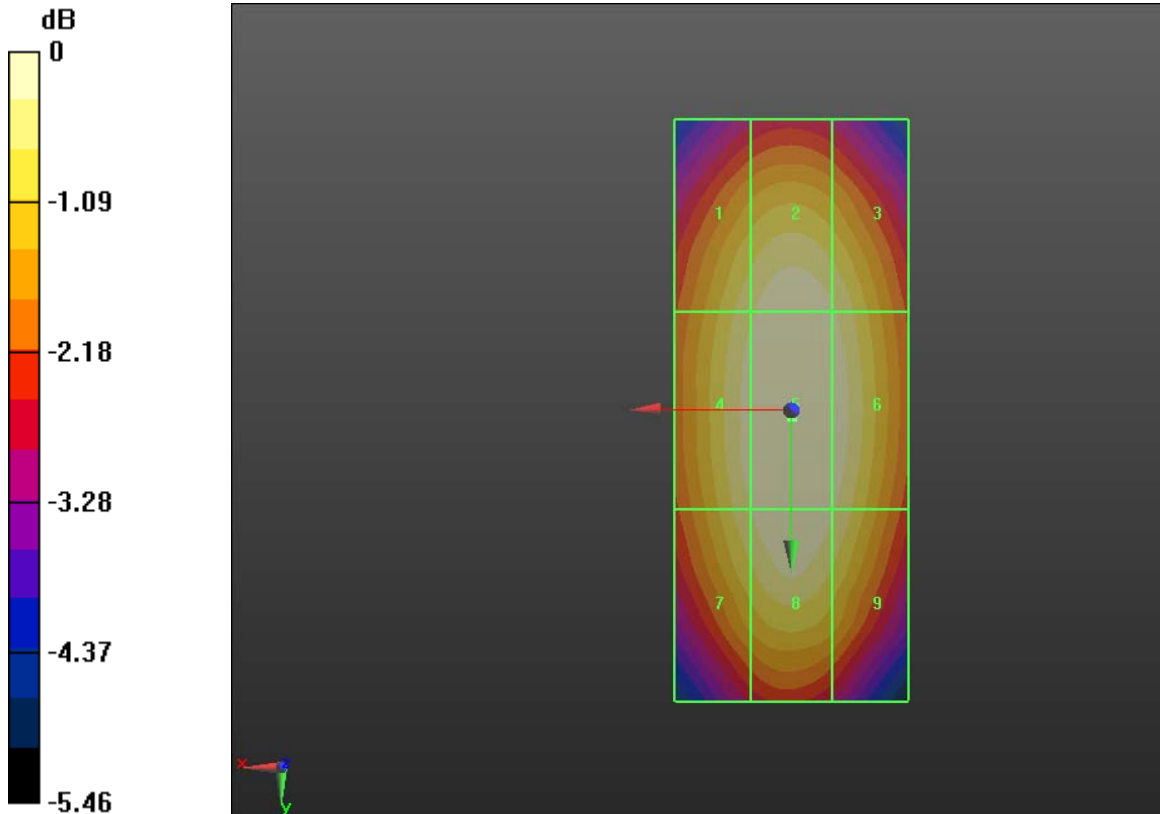
FCC ID  
**L6ARDU70CW**  
**L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.143 M4</b>	Grid 2 <b>0.150 M4</b>	Grid 3 <b>0.145 M4</b>
Grid 4 <b>0.147 M4</b>	Grid 5 <b>0.154 M4</b>	Grid 6 <b>0.149 M4</b>
Grid 7 <b>0.144 M4</b>	Grid 8 <b>0.152 M4</b>	Grid 9 <b>0.145 M4</b>

**Cursor:**

Total = 0.154 A/m  
H Category: M4  
Location: 0, 0.5, 4.7 mm



0 dB = 0.150A/m

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Date/Time: 3/23/2011 12:37:44 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_PMF\_CW1880 MHz\_CDMA**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.161 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.170 A/m; Power Drift = 0.03 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

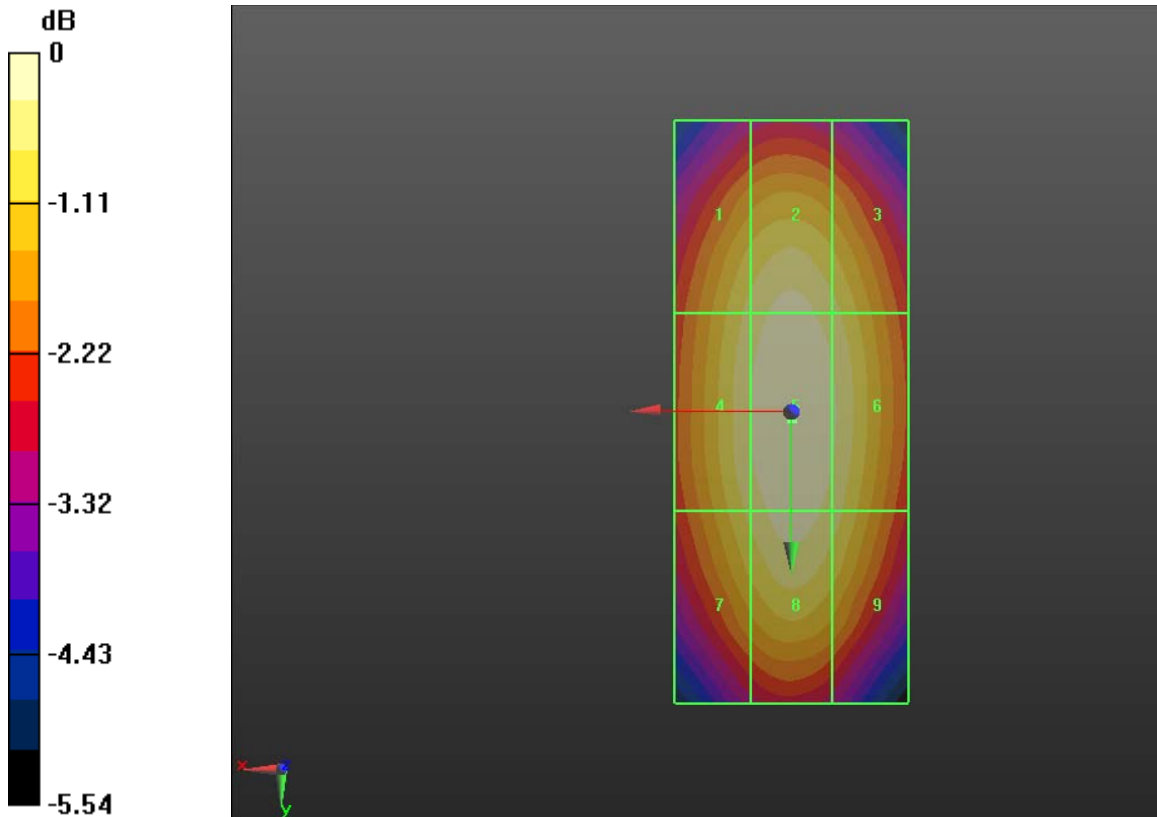
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.149 M4</b>	Grid 2 <b>0.156 M4</b>	Grid 3 <b>0.149 M4</b>
Grid 4 <b>0.153 M4</b>	Grid 5 <b>0.161 M4</b>	Grid 6 <b>0.155 M4</b>
Grid 7 <b>0.149 M4</b>	Grid 8 <b>0.157 M4</b>	Grid 9 <b>0.150 M4</b>

**Cursor:**

Total = 0.161 A/m  
 H Category: M4  
 Location: 0, 0.5, 4.7 mm



0 dB = 0.160A/m

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Date/Time: 3/23/2011 12:55:35 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_PMF\_AM80%1880 MHz\_CDMA**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: AM 80%; Communication System Band: D1900 (1900.0 MHz);  
Frequency: 1880 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: TCoil Section  
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.102 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.108 A/m; Power Drift = 0.06 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

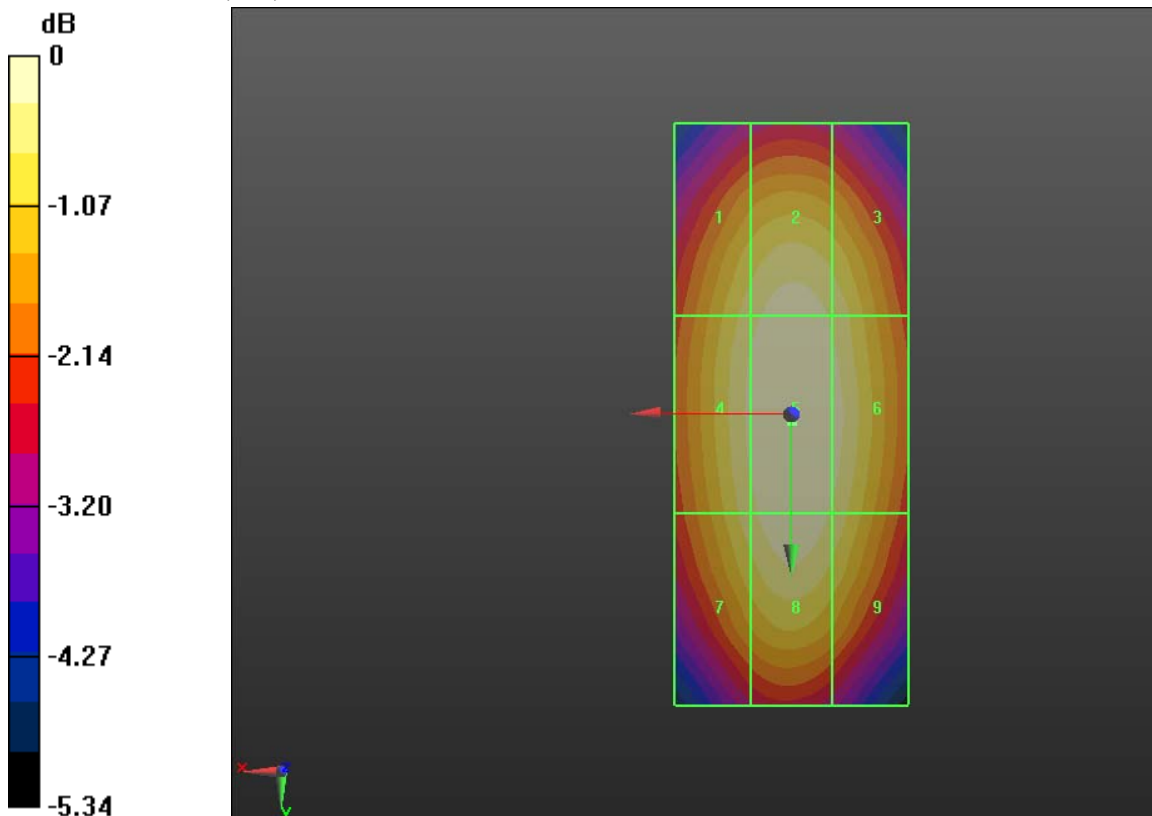
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Peak H-field in A/m


Grid 1 <b>0.094 M4</b>	Grid 2 <b>0.099 M4</b>	Grid 3 <b>0.095 M4</b>
Grid 4 <b>0.097 M4</b>	Grid 5 <b>0.102 M4</b>	Grid 6 <b>0.098 M4</b>
Grid 7 <b>0.095 M4</b>	Grid 8 <b>0.100 M4</b>	Grid 9 <b>0.095 M4</b>

**Cursor:**

Total = 0.102 A/m  
 H Category: M4  
 Location: 0, 0.5, 4.7 mm



0 dB = 0.100A/m

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Date/Time: 2/28/2011 1:07:46 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_PMF\_UMTS\_band\_V\_835 MHz**

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: WCDMA FDD V;; Frequency: 835 MHz; Communication System  
PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(5x37x1):** Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 42.995 V/m; Power Drift = 0.01 dB


Maximum value of Total (measured) = 56.244 V/m

Date/Time: 2/28/2011 1:07:46 PM

Test Laboratory: RIM Testing Services

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

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Communication System: WCDMA FDD V; Communication System Band:; Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):** Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 56.944 V/m  
Probe Modulation Factor = 1.000  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 42.995 V/m; Power Drift = 0.01 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak E-field in V/m

Grid 1 <b>53.505 M4</b>	Grid 2 <b>56.944 M4</b>	Grid 3 <b>56.718 M4</b>
Grid 4 <b>30.372 M4</b>	Grid 5 <b>31.039 M4</b>	Grid 6 <b>30.245 M4</b>
Grid 7 <b>54.971 M4</b>	Grid 8 <b>56.115 M4</b>	Grid 9 <b>54.501 M4</b>

**Cursor:**

Total = 56.944 V/m  
E Category: M4  
Location: -2.5, -79.5, 4.7 mm





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RDU71CW/RDE71UW**

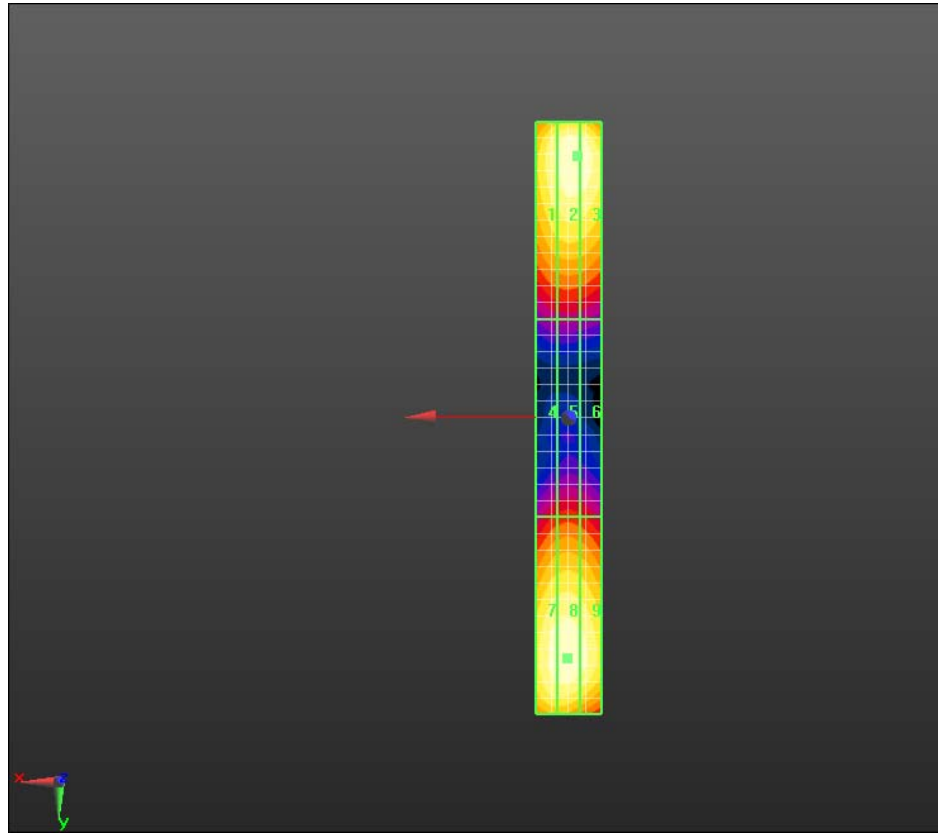
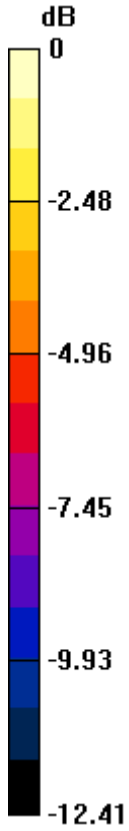
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Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
L6ARDE70UW**



0 dB = 56.940V/m

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Date/Time: 2/28/2011 12:43:40 PM

Test Laboratory: RIM Testing Services

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x361x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 57.608 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 42.622 V/m; Power Drift = -0.06 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**



Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
L6ARDE70UW**

Peak E-field in V/m

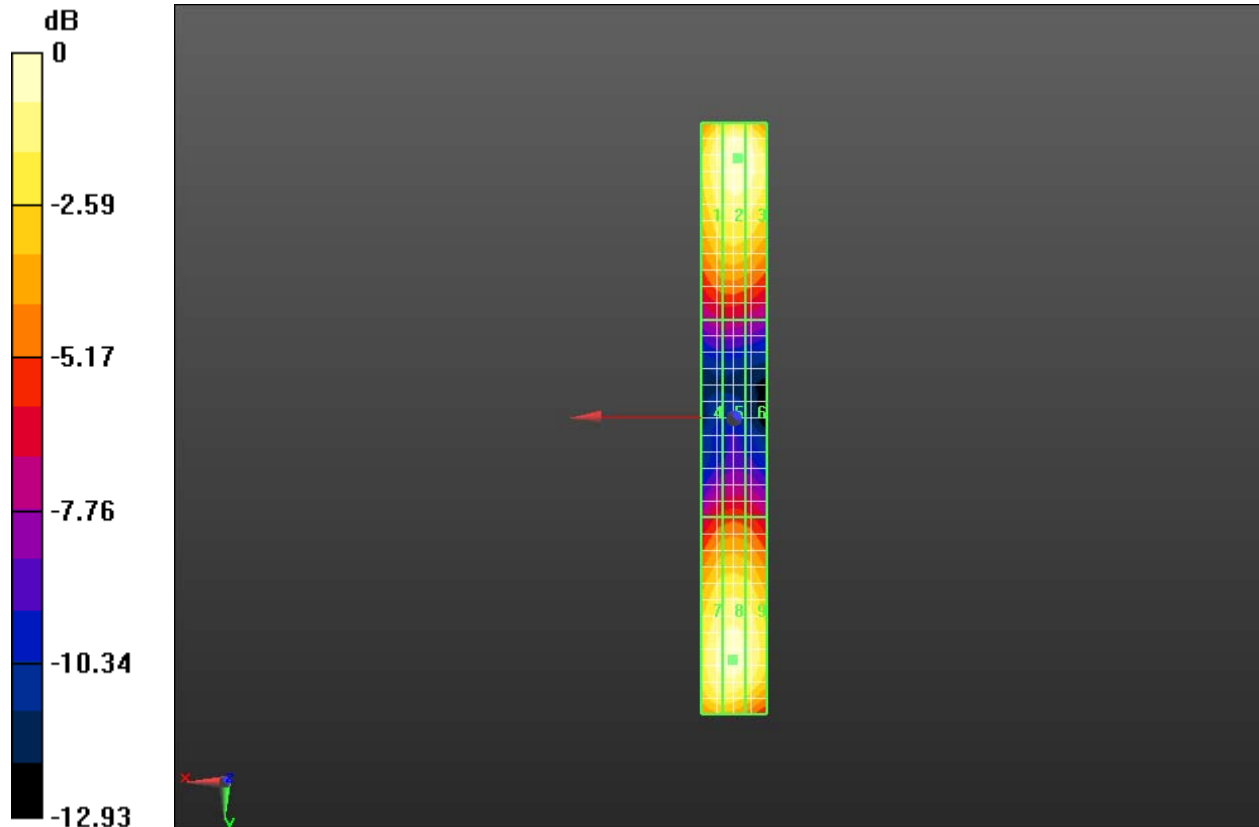
Grid 1 <b>54.388 M4</b>	Grid 2 <b>57.608 M4</b>	Grid 3 <b>56.620 M4</b>
Grid 4 <b>30.355 M4</b>	Grid 5 <b>30.943 M4</b>	Grid 6 <b>30.261 M4</b>
Grid 7 <b>54.334 M4</b>	Grid 8 <b>55.102 M4</b>	Grid 9 <b>5076 M4</b>

**Cursor:**


Total = 57.608 V/m

E Category: M4

Location: -1, -79, 4.7 mm



0 dB = 57.610V/m

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Date/Time: 2/28/2011 12:54:03 PM

Test Laboratory: RIM Testing Services

**DUT: HAC-Dipole 835 MHz; Type: D835V3**

Communication System: AM 80%; Communication System Band: D835 (835.0 MHz);  
Frequency: 835 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x361x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 37.106 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 26.469 V/m; Power Drift = 0.17 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak E-field in V/m

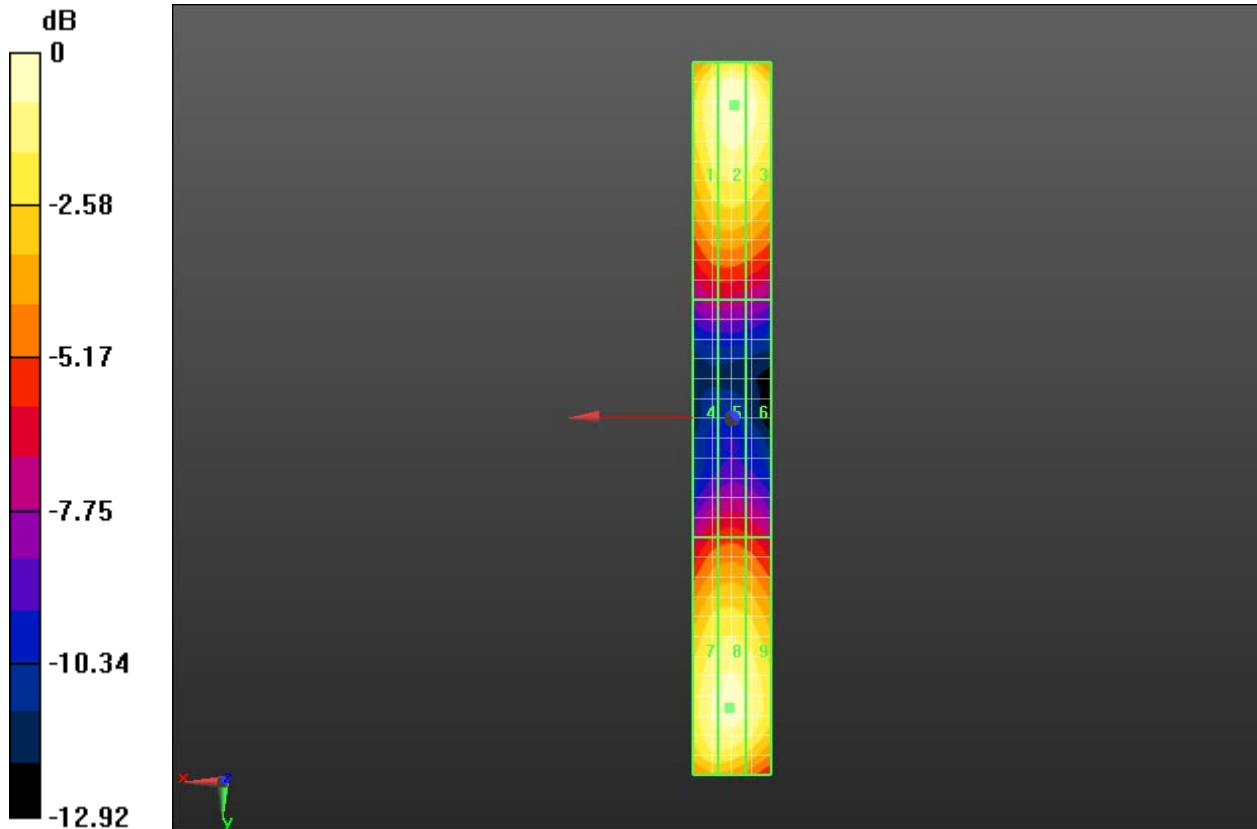
Grid 1 <b>35.158 M4</b>	Grid 2 <b>37.106 M4</b>	Grid 3 <b>36.227 M4</b>
Grid 4 <b>19.445 M4</b>	Grid 5 <b>19.878 M4</b>	Grid 6 <b>19.259 M4</b>
Grid 7 <b>34.812 M4</b>	Grid 8 <b>35.203 M4</b>	Grid 9 <b>34.158 M4</b>

**Cursor:**


Total = 37.106 V/m

E Category: M4

Location: -0.5, -79, 4.7 mm



0 dB = 37.110V/m

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Date/Time: 2/28/2011 2:07:15 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_PMF\_UMTS\_band\_II\_1880 MHz**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial**

Communication System: WCDMA FDD II;.; Frequency: 1880 MHz;Communication System  
PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 38.483 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 35.028 V/m; Power Drift = 0.10 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A**  
**RTS-2580-1106-36**

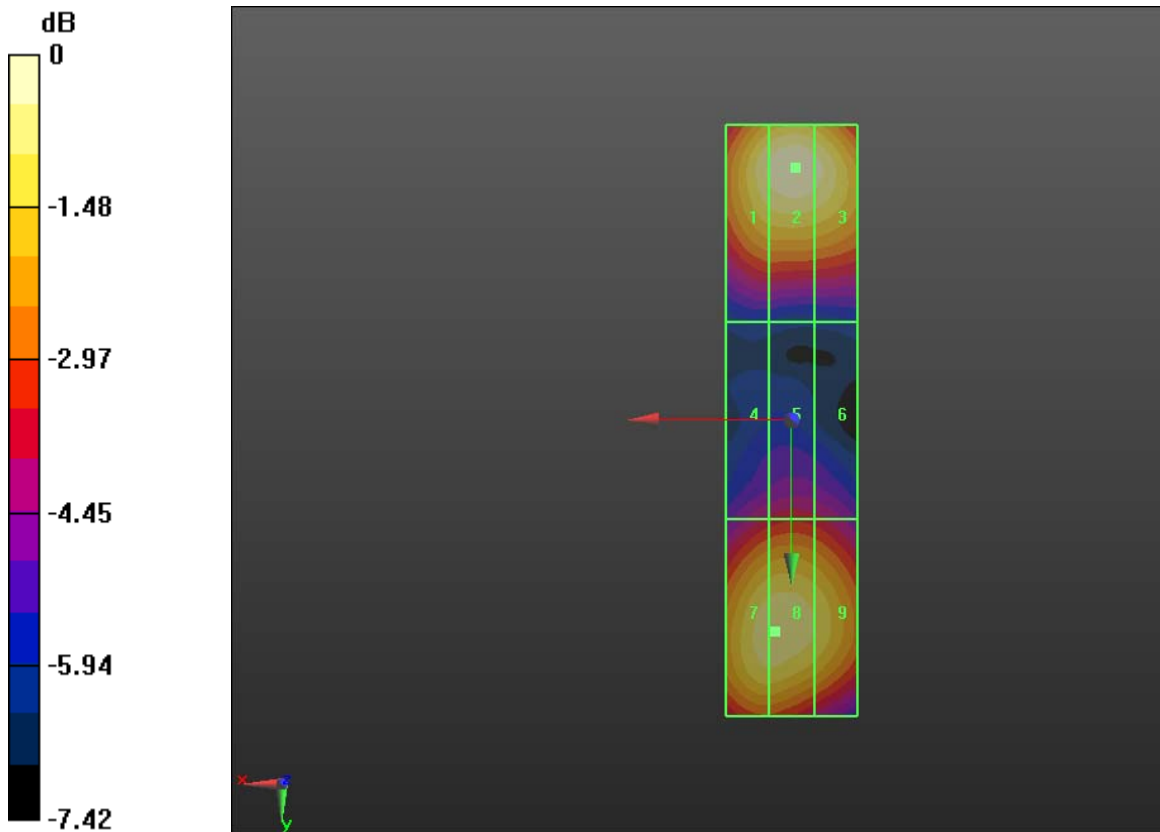
FCC ID  
**L6ARDU70CW**  
**L6ARDE70UW**

Peak E-field in V/m


Grid 1 <b>36.706 M4</b>	Grid 2 <b>38.483 M4</b>	Grid 3 <b>37.337 M4</b>
Grid 4 <b>24.878 M4</b>	Grid 5 <b>25.643 M4</b>	Grid 6 <b>25.076 M4</b>
Grid 7 <b>35.871 M4</b>	Grid 8 <b>35.988 M4</b>	Grid 9 <b>34.479 M4</b>

**Cursor:**

Total = 38.483 V/m  
 E Category: M4  
 Location: -0.5, -38.5, 4.7 mm



0 dB = 38.480V/m

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Date/Time: 2/28/2011 2:16:59 PM

Test Laboratory: RIM Testing Services

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 43.024 V/m


Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 38.861 V/m; Power Drift = 0.02 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**



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Peak E-field in V/m

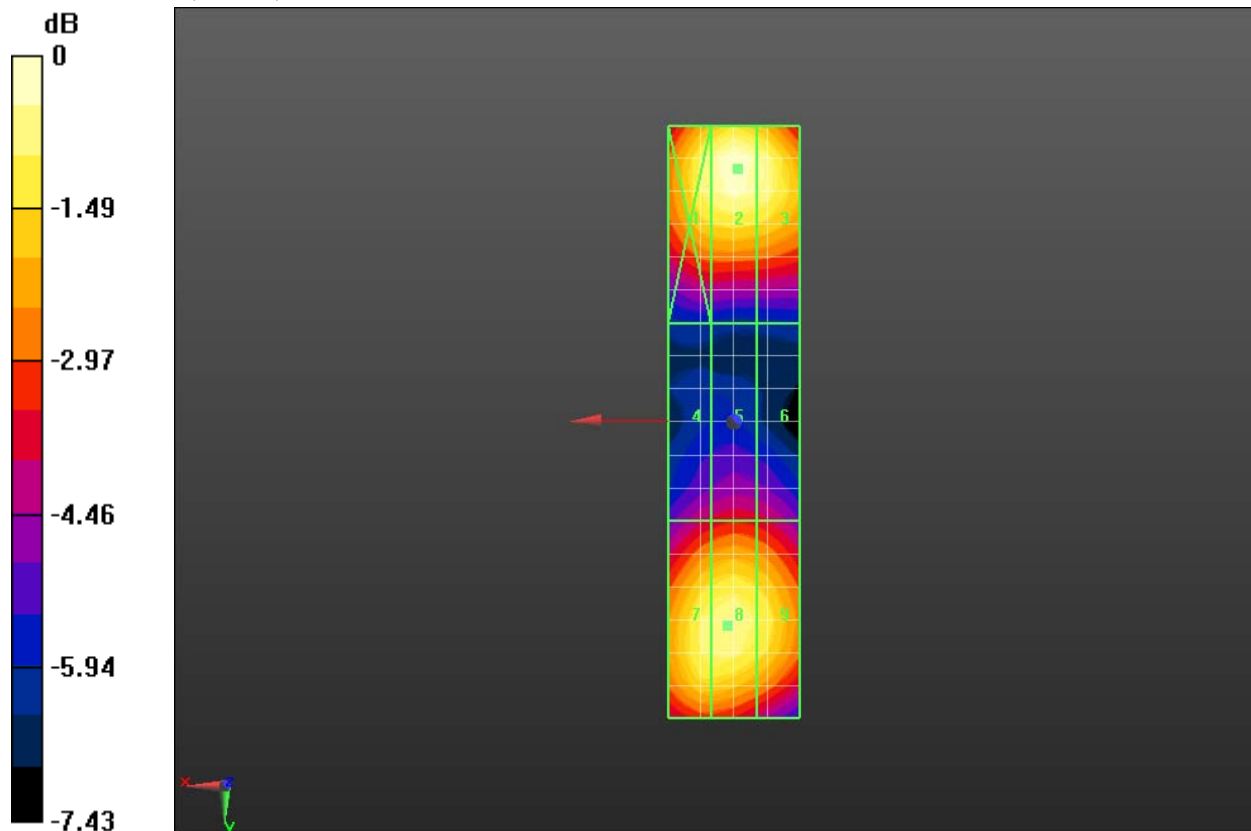
Grid 1 <b>40.897 M4</b>	Grid 2 <b>43.024 M4</b>	Grid 3 <b>41.671 M4</b>
Grid 4 <b>27.919 M4</b>	Grid 5 <b>28.886 M4</b>	Grid 6 <b>28.274 M4</b>
Grid 7 <b>39.759 M4</b>	Grid 8 <b>40.082 M4</b>	Grid 9 <b>38.641 M4</b>

**Cursor:**


Total = 43.024 V/m

E Category: M4

Location: -0.5, -38.5, 4.7 mm



0 dB = 43.020V/m

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Date/Time: 2/28/2011 2:21:55 PM

Test Laboratory: RIM Testing Services

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: AM 80%; Communication System Band: D1900 (1900.0 MHz);  
Frequency: 1880 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test**

**(41x181x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 27.543 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 25.024 V/m; Power Drift = -0.0069 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

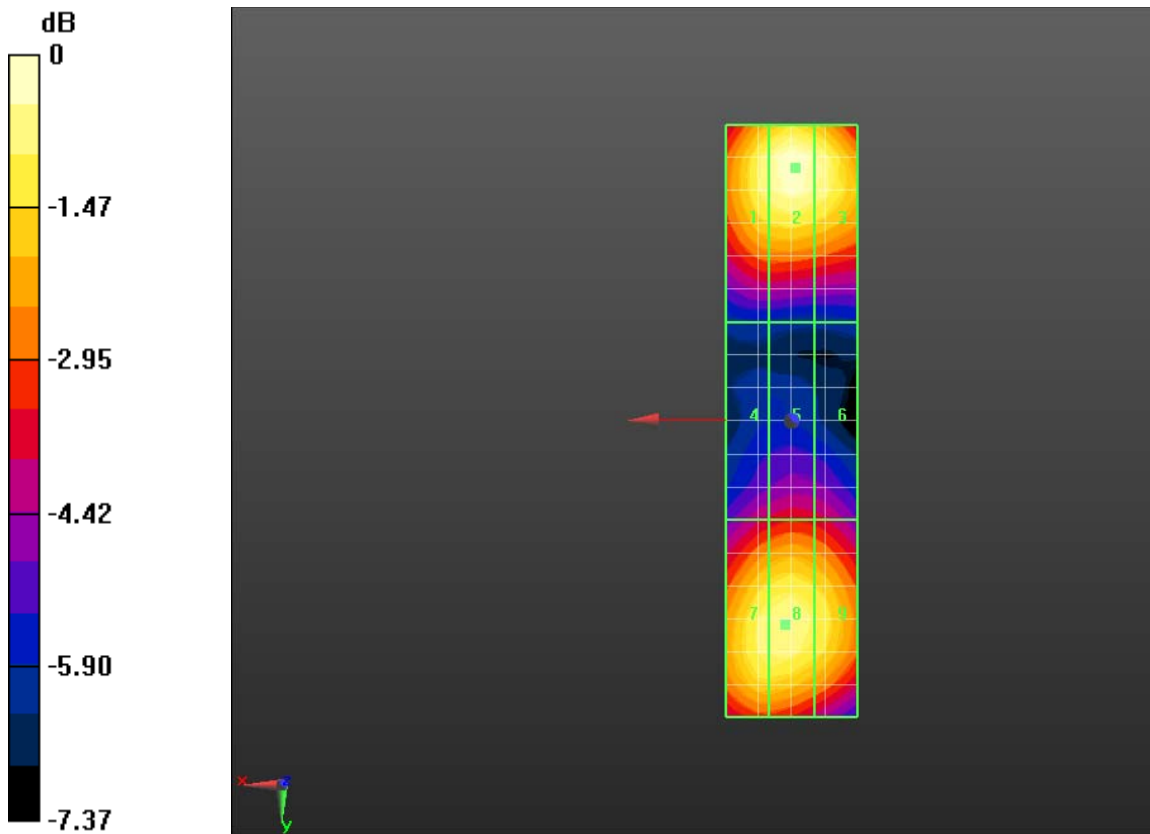
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Peak E-field in V/m


Grid 1 <b>26.151 M4</b>	Grid 2 <b>27.543 M4</b>	Grid 3 <b>26.639 M4</b>
Grid 4 <b>17.904 M4</b>	Grid 5 <b>18.574 M4</b>	Grid 6 <b>18.189 M4</b>
Grid 7 <b>25.506 M4</b>	Grid 8 <b>25.701 M4</b>	Grid 9 <b>24.770 M4</b>

Cursor:

Total = 27.543 V/m  
 E Category: M4  
 Location: -0.5, -38.5, 4.7 mm



0 dB = 27.540V/m

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Date/Time: 2/28/2011 2:57:08 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_PMF\_UMTS\_band II\_1880 MHz**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: WCDMA FDD II; Communication System Band:; Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.138 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.147 A/m; Power Drift = 0.04 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak H-field in A/m

Grid 1 <b>0.127 M4</b>	Grid 2 <b>0.134 M4</b>	Grid 3 <b>0.128 M4</b>
Grid 4 <b>0.132 M4</b>	Grid 5 <b>0.138 M4</b>	Grid 6 <b>0.132 M4</b>
Grid 7 <b>0.129 M4</b>	Grid 8 <b>0.136 M4</b>	Grid 9 <b>0.127 M4</b>

**Cursor:**

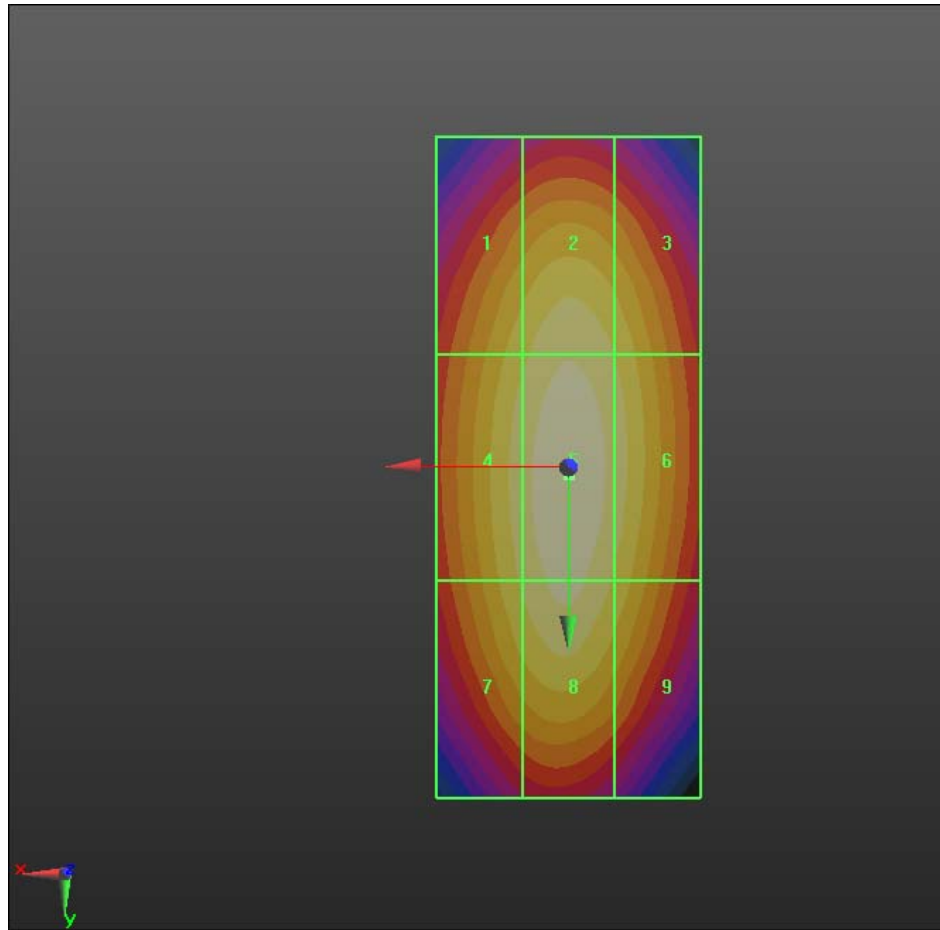
Total = 0.138 A/m  
H Category: M4  
Location: 0, 0.5, 4.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 0.140A/m

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Date/Time: 3/23/2011 1:10:44 PM

Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_PMF\_CDMA\_1880 MHz**

**DUT: HAC Dipole 1880 MHz; Type: CD1880V3**

Communication System: CDMA 1900; Communication System Band: Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid**

**Compatibility Test (41x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.154 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.165 A/m; Power Drift = -0.02 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A**  
**RTS-2580-1106-36**

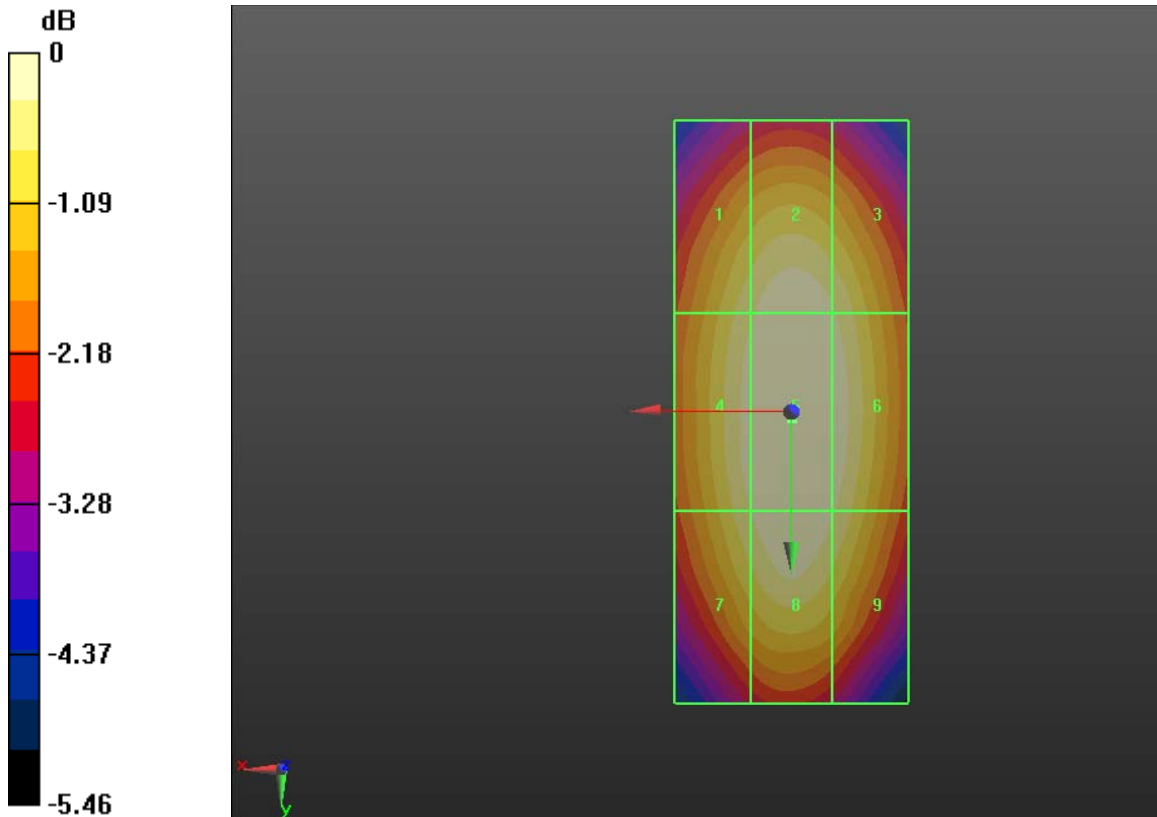
FCC ID  
**L6ARDU70CW**  
**L6ARDE70UW**

Peak H-field in A/m

Grid 1 <b>0.143 M4</b>	Grid 2 <b>0.150 M4</b>	Grid 3 <b>0.145 M4</b>
Grid 4 <b>0.147 M4</b>	Grid 5 <b>0.154 M4</b>	Grid 6 <b>0.149 M4</b>
Grid 7 <b>0.144 M4</b>	Grid 8 <b>0.152 M4</b>	Grid 9 <b>0.145 M4</b>


**Cursor:**

Total = 0.154 A/m  
H Category: M4  
Location: 0, 0.5, 4.7 mm




0 dB = 0.150A/m



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### A.3 RF emission field plots

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Date/Time: 3/23/2011 4:33:26 PM, Date/Time: 3/23/2011 4:38:37 PM, Date/Time: 3/23/2011 4:43:10 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_GSM 850**

**DUT: BlackBerry Smartphone; Type: Sample**


Communication System: GSM 850; .; Frequency: 824.2 MHz, Frequency: 836.8 MHz, Frequency: 848.8 MHz; Communication System PAR: 9.191 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 140.3 V/m  
Probe Modulation Factor = 2.940  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 53.962 V/m; Power Drift = -0.12 dB  
**Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

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Peak E-field in V/m

Grid 1 <b>118.0 M4</b>	Grid 2 <b>136.7 M4</b>	Grid 3 <b>131.6 M4</b>
Grid 4 <b>121.5 M4</b>	Grid 5 <b>140.3 M4</b>	Grid 6 <b>134.4 M4</b>
Grid 7 <b>122.9 M4</b>	Grid 8 <b>139.4 M4</b>	Grid 9 <b>133.1 M4</b>

**Cursor:**

Total = 140.3 V/m  
E Category: M4  
Location: -3, -2.5, 8.7 mm

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007:  
15 mm from Probe Center to the Device 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 154.3 V/m

Probe Modulation Factor = 2.940


Device Reference Point: 0, 0, -6.3 mm

Reference Value = 59.107 V/m; Power Drift = 0.19 dB

**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak E-field in V/m

Grid 1 <b>116.8 M4</b>	Grid 2 <b>150.4 M3</b>	Grid 3 <b>150.5 M3</b>
Grid 4 <b>121.9 M4</b>	Grid 5 <b>154.3 M3</b>	Grid 6 <b>154.3 M3</b>
Grid 7 <b>128.6 M4</b>	Grid 8 <b>154.4 M3</b>	Grid 9 <b>154.4 M3</b>

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**Cursor:**

Total = 154.4 V/m  
E Category: M3  
Location: -8.5, 13.5, 8.7 mm

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007:  
15 mm from Probe Center to the Device 2 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 165.7 V/m

Probe Modulation Factor = 2.940

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 64.371 V/m; Power Drift = -0.34 dB

**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

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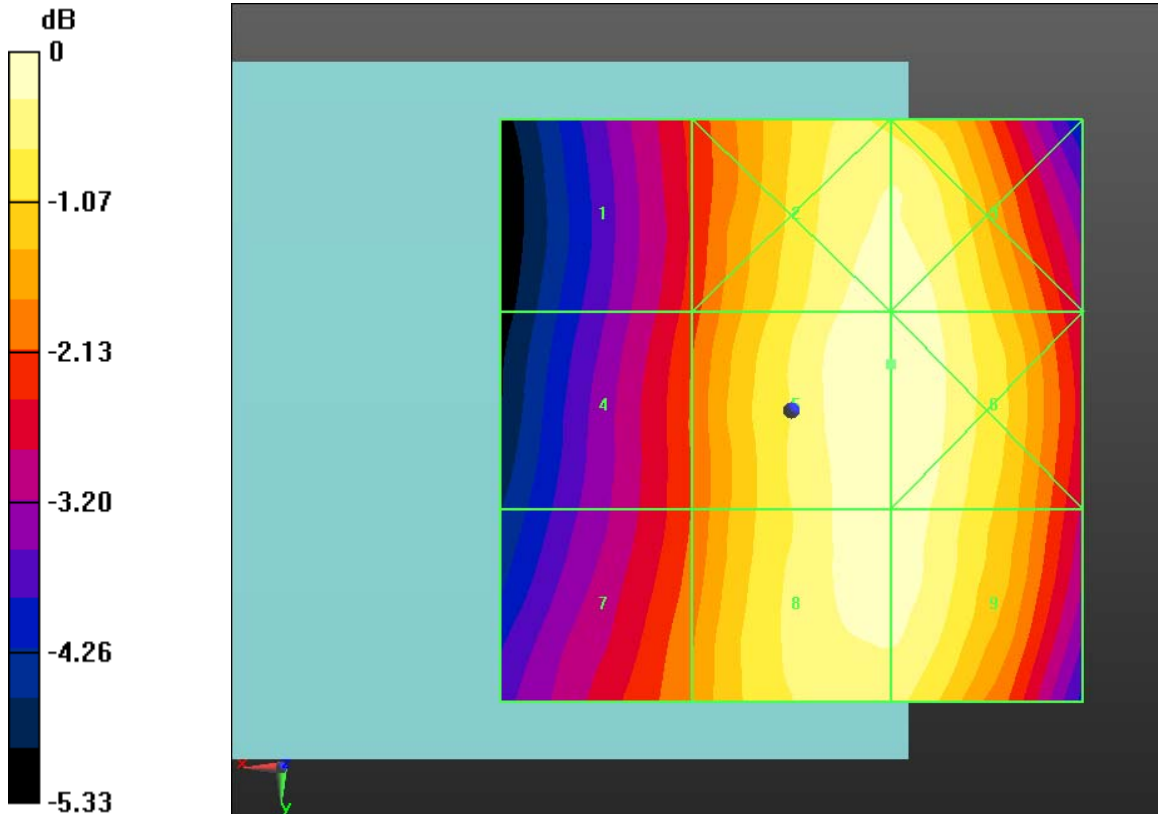
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak E-field in V/m


Grid 1 <b>127.5 M4</b>	Grid 2 <b>164.1 M3</b>	Grid 3 <b>164.1 M3</b>
Grid 4 <b>130.7 M4</b>	Grid 5 <b>165.7 M3</b>	Grid 6 <b>165.7 M3</b>
Grid 7 <b>135.6 M4</b>	Grid 8 <b>162.9 M3</b>	Grid 9 <b>162.9 M3</b>

**Cursor:**

Total = 165.7 V/m  
 E Category: M3  
 Location: -8.5, -4, 8.7 mm



0 dB = 165.7V/m

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Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_GSM 850\_high\_chan\_Telecoil**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: GSM 850; .; Frequency: 848.8 MHz; Communication System PAR: 9.191 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 159.4 V/m

Probe Modulation Factor = 2.940

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 64.183 V/m; Power Drift = -0.02 dB

**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Author Data  
**Daoud Attayi**

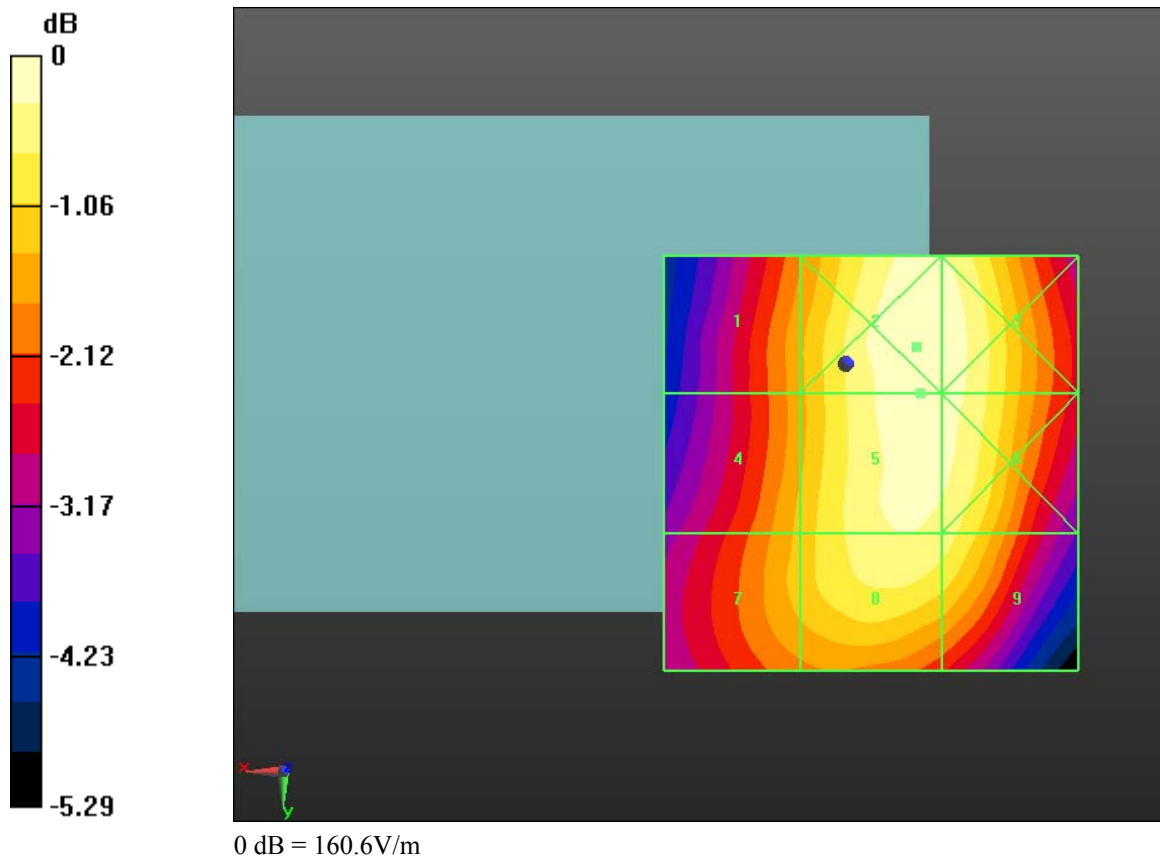
Dates of Test  
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 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak E-field in V/m

Grid 1 <b>135.7 M4</b>	Grid 2 <b>160.6 M3</b>	Grid 3 <b>159.1 M3</b>
Grid 4 <b>138.5 M4</b>	Grid 5 <b>159.4 M3</b>	Grid 6 <b>158.3 M3</b>
Grid 7 <b>139.4 M4</b>	Grid 8 <b>154.3 M3</b>	Grid 9 <b>151.6 M3</b>



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Date/Time: 3/23/2011 5:02:28 PM, Date/Time: 3/23/2011 5:06:54 PM, Date/Time: 3/23/2011 5:10:57 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_GSM1900**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: GSM 1900; .; Frequency: 1850.2 MHz, Frequency: 1880 MHz, Frequency: 1909.8 MHz; Communication System PAR: 9.191 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)


DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 73.806 V/m  
Probe Modulation Factor = 2.970  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 19.960 V/m; Power Drift = 0.19 dB  
**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**



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Peak E-field in V/m

Grid 1 <b>71.549 M3</b>	Grid 2 <b>58.794 M3</b>	Grid 3 <b>62.906 M3</b>
Grid 4 <b>63.524 M3</b>	Grid 5 <b>73.806 M3</b>	Grid 6 <b>77.966 M3</b>
Grid 7 <b>60.542 M3</b>	Grid 8 <b>83.257 M3</b>	Grid 9 <b>84.405 M2</b>

**Cursor:**

Total = 84.405 V/m  
E Category: M2  
Location: -12.5, 22.5, 8.7 mm

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007:  
15 mm from Probe Center to the Device 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 81.563 V/m

Probe Modulation Factor = 2.970


Device Reference Point: 0, 0, -6.3 mm

Reference Value = 21.360 V/m; Power Drift = 0.06 dB

**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak E-field in V/m

Grid 1 <b>68.321 M3</b>	Grid 2 <b>62.046 M3</b>	Grid 3 <b>66.802 M3</b>
Grid 4 <b>59.229 M3</b>	Grid 5 <b>81.563 M3</b>	Grid 6 <b>82.987 M3</b>
Grid 7 <b>64.252 M3</b>	Grid 8 <b>91.201 M2</b>	Grid 9 <b>91.215 M2</b>

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**Cursor:**

Total = 91.214 V/m  
E Category: M2  
Location: -9, 23.5, 8.7 mm

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007:  
15 mm from Probe Center to the Device 2 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 76.911 V/m

Probe Modulation Factor = 2.970

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 22.361 V/m; Power Drift = 0.27 dB

**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

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FCC ID  
**L6ARDU70CW  
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Peak E-field in V/m

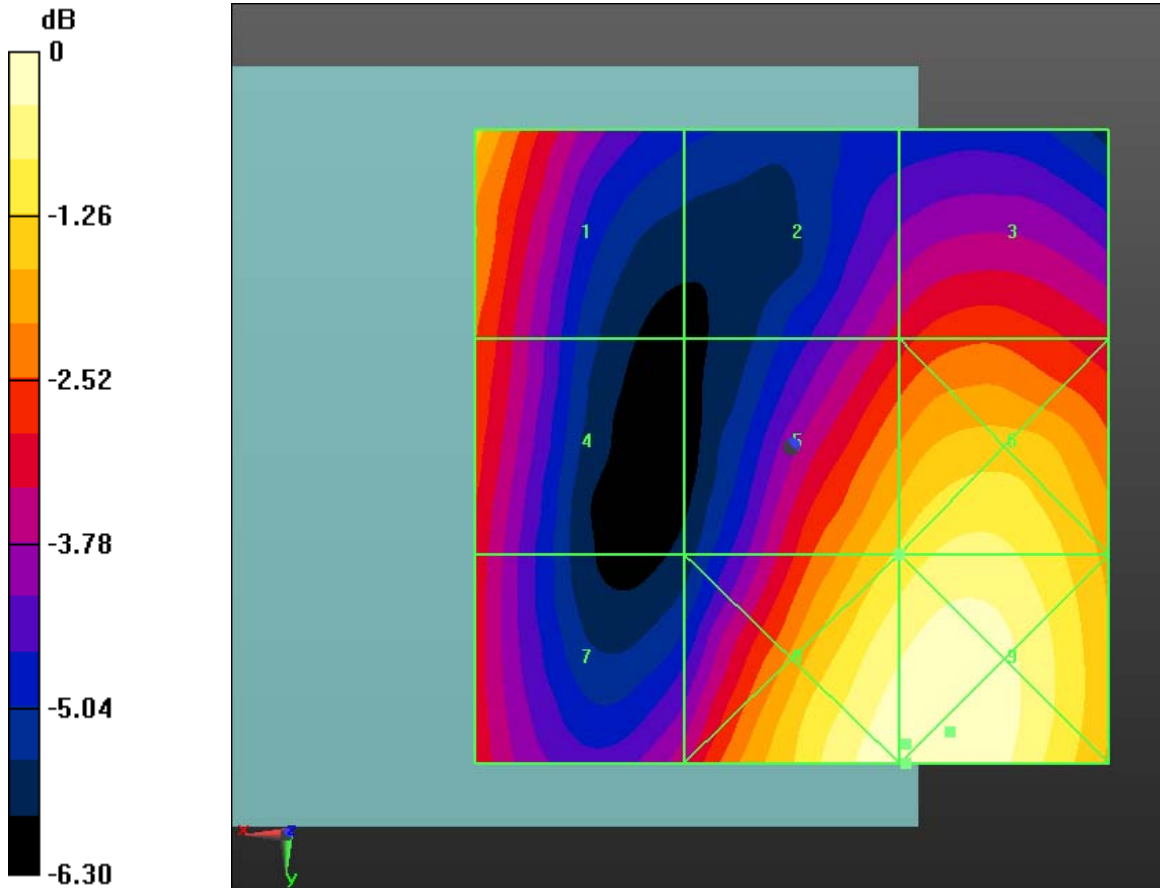
Grid 1 <b>63.086 M3</b>	Grid 2 <b>55.906 M3</b>	Grid 3 <b>58.028 M3</b>
Grid 4 <b>59.991 M3</b>	Grid 5 <b>76.911 M3</b>	Grid 6 <b>79.327 M3</b>
Grid 7 <b>68.615 M3</b>	Grid 8 <b>90.494 M2</b>	Grid 9 <b>90.499 M2</b>

**Cursor:**


Total = 90.499 V/m

E Category: M2

Location: -9, 25, 8.7 mm



0 dB = 84.400V/m

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Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_GSM1900\_telecoil**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: GSM 1900; .; Frequency: 1880 MHz; Communication System PAR: 9.191 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 81.717 V/m

Probe Modulation Factor = 2.970

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 16.233 V/m; Power Drift = 0.73 dB

**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

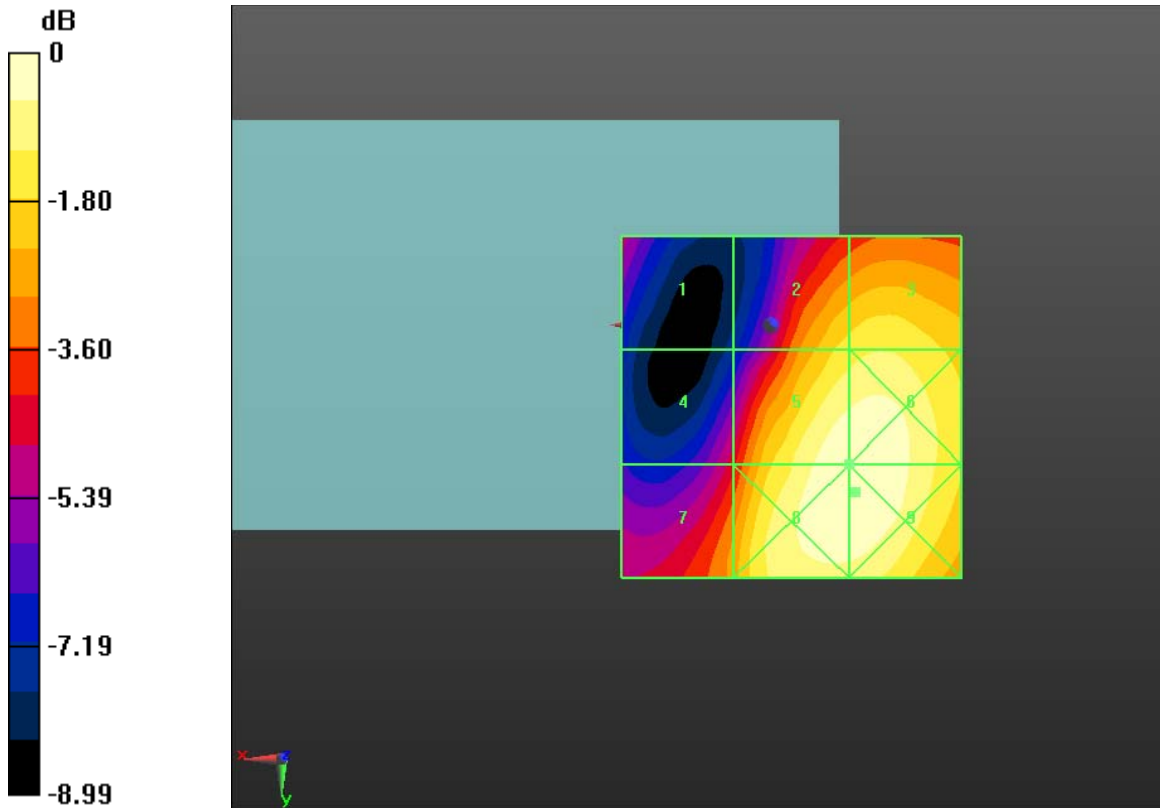
Peak E-field in V/m

Grid 1 <b>46.664 M4</b>	Grid 2 <b>69.198 M3</b>	Grid 3 <b>71.497 M3</b>
Grid 4 <b>50.027 M3</b>	Grid 5 <b>81.717 M3</b>	Grid 6 <b>82.056 M3</b>
Grid 7 <b>60.503 M3</b>	Grid 8 <b>82.292 M3</b>	Grid 9 <b>82.376 M3</b>


-5 < 149.6 < 0.45

**Cursor:**

Total = 82.376 V/m  
 E Category: M3  
 Location: -12.5, 24.5, 8.7 mm



0 dB = 82.380V/m

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Date/Time: 3/23/2011 5:31:24 PM, Date/Time: 3/23/2011 5:34:58 PM, Date/Time: 3/23/2011 5:38:34 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_CDMA800**

**DUT: BlackBerry Smartphone; Type: Sample**


Communication System: CDMA 800; .; Frequency: 824.7 MHz, Frequency: 836.52 MHz, Frequency: 848.52 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 58.257 V/m  
Probe Modulation Factor = 0.990  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 70.405 V/m; Power Drift = 0.08 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>48.315 M4</b>	Grid 2 <b>57.299 M4</b>	Grid 3 <b>57.331 M4</b>
Grid 4 <b>49.702 M4</b>	Grid 5 <b>58.257 M4</b>	Grid 6 <b>58.257 M4</b>
Grid 7 <b>51.212 M4</b>	Grid 8 <b>57.631 M4</b>	Grid 9 <b>57.676 M4</b>

**Cursor:**

Total = 58.257 V/m  
E Category: M4  
Location: -8.5, -0.5, 8.7 mm

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007:  
15 mm from Probe Center to the Device 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 65.799 V/m

Probe Modulation Factor = 0.990


Device Reference Point: 0, 0, -6.3 mm

Reference Value = 78.501 V/m; Power Drift = -0.02 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak E-field in V/m

Grid 1 <b>50.455 M4</b>	Grid 2 <b>63.980 M4</b>	Grid 3 <b>64.048 M4</b>
Grid 4 <b>52.894 M4</b>	Grid 5 <b>65.799 M4</b>	Grid 6 <b>65.842 M4</b>
Grid 7 <b>56.196 M4</b>	Grid 8 <b>65.900 M4</b>	Grid 9 <b>65.942 M4</b>

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**Cursor:**

Total = 65.942 V/m  
E Category: M4  
Location: -9, 10, 8.7 mm

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007:  
15 mm from Probe Center to the Device 2 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 66.716 V/m

Probe Modulation Factor = 0.990

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 82.434 V/m; Power Drift = -0.11 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**



Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

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**RTS-3933-1104-55A  
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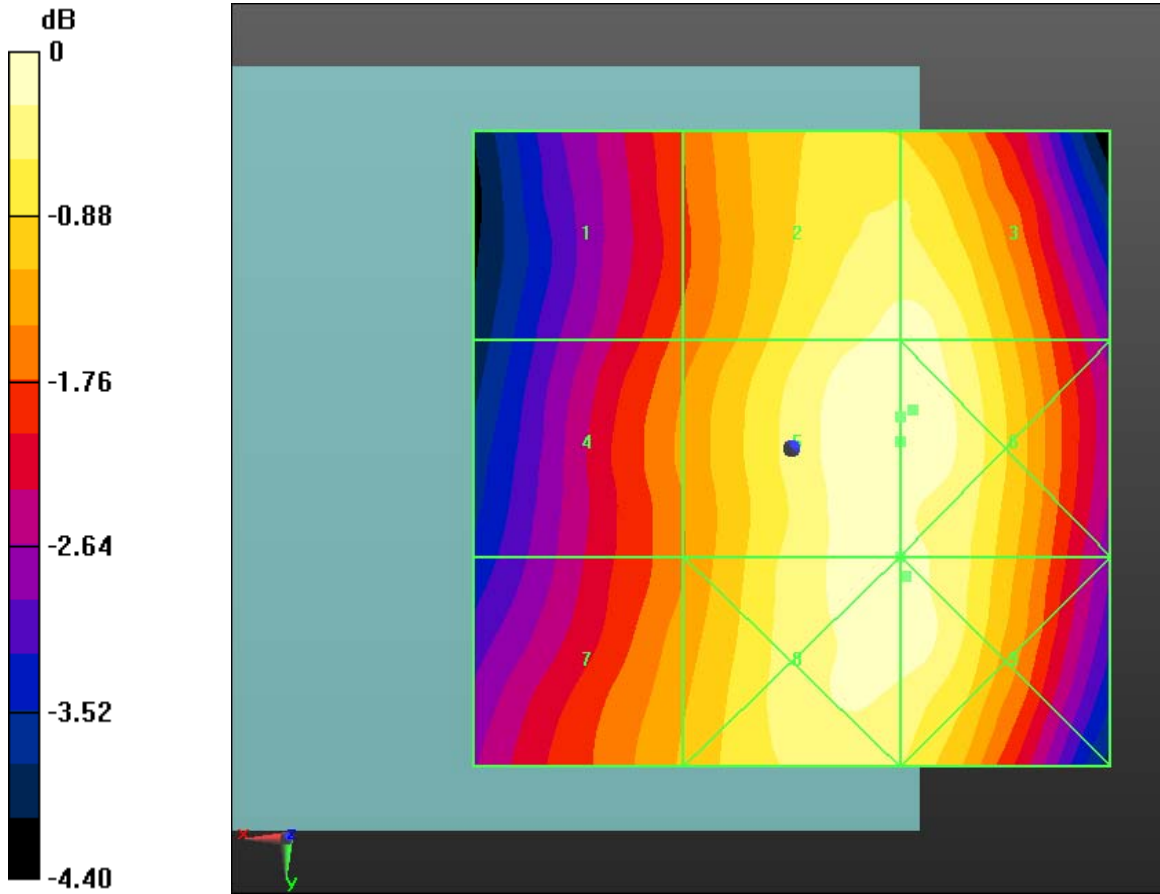
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak E-field in V/m


Grid 1 <b>53.873 M4</b>	Grid 2 <b>65.647 M4</b>	Grid 3 <b>65.743 M4</b>
Grid 4 <b>55.139 M4</b>	Grid 5 <b>66.716 M4</b>	Grid 6 <b>66.755 M4</b>
Grid 7 <b>56.044 M4</b>	Grid 8 <b>65.974 M4</b>	Grid 9 <b>65.987 M4</b>

**Cursor:**

Total = 66.755 V/m  
 E Category: M4  
 Location: -9.5, -3, 8.7 mm



0 dB = 58.260V/m

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Date/Time: 3/23/2011 5:43:48 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_CDMA800\_high\_chan\_Telecoil\_Center**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: CDMA 800; .; Frequency: 848.52 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 68.338 V/m

Probe Modulation Factor = 0.990

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 81.494 V/m; Power Drift = 0.08 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

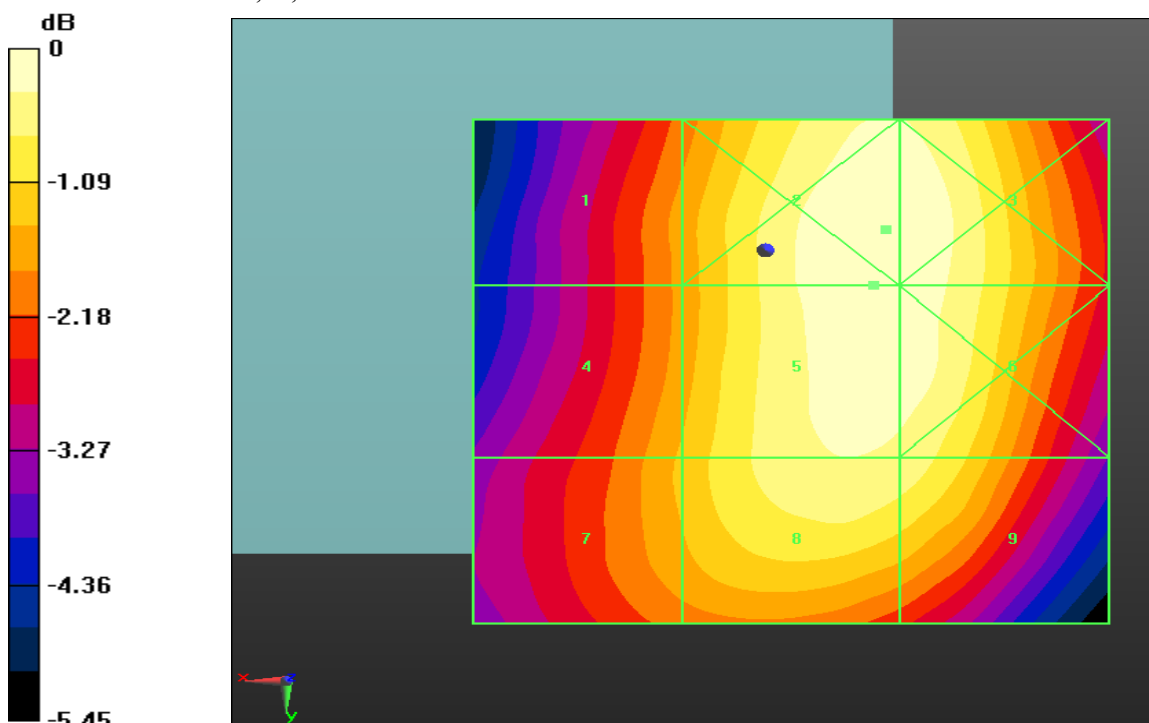
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Peak E-field in V/m


Grid 1 <b>57.179 M4</b>	Grid 2 <b>68.919 M4</b>	Grid 3 <b>68.863 M4</b>
Grid 4 <b>58.849 M4</b>	Grid 5 <b>68.338 M4</b>	Grid 6 <b>68.100 M4</b>
Grid 7 <b>59.002 M4</b>	Grid 8 <b>66.118 M4</b>	Grid 9 <b>65.449 M4</b>

**Cursor:**

Total = 68.919 V/m  
 E Category: M4  
 Location: -9.5, -2, 8.7 mm



0 dB = 68.920V/m

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Date/Time: 3/23/2011 6:02:17 PM, Date/Time: 3/23/2011 6:10:14 PM, Date/Time: 3/23/2011 6:26:17 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_CDMA1900**

#### **DUT: BlackBerry Smartphone; Type: Sample**


Communication System: CDMA 1900; .; Frequency: 1851.25 MHz, Frequency: 1880 MHz, Frequency: 1908.5 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

#### DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

#### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 38.833 V/m  
Probe Modulation Factor = 1.060  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 31.653 V/m; Power Drift = -0.27 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>34.416 M4</b>	Grid 2 <b>31.153 M4</b>	Grid 3 <b>33.214 M4</b>
Grid 4 <b>31.627 M4</b>	Grid 5 <b>38.833 M4</b>	Grid 6 <b>40.747 M4</b>
Grid 7 <b>32.684 M4</b>	Grid 8 <b>43.564 M4</b>	Grid 9 <b>43.739 M4</b>

**Cursor:**

Total = 43.738 V/m  
E Category: M4  
Location: -10.5, 25, 8.7 mm

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007:  
15 mm from Probe Center to the Device 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 39.926 V/m

Probe Modulation Factor = 1.060


Device Reference Point: 0, 0, -6.3 mm

Reference Value = 30.557 V/m; Power Drift = 0.03 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak E-field in V/m

Grid 1 <b>34.963 M4</b>	Grid 2 <b>29.889 M4</b>	Grid 3 <b>32.594 M4</b>
Grid 4 <b>29.385 M4</b>	Grid 5 <b>39.926 M4</b>	Grid 6 <b>41.342 M4</b>
Grid 7 <b>32.233 M4</b>	Grid 8 <b>45.424 M4</b>	Grid 9 <b>45.533 M4</b>

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**Cursor:**

Total = 45.533 V/m  
E Category: M4  
Location: -10, 24, 8.7 mm

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007:  
15 mm from Probe Center to the Device 2 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 38.945 V/m

Probe Modulation Factor = 1.060

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 30.729 V/m; Power Drift = 0.28 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak E-field in V/m

Grid 1 <b>34.127 M4</b>	Grid 2 <b>28.319 M4</b>	Grid 3 <b>28.934 M4</b>
Grid 4 <b>32.603 M4</b>	Grid 5 <b>38.945 M4</b>	Grid 6 <b>39.630 M4</b>
Grid 7 <b>33.799 M4</b>	Grid 8 <b>45.132 M4</b>	Grid 9 <b>45.137 M4</b>

**Cursor:**

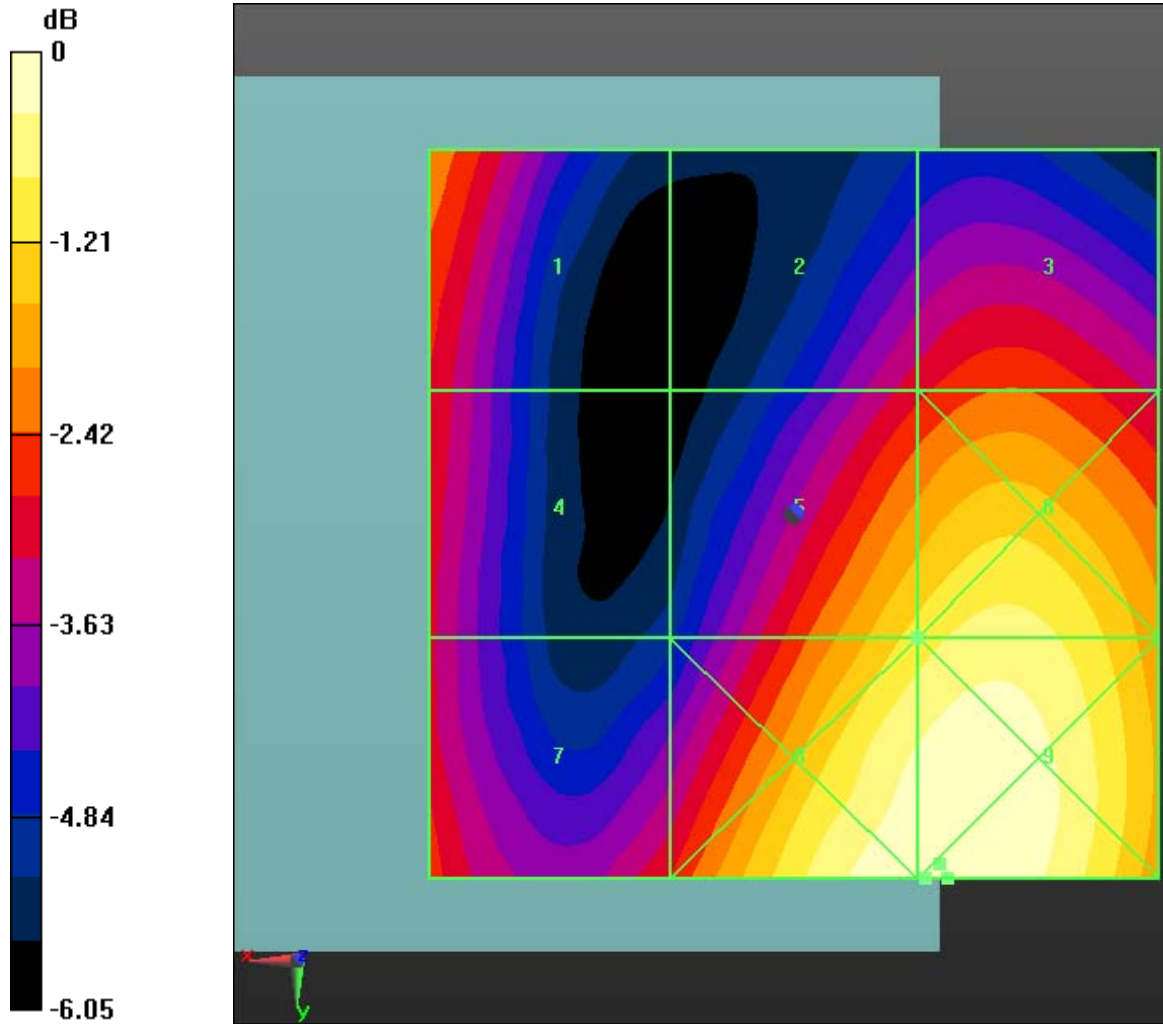
Total = 45.137 V/m  
E Category: M4  
Location: -9, 25, 8.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 43.740V/m

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Date/Time: 3/23/2011 6:37:00 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_CDMA1900\_mid\_chan\_Telecoil\_Center**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: CDMA 1900; Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 46.042 V/m


Probe Modulation Factor = 1.060

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 30.894 V/m; Power Drift = -0.06 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**



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Peak E-field in V/m

Grid 1 <b>27.846 M4</b>	Grid 2 <b>38.794 M4</b>	Grid 3 <b>39.000 M4</b>
Grid 4 <b>34.722 M4</b>	Grid 5 <b>46.042 M4</b>	Grid 6 <b>45.978 M4</b>
Grid 7 <b>40.119 M4</b>	Grid 8 <b>46.442 M4</b>	Grid 9 <b>46.234 M4</b>

**Cursor:**

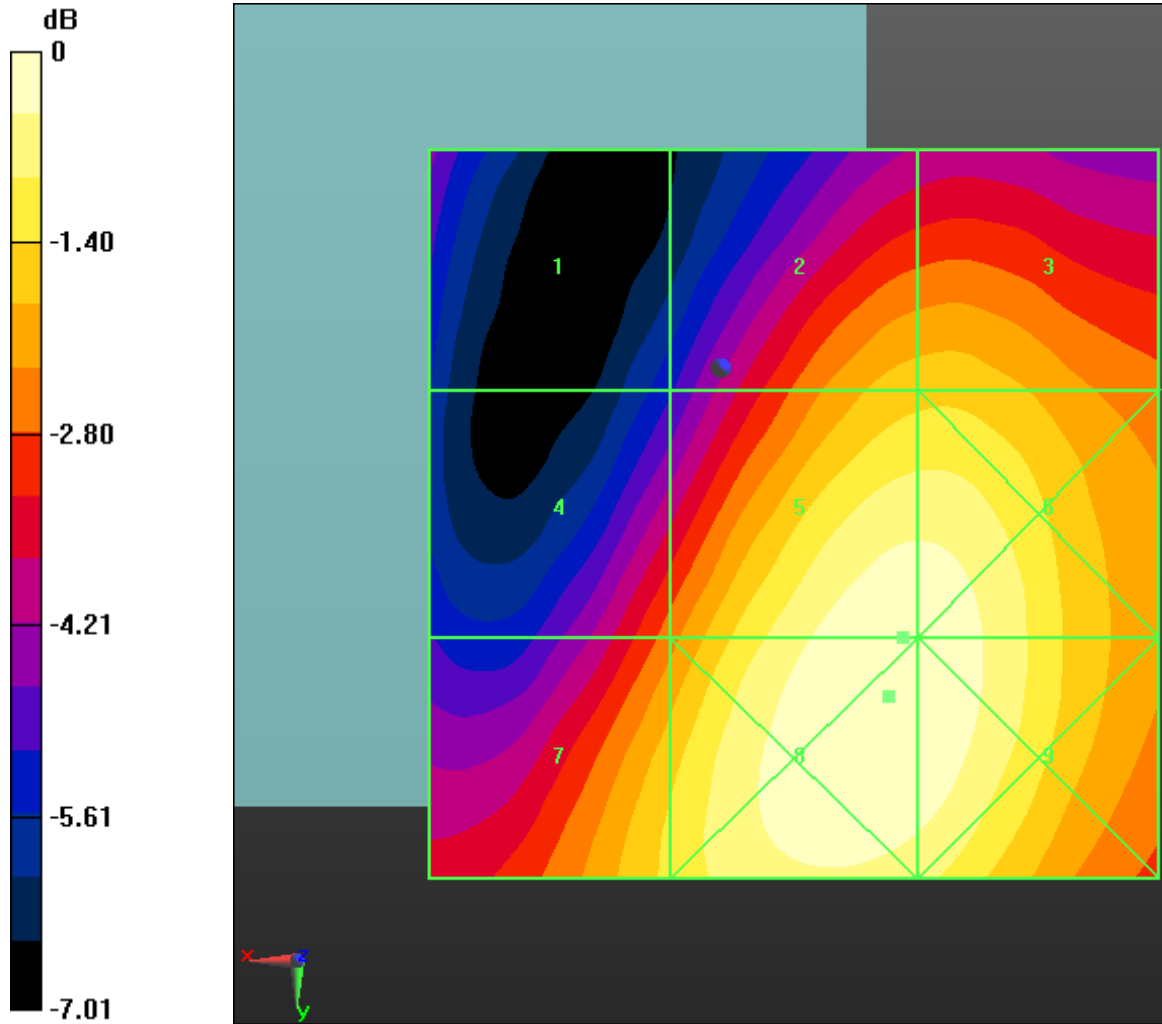
Total = 46.442 V/m  
E Category: M4  
Location: -11.5, 22.5, 8.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 46.440V/m

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Date/Time: 3/23/2011 10:52:43 PM, Date/Time: 3/23/2011 10:56:48 PM, Date/Time: 3/23/2011 11:00:47 PM

Test Laboratory: RIM Testing Services

### HAC RF\_H-Field\_GSM850

**DUT: BlackBerry Smartphone; Type: Sample ;**


Communication System: GSM 850; .; Frequency: 824.2 MHz, Frequency: 836.8 MHz, Frequency: 848.8 MHz; Communication System PAR: 9.191 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 0.278 A/m  
Probe Modulation Factor = 2.870  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 0.046 A/m; Power Drift = 0.21 dB  
**Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

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Peak H-field in A/m

Grid 1 <b>0.278 M4</b>	Grid 2 <b>0.200 M4</b>	Grid 3 <b>0.129 M4</b>
Grid 4 <b>0.238 M4</b>	Grid 5 <b>0.173 M4</b>	Grid 6 <b>0.106 M4</b>
Grid 7 <b>0.255 M4</b>	Grid 8 <b>0.183 M4</b>	Grid 9 <b>0.114 M4</b>

**Cursor:**

Total = 0.278 A/m  
H Category: M4  
Location: 25, -25, 8.7 mm

**Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.332 A/m

Probe Modulation Factor = 2.870


Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.058 A/m; Power Drift = 0.28 dB

**Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

Peak H-field in A/m

Grid 1 <b>0.332 M4</b>	Grid 2 <b>0.252 M4</b>	Grid 3 <b>0.167 M4</b>
Grid 4 <b>0.286 M4</b>	Grid 5 <b>0.220 M4</b>	Grid 6 <b>0.141 M4</b>
Grid 7 <b>0.310 M4</b>	Grid 8 <b>0.233 M4</b>	Grid 9 <b>0.146 M4</b>

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**Cursor:**

Total = 0.332 A/m  
H Category: M4  
Location: 25, -25, 8.7 mm

**Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.387 A/m

Probe Modulation Factor = 2.870

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.071 A/m; Power Drift = -0.35 dB

**Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A**  
**RTS-2580-1106-36**

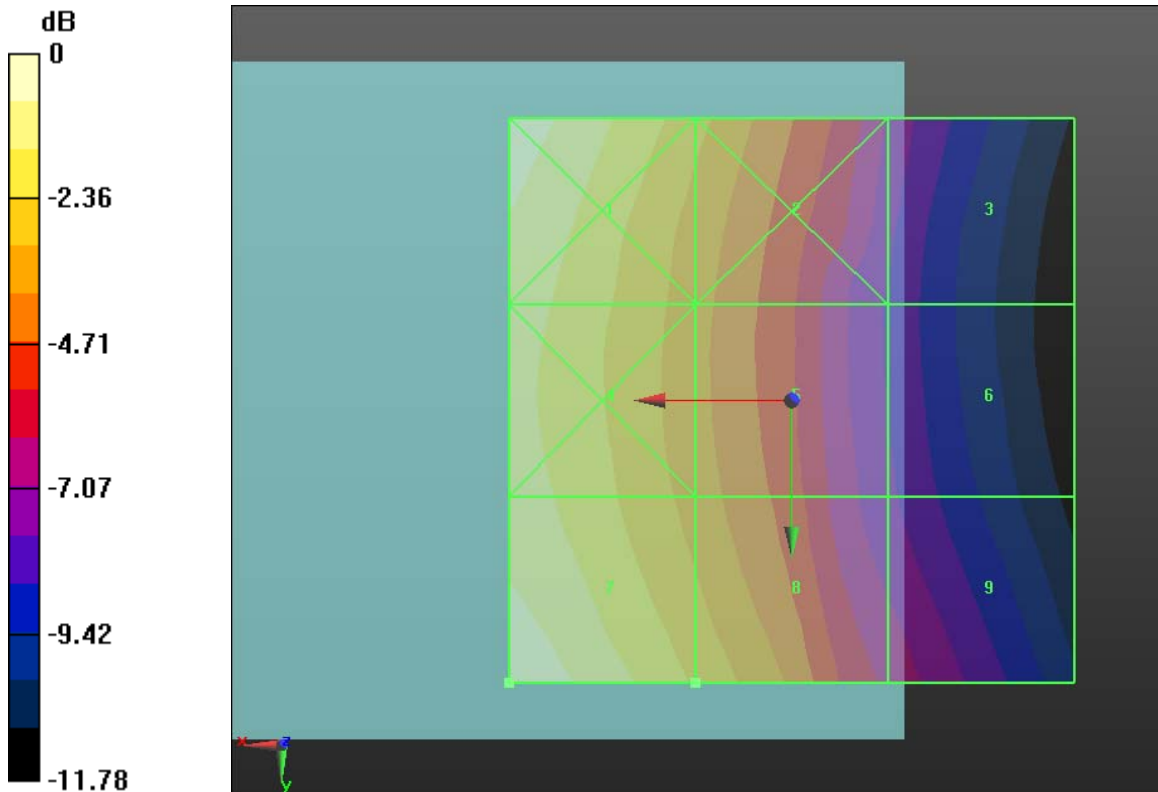
FCC ID  
**L6ARDU70CW**  
**L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.377 M4</b>	Grid 2 <b>0.281 M4</b>	Grid 3 <b>0.171 M4</b>
Grid 4 <b>0.342 M4</b>	Grid 5 <b>0.262 M4</b>	Grid 6 <b>0.162 M4</b>
Grid 7 <b>0.387 M4</b>	Grid 8 <b>0.294 M4</b>	Grid 9 <b>0.186 M4</b>

**Cursor:**

Total = 0.387 A/m  
 H Category: M4  
 Location: 25, 25, 8.7 mm



0 dB = 0.390A/m

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Date/Time: 3/23/2011 11:06:16 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_GSM850\_high\_chan\_Telecoil\_Center**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: GSM 850; ; Frequency: 848.8 MHz; Communication System PAR: 9.191 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.374 A/m

Probe Modulation Factor = 2.870

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.068 A/m; Power Drift = 0.17 dB

**Hearing Aid Near-Field Category: M4 (AWF -5 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

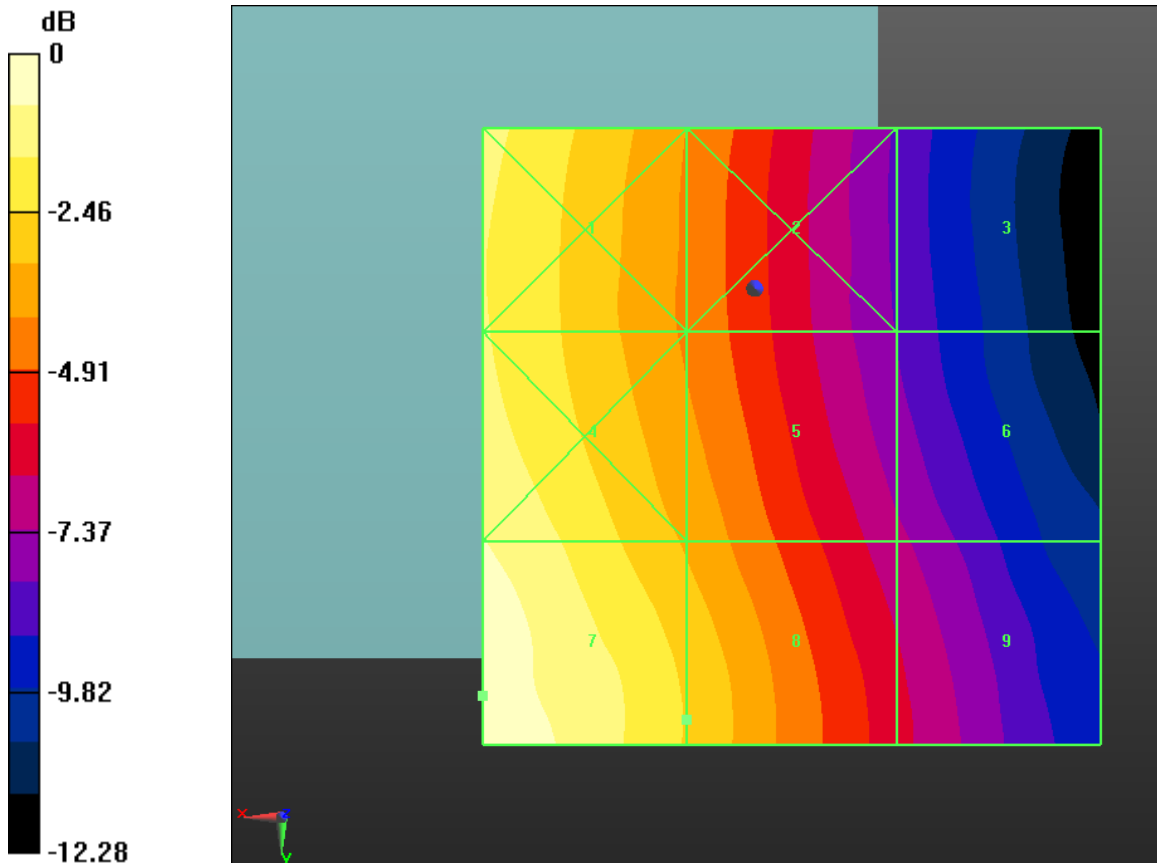
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak H-field in A/m

Grid 1 <b>0.318 M4</b>	Grid 2 <b>0.231 M4</b>	Grid 3 <b>0.144 M4</b>
Grid 4 <b>0.338 M4</b>	Grid 5 <b>0.251 M4</b>	Grid 6 <b>0.163 M4</b>
Grid 7 <b>0.374 M4</b>	Grid 8 <b>0.277 M4</b>	Grid 9 <b>0.181 M4</b>


**Cursor:**

Total = 0.374 A/m  
 H Category: M4  
 Location: 22, 33, 8.7 mm



0 dB = 0.370A/m



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Date/Time: 3/23/2011 11:13:00 PM, Date/Time: 3/23/2011 11:16:23 PM, Date/Time: 3/23/2011 11:19:51 PM

Test Laboratory: RIM Testing Services

### HAC RF\_H-Field\_GSM1900

**DUT: BlackBerry Smartphone; Type: Sample**


Communication System: GSM 1900; .; Frequency: 1850.2 MHz, Frequency: 1880 MHz, Frequency: 1909.8 MHz; Communication System PAR: 9.191 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 0.200 A/m  
Probe Modulation Factor = 2.870  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 0.061 A/m; Power Drift = 0.63 dB  
**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

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Peak H-field in A/m

Grid 1 <b>0.197 M3</b>	Grid 2 <b>0.186 M3</b>	Grid 3 <b>0.163 M3</b>
Grid 4 <b>0.221 M3</b>	Grid 5 <b>0.200 M3</b>	Grid 6 <b>0.157 M3</b>
Grid 7 <b>0.261 M2</b>	Grid 8 <b>0.226 M3</b>	Grid 9 <b>0.160 M3</b>

**Cursor:**

Total = 0.261 A/m  
H Category: M2  
Location: 25, 25, 8.7 mm

**Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.242 A/m

Probe Modulation Factor = 2.870


Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.075 A/m; Power Drift = 0.15 dB

**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Peak H-field in A/m

Grid 1 <b>0.223 M3</b>	Grid 2 <b>0.218 M3</b>	Grid 3 <b>0.193 M3</b>
Grid 4 <b>0.259 M2</b>	Grid 5 <b>0.242 M3</b>	Grid 6 <b>0.194 M3</b>
Grid 7 <b>0.306 M2</b>	Grid 8 <b>0.272 M2</b>	Grid 9 <b>0.197 M3</b>

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**Cursor:**

Total = 0.306 A/m  
H Category: M2  
Location: 24.5, 25, 8.7 mm

**Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.226 A/m

Probe Modulation Factor = 2.870

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.073 A/m; Power Drift = -0.14 dB

**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

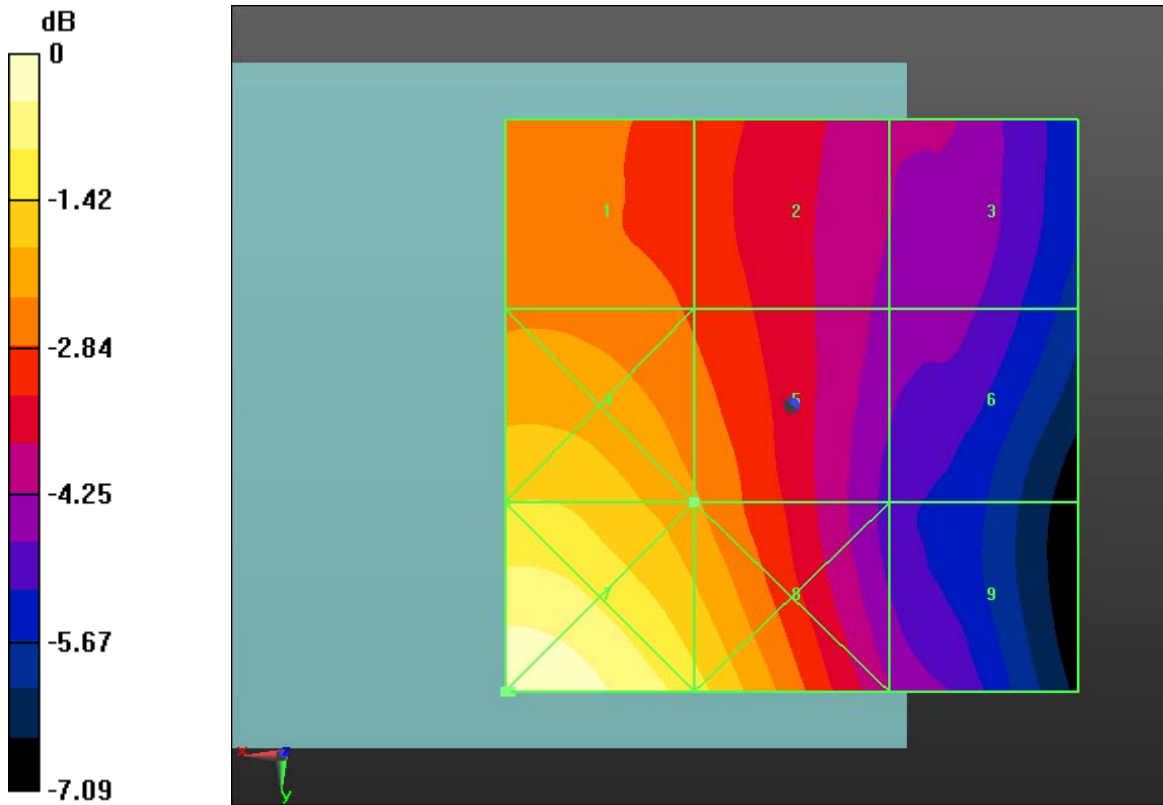
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Peak H-field in A/m


Grid 1 <b>0.200 M3</b>	Grid 2 <b>0.197 M3</b>	Grid 3 <b>0.170 M3</b>
Grid 4 <b>0.240 M3</b>	Grid 5 <b>0.226 M3</b>	Grid 6 <b>0.172 M3</b>
Grid 7 <b>0.299 M2</b>	Grid 8 <b>0.264 M2</b>	Grid 9 <b>0.181 M3</b>

**Cursor:**

Total = 0.299 A/m  
H Category: M2  
Location: 25, 25, 8.7 mm



0 dB = 0.260A/m

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Date/Time: 4/27/2011 3:05:33 PM

Test Laboratory: RIM Testing Services

### HAC RF\_H-Field\_GSM1900\_telecoil

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: GSM 1900; .; Frequency: 1880 MHz; Communication System PAR: 9.191 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.213 A/m

Probe Modulation Factor = 2.870

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.065 A/m; Power Drift = 0.10 dB

**Hearing Aid Near-Field Category: M3 (AWF -5 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A**  
**RTS-2580-1106-36**

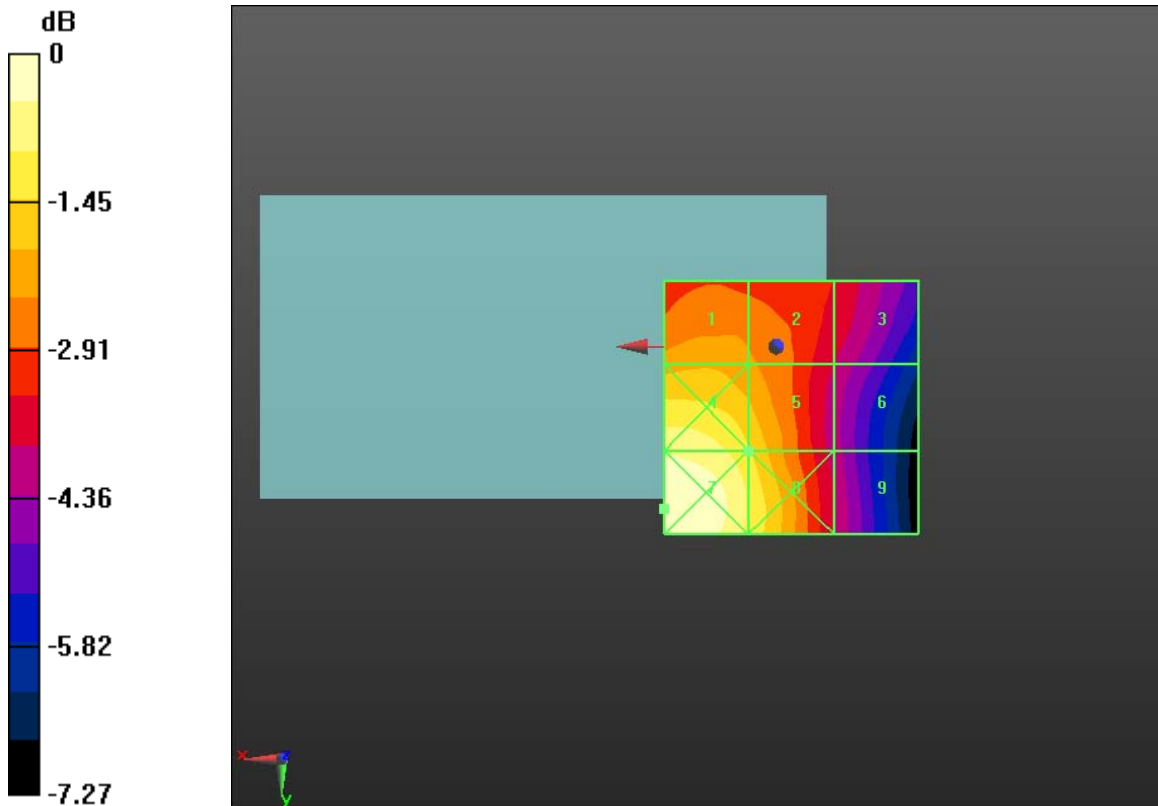
FCC ID  
**L6ARDU70CW**  
**L6ARDE70UW**

Peak H-field in A/m


Grid 1 <b>0.199 M3</b>	Grid 2 <b>0.192 M3</b>	Grid 3 <b>0.169 M3</b>
Grid 4 <b>0.234 M3</b>	Grid 5 <b>0.213 M3</b>	Grid 6 <b>0.160 M3</b>
Grid 7 <b>0.254 M2</b>	Grid 8 <b>0.223 M3</b>	Grid 9 <b>0.161 M3</b>

**Cursor:**

Total = 0.254 A/m  
 H Category: M2  
 Location: 22, 32, 8.7 mm



0 dB = 0.250A/m

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Date/Time: 3/23/2011 9:54:08 PM, Date/Time: 3/23/2011 9:58:10 PM, Date/Time: 3/23/2011 10:01:52 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_CDMA800**

**DUT: BlackBerry Smartphone; Type: Sample**


Communication System: CDMA 800; Frequency: 824.7 MHz, Frequency: 836.52 MHz, Frequency: 848.52 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 0.049 A/m  
Probe Modulation Factor = 1.040  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 0.019 A/m; Power Drift = 1.06 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak H-field in A/m

Grid 1 <b>0.049 M4</b>	Grid 2 <b>0.034 M4</b>	Grid 3 <b>0.019 M4</b>
Grid 4 <b>0.041 M4</b>	Grid 5 <b>0.028 M4</b>	Grid 6 <b>0.017 M4</b>
Grid 7 <b>0.040 M4</b>	Grid 8 <b>0.030 M4</b>	Grid 9 <b>0.018 M4</b>

**Cursor:**

Total = 0.049 A/m  
H Category: M4  
Location: 25, -25, 8.7 mm

**Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.051 A/m

Probe Modulation Factor = 1.040

Device Reference Point: 0, 0, -6.3 mm


Reference Value = 0.025 A/m; Power Drift = -0.16 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak H-field in A/m

Grid 1 <b>0.051 M4</b>	Grid 2 <b>0.041 M4</b>	Grid 3 <b>0.025 M4</b>
Grid 4 <b>0.050 M4</b>	Grid 5 <b>0.036 M4</b>	Grid 6 <b>0.024 M4</b>
Grid 7 <b>0.050 M4</b>	Grid 8 <b>0.037 M4</b>	Grid 9 <b>0.025 M4</b>



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**Cursor:**

Total = 0.051 A/m  
H Category: M4  
Location: 25, -25, 8.7 mm

**Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.047 A/m

Probe Modulation Factor = 1.040

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.030 A/m; Power Drift = 0.99 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

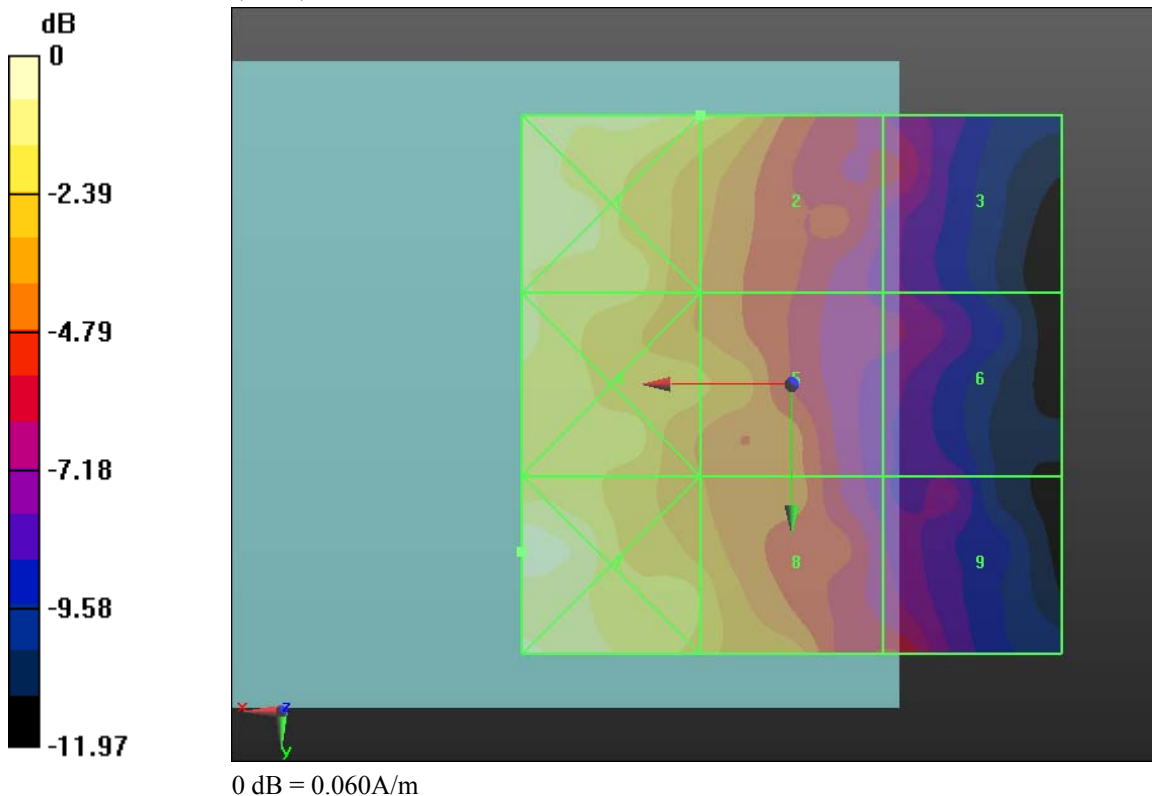
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Peak H-field in A/m

Grid 1 <b>0.055 M4</b>	Grid 2 <b>0.047 M4</b>	Grid 3 <b>0.030 M4</b>
Grid 4 <b>0.052 M4</b>	Grid 5 <b>0.042 M4</b>	Grid 6 <b>0.027 M4</b>
Grid 7 <b>0.058 M4</b>	Grid 8 <b>0.046 M4</b>	Grid 9 <b>0.033 M4</b>

Cursor:

Total = 0.058 A/m  
H Category: M4  
Location: 25, 15.5, 8.7 mm



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Date/Time: 3/23/2011 10:07:55 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_CDMA800\_mid\_chan\_Telecoil\_Center**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: CDMA 800; Communication System Band:; Frequency: 836.52 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.052 A/m

Probe Modulation Factor = 1.040

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.024 A/m; Power Drift = 1.07 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

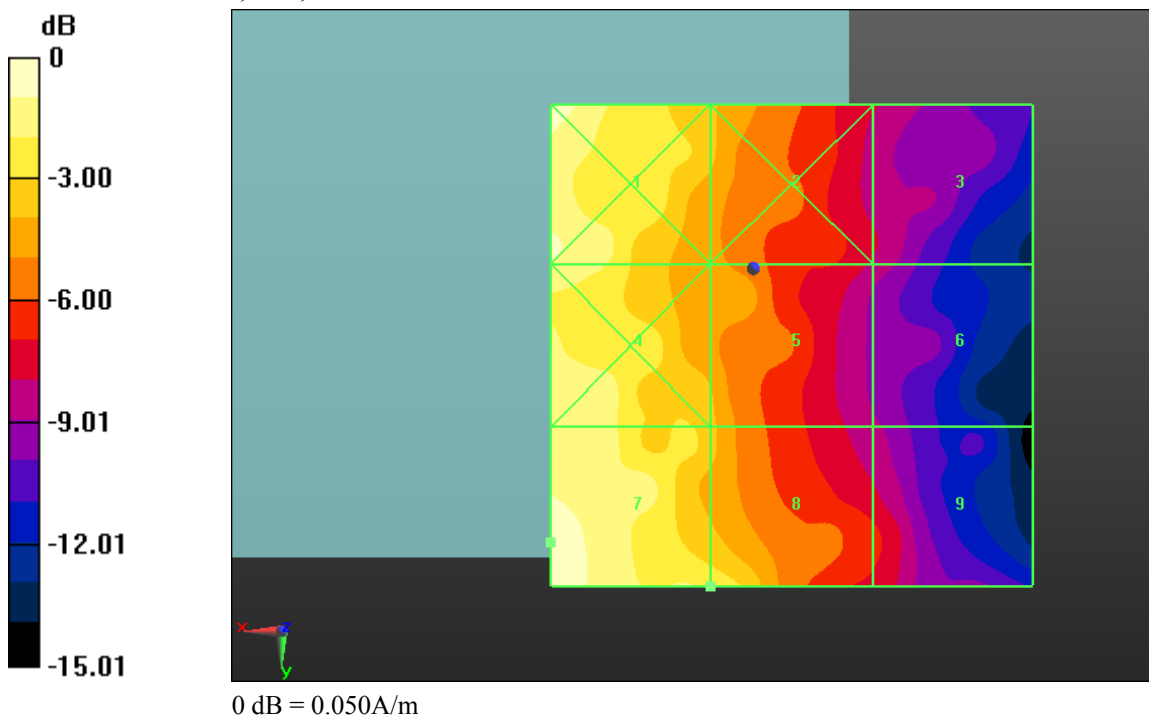
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Peak H-field in A/m

Grid 1 <b>0.050 M4</b>	Grid 2 <b>0.033 M4</b>	Grid 3 <b>0.020 M4</b>
Grid 4 <b>0.044 M4</b>	Grid 5 <b>0.033 M4</b>	Grid 6 <b>0.020 M4</b>
Grid 7 <b>0.052 M4</b>	Grid 8 <b>0.039 M4</b>	Grid 9 <b>0.023 M4</b>

**Cursor:**

Total = 0.052 A/m  
 H Category: M4  
 Location: 21, 28.5, 8.7 mm



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Date/Time: 3/23/2011 10:15:39 PM, Date/Time: 3/23/2011 10:28:50 PM, Date/Time: 3/23/2011 10:34:20 PM

Test Laboratory: RIM Testing Services

### HAC RF\_H-Field\_CDMA1900

#### DUT: BlackBerry Smartphone; Type: Sample


Communication System: CDMA 1900;; Frequency: 1851.25 MHz, Frequency: 1880 MHz, Frequency: 1908.5 MHz; Communication System PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

#### DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

#### Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 0.037 A/m  
Probe Modulation Factor = 1.040  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 0.031 A/m; Power Drift = -0.02 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak H-field in A/m

Grid 1 <b>0.036 M4</b>	Grid 2 <b>0.035 M4</b>	Grid 3 <b>0.031 M4</b>
Grid 4 <b>0.041 M4</b>	Grid 5 <b>0.037 M4</b>	Grid 6 <b>0.030 M4</b>
Grid 7 <b>0.047 M4</b>	Grid 8 <b>0.042 M4</b>	Grid 9 <b>0.029 M4</b>

**Cursor:**

Total = 0.047 A/m  
H Category: M4  
Location: 22.5, 25, 8.7 mm

**Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.121 A/m

Probe Modulation Factor = 1.040


Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.105 A/m; Power Drift = -0.02 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Peak H-field in A/m

Grid 1 <b>0.111 M4</b>	Grid 2 <b>0.108 M4</b>	Grid 3 <b>0.094 M4</b>
Grid 4 <b>0.130 M4</b>	Grid 5 <b>0.121 M4</b>	Grid 6 <b>0.094 M4</b>
Grid 7 <b>0.152 M4</b>	Grid 8 <b>0.135 M4</b>	Grid 9 <b>0.096 M4</b>

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**Cursor:**

Total = 0.152 A/m  
H Category: M4  
Location: 25, 25, 8.7 mm

**Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid**

**Compatibility Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.120 A/m

Probe Modulation Factor = 1.040

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.104 A/m; Power Drift = 0.03 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

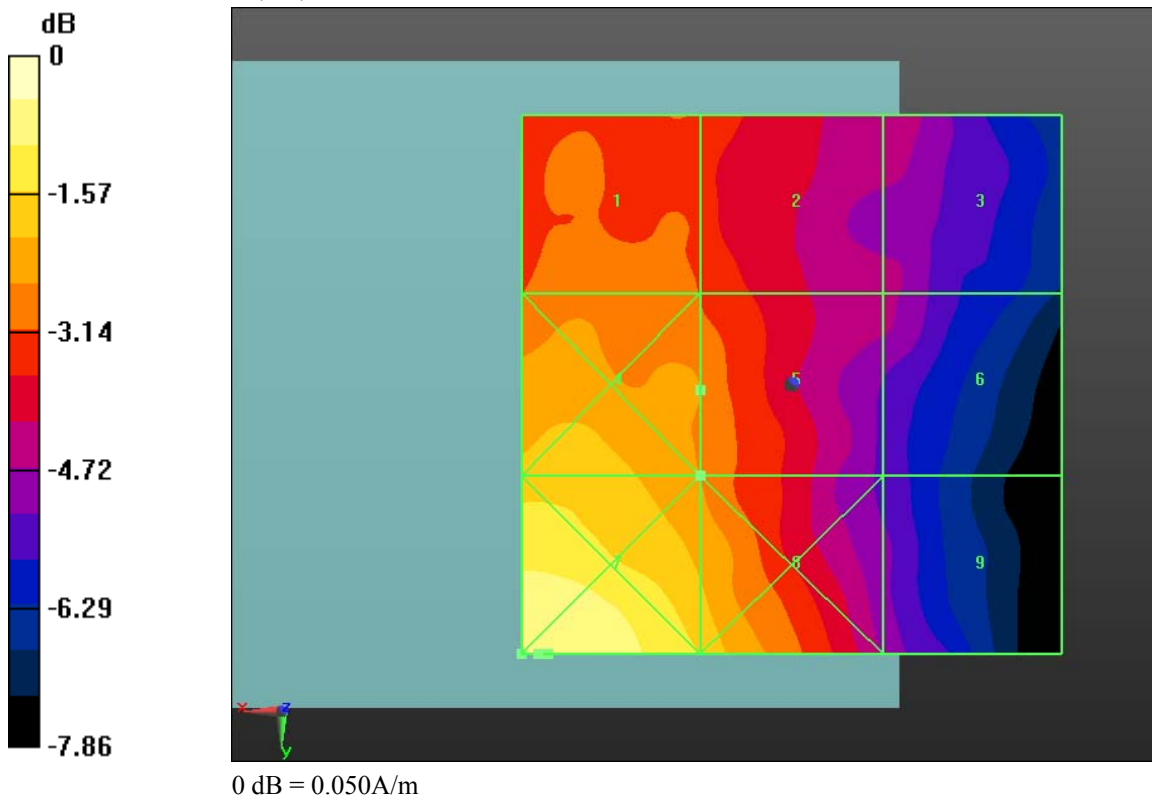
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Peak H-field in A/m


Grid 1 <b>0.103 M4</b>	Grid 2 <b>0.103 M4</b>	Grid 3 <b>0.092 M4</b>
Grid 4 <b>0.127 M4</b>	Grid 5 <b>0.120 M4</b>	Grid 6 <b>0.094 M4</b>
Grid 7 <b>0.156 M4</b>	Grid 8 <b>0.139 M4</b>	Grid 9 <b>0.097 M4</b>

**Cursor:**

Total = 0.156 A/m  
 H Category: M4  
 Location: 23.5, 25, 8.7 mm





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Date/Time: 3/23/2011 10:40:20 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_CDMA1900\_mid\_chan\_Telecoil\_Center**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: CDMA 1900; Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.105 A/m

Probe Modulation Factor = 1.040

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.100 A/m; Power Drift = 0.08 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

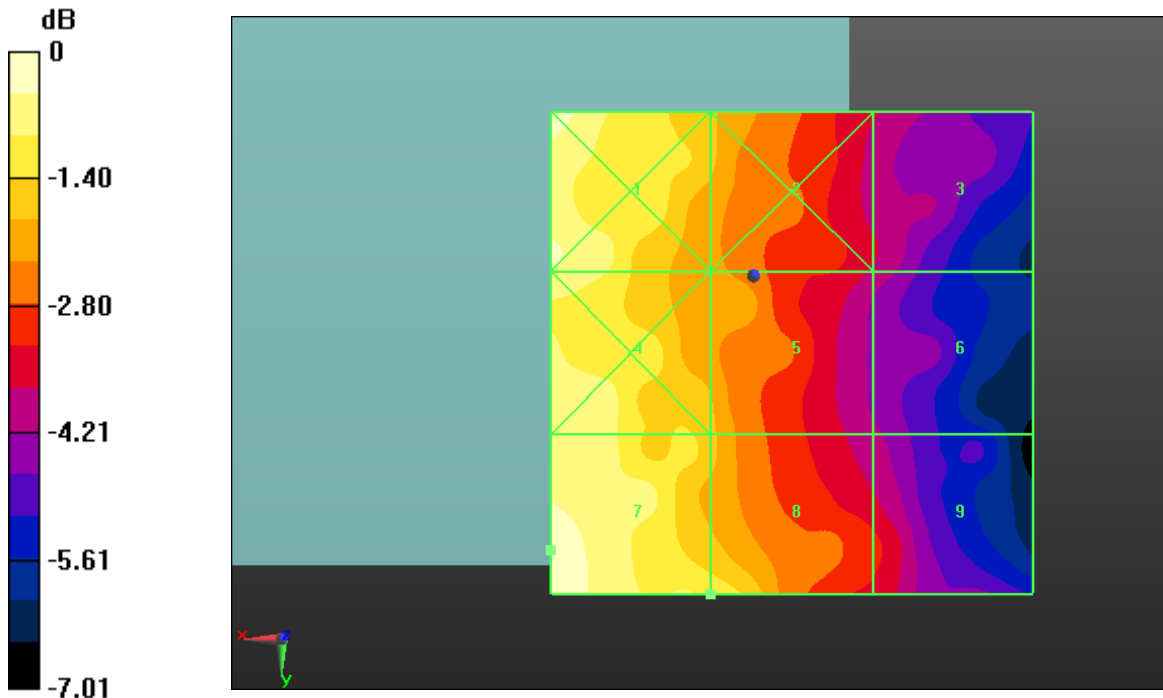
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Peak H-field in A/m


Grid 1 <b>0.100 M4</b>	Grid 2 <b>0.097 M4</b>	Grid 3 <b>0.086 M4</b>
Grid 4 <b>0.113 M4</b>	Grid 5 <b>0.105 M4</b>	Grid 6 <b>0.087 M4</b>
Grid 7 <b>0.131 M4</b>	Grid 8 <b>0.113 M4</b>	Grid 9 <b>0.086 M4</b>

**Cursor:**

Total = 0.131 A/m  
 H Category: M4  
 Location: 20, 15, 8.7 mm



0 dB = 0.130A/m

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Date/Time: 4/28/2011 6:01:59 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_UMTS\_band\_V\_low\_chan**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD V;; Frequency: 826.4 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 53.150 V/m

Probe Modulation Factor = 1.010

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 63.044 V/m; Power Drift = -0.16 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

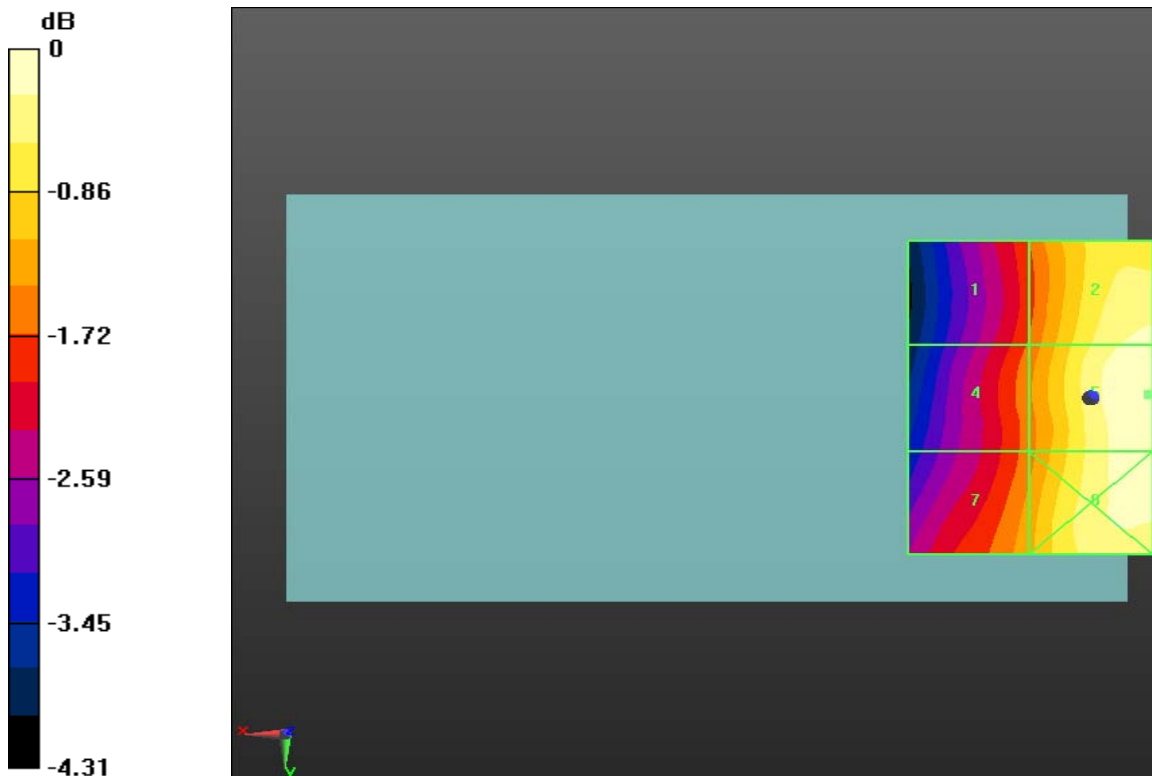
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Peak E-field in V/m


Grid 1 <b>43.827 M4</b>	Grid 2 <b>52.082 M4</b>	Grid 3 <b>52.079 M4</b>
Grid 4 <b>44.778 M4</b>	Grid 5 <b>53.150 M4</b>	Grid 6 <b>53.136 M4</b>
Grid 7 <b>46.154 M4</b>	Grid 8 <b>52.479 M4</b>	Grid 9 <b>52.453 M4</b>

**Cursor:**

Total = 53.150 V/m  
 E Category: M4  
 Location: -8, -0.5, 8.7 mm



0 dB = 53.150V/m

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Date/Time: 4/28/2011 6:05:28 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_UMTS\_band\_V\_mid\_chan**

**DUT: BlackBerry Smartphone; Type: Sample ;**

Communication System: WCDMA FDD V; Frequency: 836.4 MHz; Communication System

PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 58.048 V/m

Probe Modulation Factor = 1.010

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 66.643 V/m; Power Drift = 0.07 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

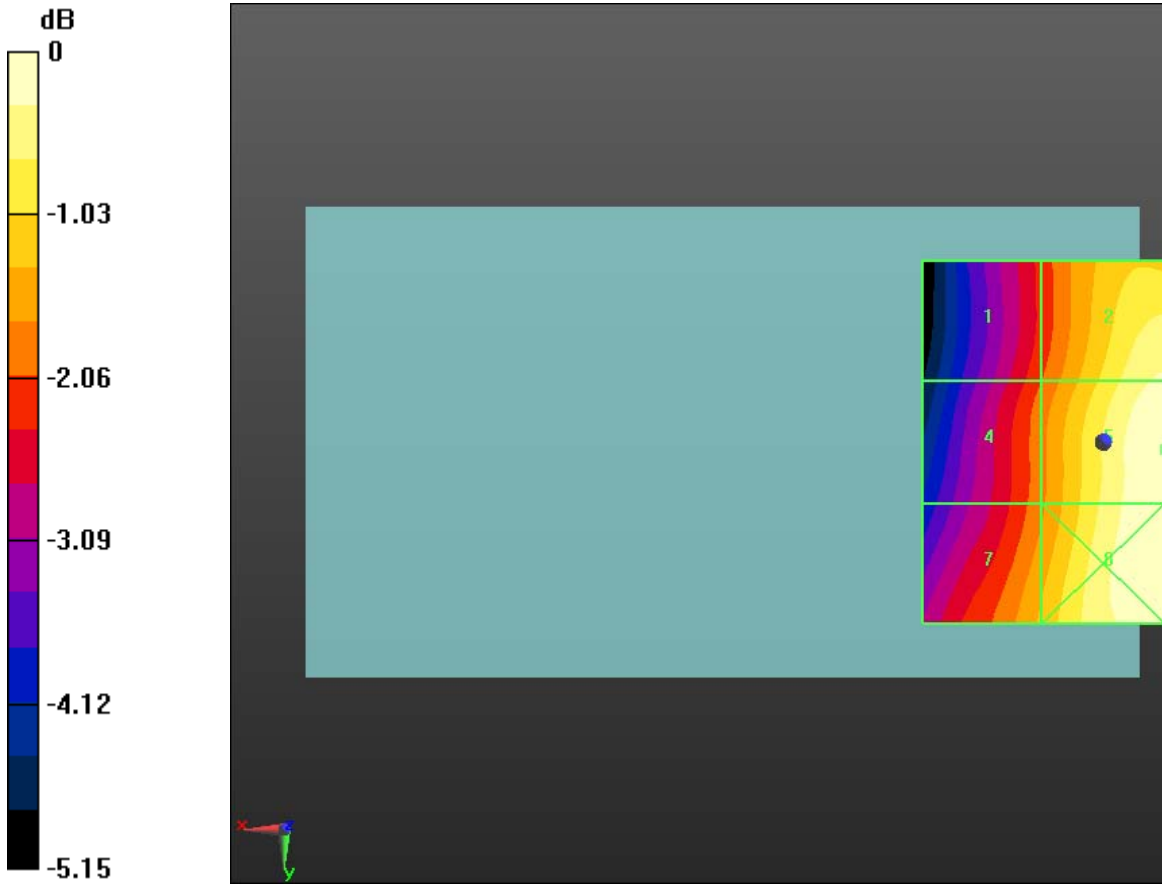
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Peak E-field in V/m


Grid 1 <b>45.867 M4</b>	Grid 2 <b>56.235 M4</b>	Grid 3 <b>56.249 M4</b>
Grid 4 <b>47.353 M4</b>	Grid 5 <b>58.048 M4</b>	Grid 6 <b>58.085 M4</b>
Grid 7 <b>50.062 M4</b>	Grid 8 <b>57.881 M4</b>	Grid 9 <b>57.881 M4</b>

Cursor:

Total = 58.085 V/m  
 E Category: M4  
 Location: -9, 1, 8.7 mm



0 dB = 58.080V/m

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Date/Time: 4/28/2011 6:09:21 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_UMTS\_band\_V\_high\_chan**

**DUT: BlackBerry Smartphone; Type: Sample ;**

Communication System: WCDMA FDD V;; Frequency: 846.6 MHz; Communication System  
PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 60.970 V/m

Probe Modulation Factor = 1.010

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 69.960 V/m; Power Drift = 0.10 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

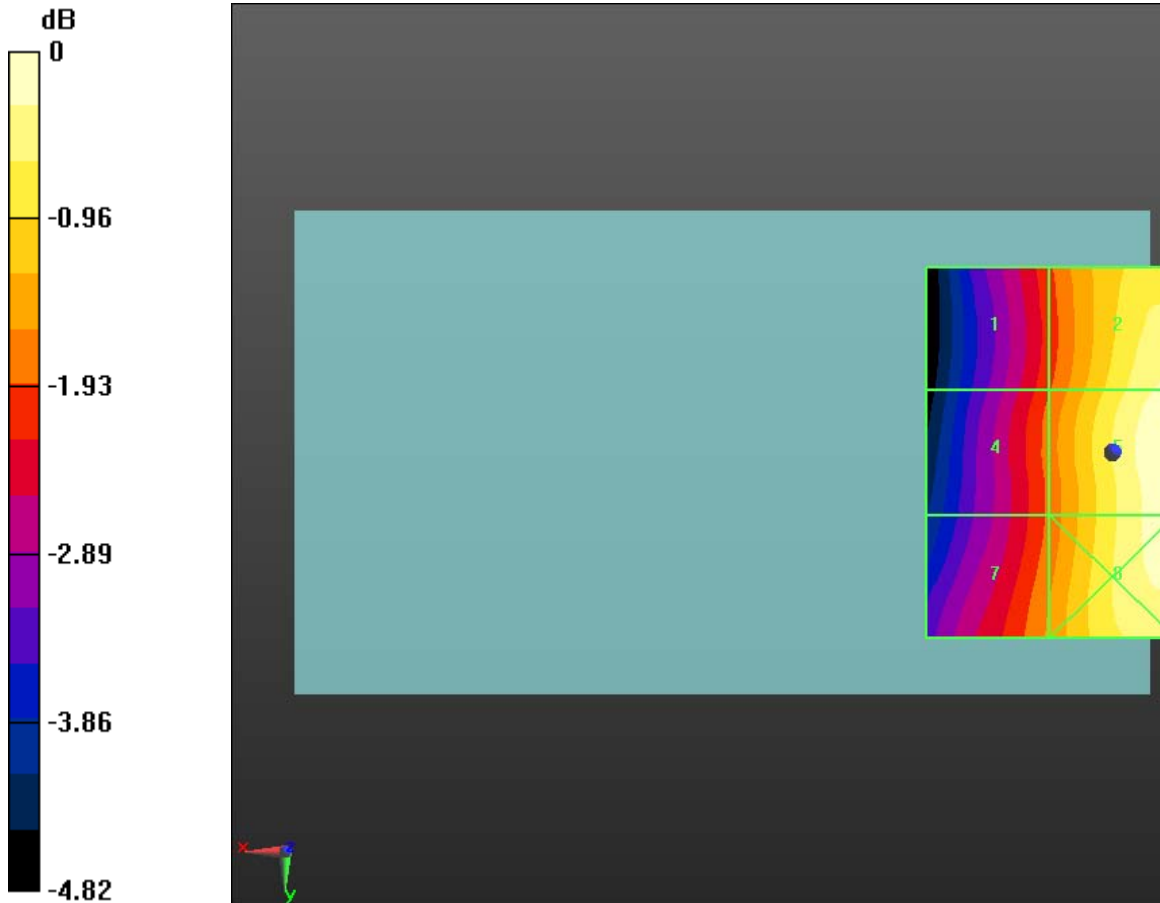
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak E-field in V/m

Grid 1 <b>48.697 M4</b>	Grid 2 <b>59.549 M4</b>	Grid 3 <b>59.549 M4</b>
Grid 4 <b>49.795 M4</b>	Grid 5 <b>60.970 M4</b>	Grid 6 <b>60.985 M4</b>
Grid 7 <b>51.111 M4</b>	Grid 8 <b>59.782 M4</b>	Grid 9 <b>59.780 M4</b>


**Cursor:**

Total = 60.985 V/m  
 E Category: M4  
 Location: -9, -0.5, 8.7 mm



0 dB = 60.990V/m



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Date/Time: 4/28/2011 6:13:37 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_UMTS\_band\_V\_high\_chan\_telecoil\_center**

**DUT: BlackBerry Smartphone; Type: Sample**


Communication System: WCDMA FDD V;; Frequency: 846.6 MHz; Communication System  
PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 60.037 V/m  
Probe Modulation Factor = 1.010  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 69.862 V/m; Power Drift = -0.10 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

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Peak E-field in V/m

Grid 1 <b>48.094 M4</b>	Grid 2 <b>57.445 M4</b>	Grid 3 <b>57.445 M4</b>
Grid 4 <b>49.292 M4</b>	Grid 5 <b>60.037 M4</b>	Grid 6 <b>60.045 M4</b>
Grid 7 <b>49.767 M4</b>	Grid 8 <b>59.932 M4</b>	Grid 9 <b>59.939 M4</b>

**Cursor:**

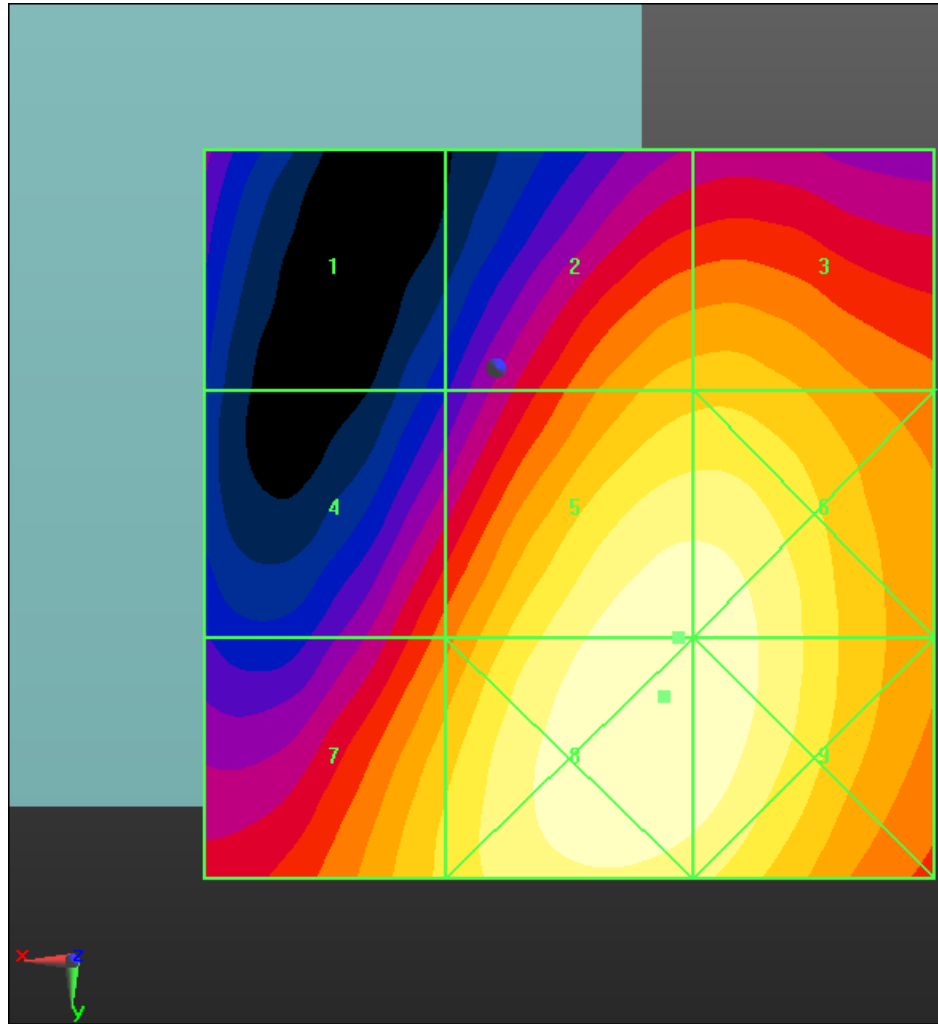
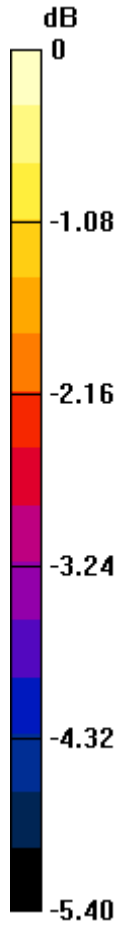
Total = 60.045 V/m  
E Category: M4  
Location: -9, -2, 8.7 mm

Author Data  
**Daoud Attayi**


Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**



0 dB = 60.040V/m

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Date/Time: 4/28/2011 6:27:09 PM

Test Laboratory: RIM Testing Services

**HAC RF\_E-Field\_UMTS\_band\_II\_low\_chan**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD II,.; Frequency: 1852.4 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 26.748 V/m

Probe Modulation Factor = 1.120

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 16.724 V/m; Power Drift = -0.08 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

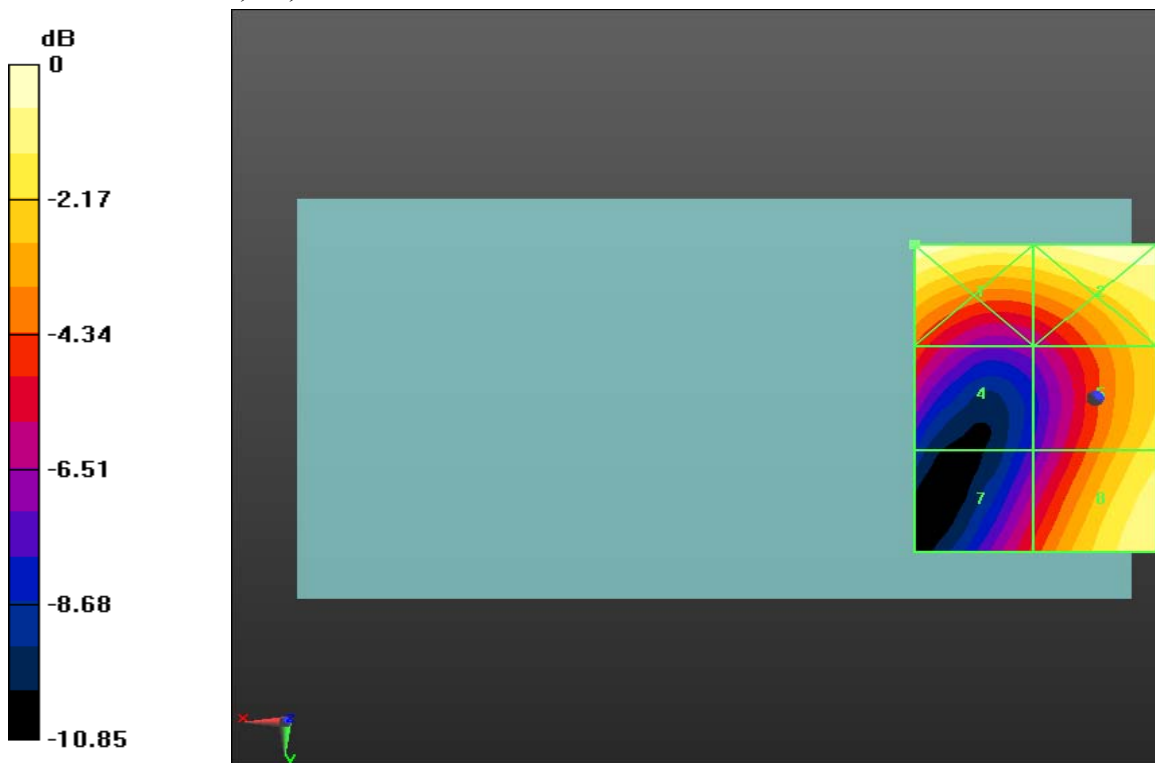
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Peak E-field in V/m


Grid 1 <b>28.684 M4</b>	Grid 2 <b>28.195 M4</b>	Grid 3 <b>27.724 M4</b>
Grid 4 <b>17.480 M4</b>	Grid 5 <b>23.673 M4</b>	Grid 6 <b>25.140 M4</b>
Grid 7 <b>16.671 M4</b>	Grid 8 <b>26.458 M4</b>	Grid 9 <b>26.748 M4</b>

**Cursor:**

Total = 28.684 V/m  
 E Category: M4  
 Location: 25, -25, 8.7 mm



0 dB = 28.680V/m

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Date/Time: 4/28/2011 6:30:30 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_UMTS\_band\_II\_mid\_chan**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Communication System

PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 25.642 V/m

Probe Modulation Factor = 1.120

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 15.839 V/m; Power Drift = 0.06 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

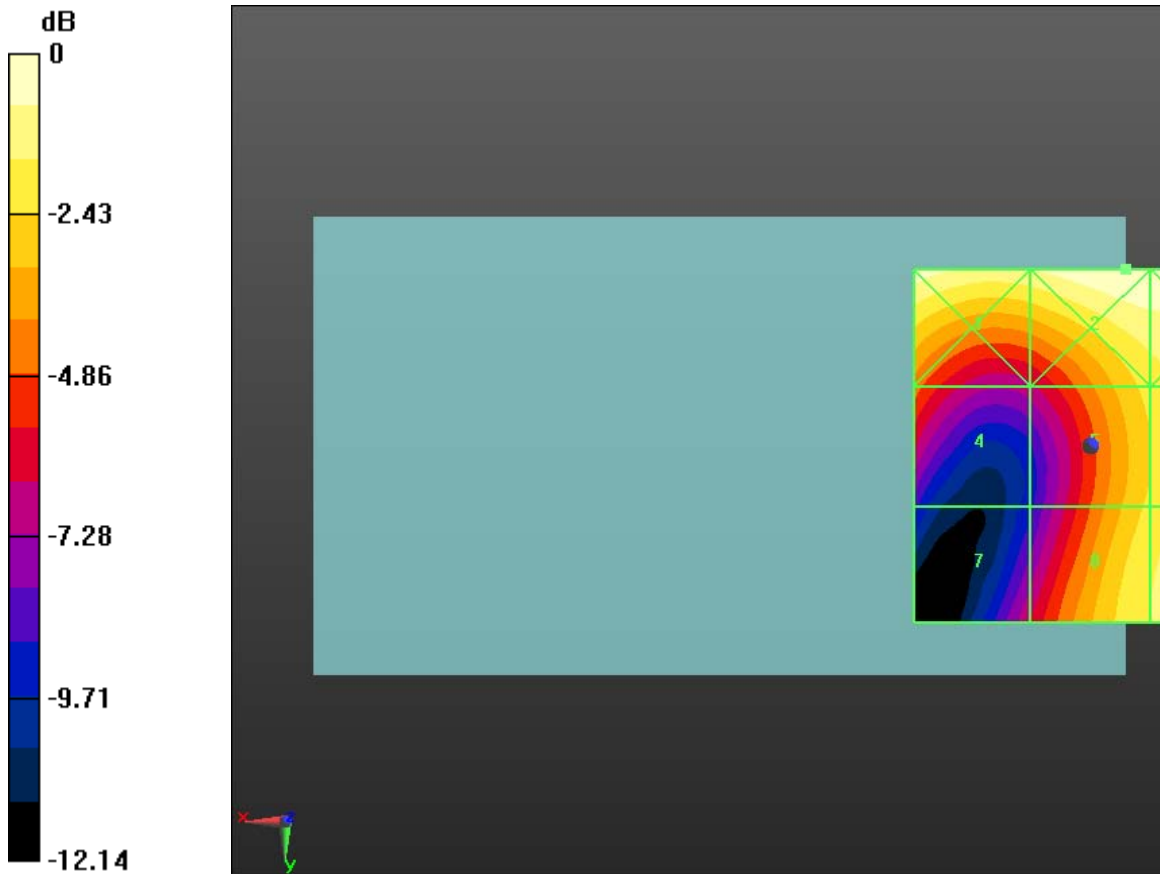
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak E-field in V/m


Grid 1 <b>28.994 M4</b>	Grid 2 <b>29.755 M4</b>	Grid 3 <b>29.518 M4</b>
Grid 4 <b>18.013 M4</b>	Grid 5 <b>2013 M4</b>	Grid 6 <b>24.974 M4</b>
Grid 7 <b>14.336 M4</b>	Grid 8 <b>24.701 M4</b>	Grid 9 <b>25.642 M4</b>

**Cursor:**

Total = 29.755 V/m  
 E Category: M4  
 Location: -5, -25, 8.7 mm



0 dB = 29.750V/m

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Date/Time: 4/28/2011 6:36:20 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_UMTS\_band\_II\_high\_chan**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD II;; Frequency: 1907.6 MHz; Communication System  
PAR: 0 dB  
Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
Phantom section: RF Section  
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)


DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
  - Modulation Compensation: **Not calibrated**
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm  
Maximum value of peak Total field = 22.382 V/m  
Probe Modulation Factor = 1.120  
Device Reference Point: 0, 0, -6.3 mm  
Reference Value = 13.813 V/m; Power Drift = 0.02 dB  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**



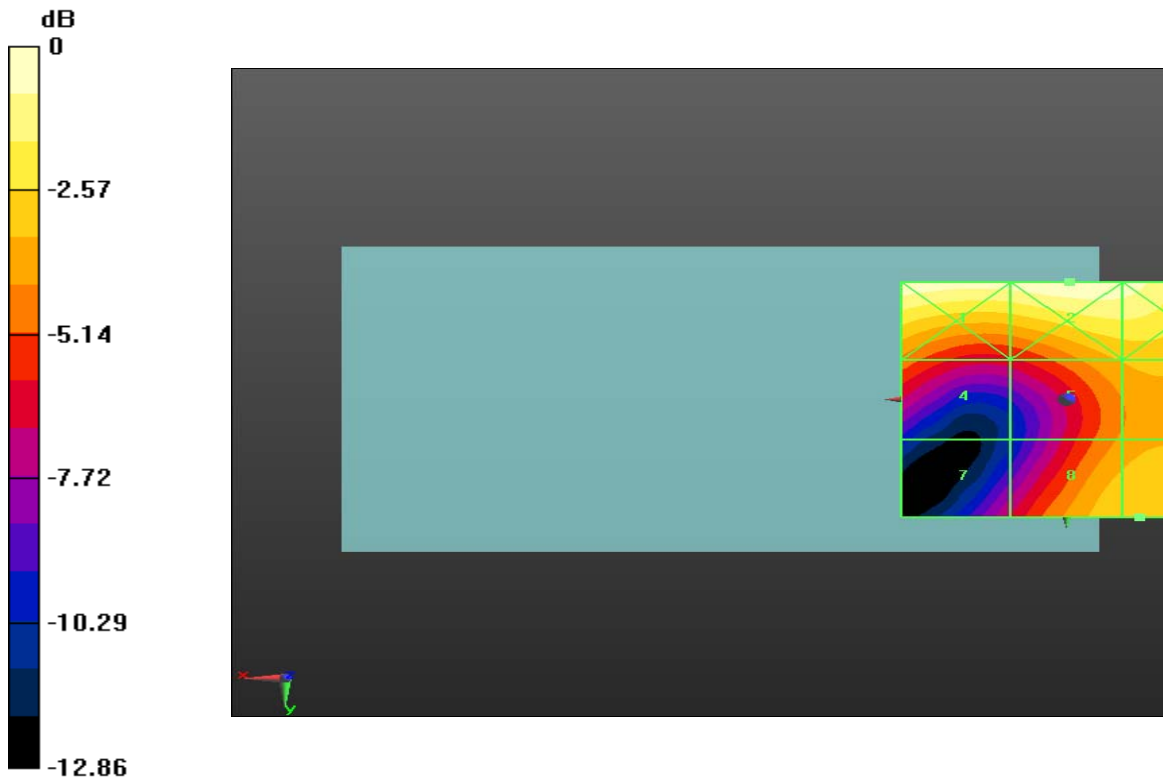
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Peak E-field in V/m


Grid 1 <b>30.381 M4</b>	Grid 2 <b>30.457 M4</b>	Grid 3 <b>29.298 M4</b>
Grid 4 <b>18.154 M4</b>	Grid 5 <b>20.760 M4</b>	Grid 6 <b>21.349 M4</b>
Grid 7 <b>14.053 M4</b>	Grid 8 <b>22.160 M4</b>	Grid 9 <b>22.382 M4</b>

**Cursor:**

Total = 30.457 V/m  
 E Category: M4  
 Location: -0.5, -25, 8.7 mm



0 dB = 30.460V/m

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Date/Time: 4/28/2011 6:52:00 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_E-Field\_UMTS\_band\_II\_low\_chan\_telecoil\_center**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD II;.; Frequency: 1852.4 MHz; Communication System  
PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 26.169 V/m

Probe Modulation Factor = 1.120

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 16.654 V/m; Power Drift = -0.22 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Author Data  
**Daoud Attayi**

Dates of Test  
**Mar. 22-23, Apr. 28, 2011**

Report No  
**RTS-3933-1104-55A  
 RTS-2580-1106-36**

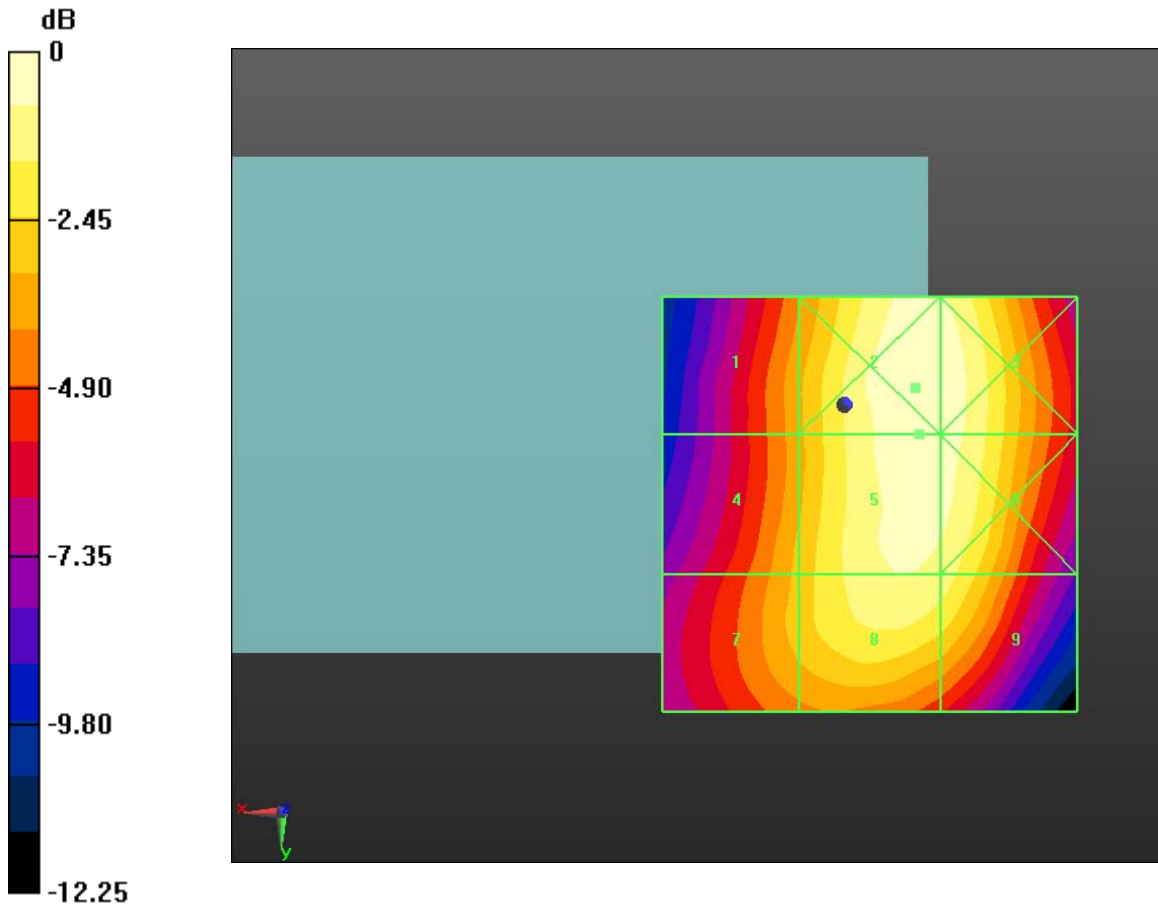
FCC ID  
**L6ARDU70CW  
 L6ARDE70UW**

Peak E-field in V/m


<b>Grid 1 35.499 M4</b>	<b>Grid 2 33.617 M4</b>	<b>Grid 3 30.067 M4</b>
<b>Grid 4 22.228 M4</b>	<b>Grid 5 2077 M4</b>	<b>Grid 6 24.905 M4</b>
<b>Grid 7 14.094 M4</b>	<b>Grid 8 25.345 M4</b>	<b>Grid 9 26.169 M4</b>

**Cursor:**

Total = 35.499 V/m  
 E Category: M4  
 Location: 25, -33, 8.7 mm



0 dB = 35.500V/m

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Date/Time: 4/28/2011 8:13:17 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_UMTS\_band V\_low\_chan**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD V; Frequency: 826.4 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.102 A/m

Probe Modulation Factor = 0.990

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.048 A/m; Power Drift = 0.07 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

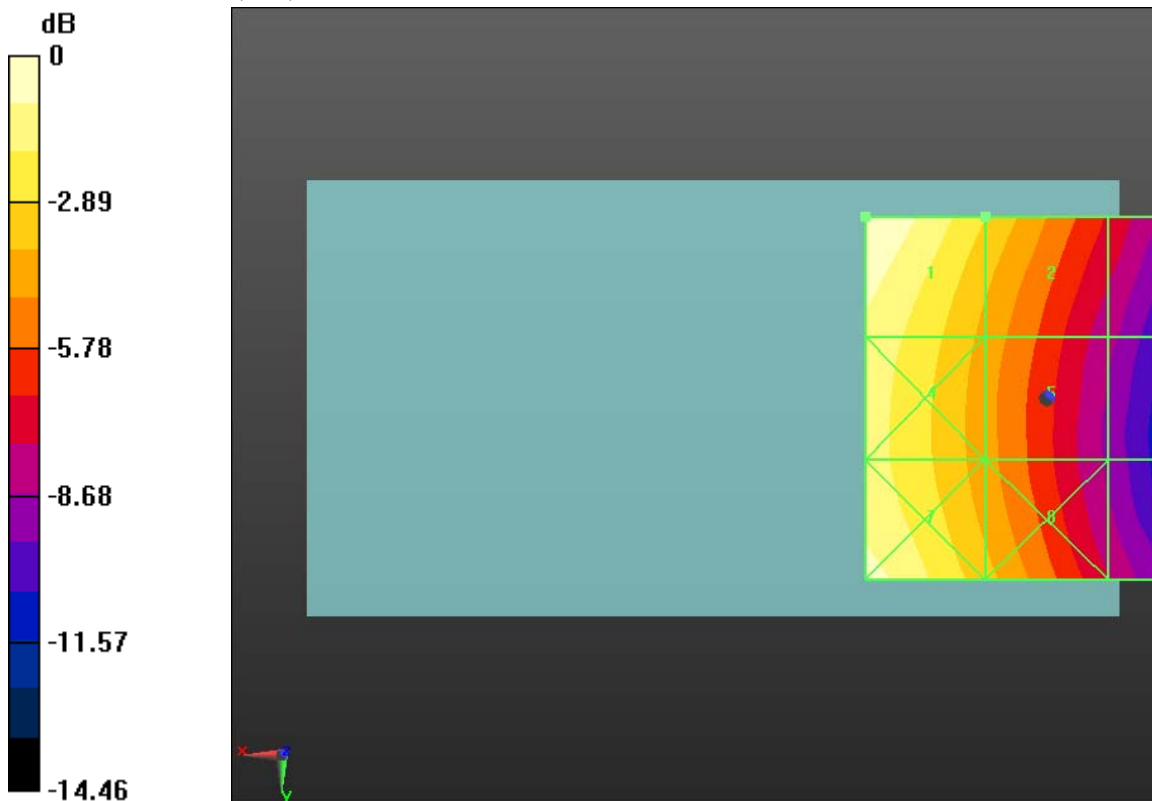
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Peak H-field in A/m


Grid 1 <b>0.102 M4</b>	Grid 2 <b>0.072 M4</b>	Grid 3 <b>0.045 M4</b>
Grid 4 <b>0.088 M4</b>	Grid 5 <b>0.062 M4</b>	Grid 6 <b>0.038 M4</b>
Grid 7 <b>0.094 M4</b>	Grid 8 <b>0.067 M4</b>	Grid 9 <b>0.041 M4</b>

**Cursor:**

Total = 0.102 A/m  
H Category: M4  
Location: 25, -25, 8.7 mm



0 dB = 0.100A/m

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Date/Time: 4/28/2011 8:16:52 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_UMTS\_band V\_mid\_chan**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD V; Frequency: 836.4 MHz; Communication System

PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.111 A/m

Probe Modulation Factor = 0.990

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.055 A/m; Power Drift = 0.06 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

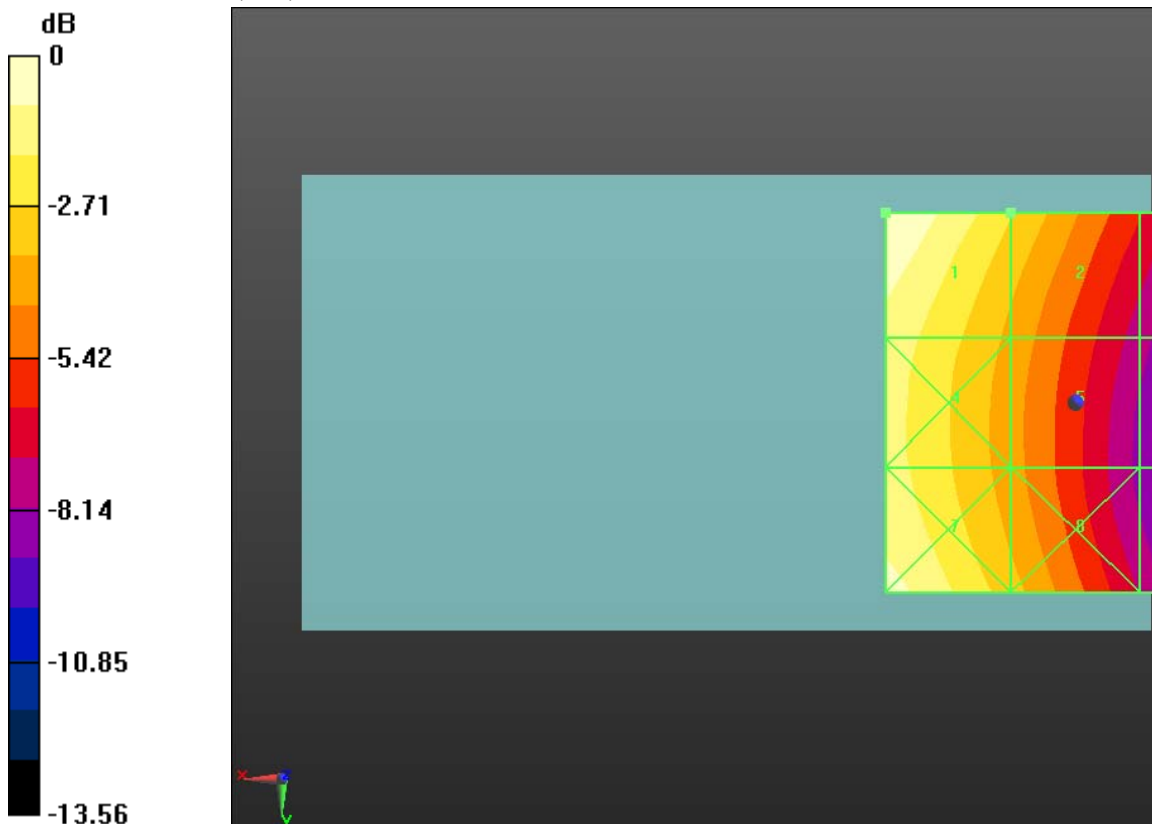
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Peak H-field in A/m


Grid 1 <b>0.111 M4</b>	Grid 2 <b>0.081 M4</b>	Grid 3 <b>0.054 M4</b>
Grid 4 <b>0.095 M4</b>	Grid 5 <b>0.071 M4</b>	Grid 6 <b>0.045 M4</b>
Grid 7 <b>0.104 M4</b>	Grid 8 <b>0.076 M4</b>	Grid 9 <b>0.048 M4</b>

**Cursor:**

Total = 0.111 A/m  
 H Category: M4  
 Location: 25, -25, 8.7 mm



0 dB = 0.110A/m

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Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_UMTS\_band V\_high\_chan**

**DUT: BlackBerry Smartphone; Type: Sample ;**

Communication System: WCDMA FDD V;.; Frequency: 846.6 MHz; Communication System  
PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.120 A/m


Probe Modulation Factor = 0.990

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.066 A/m; Power Drift = -0.07 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**



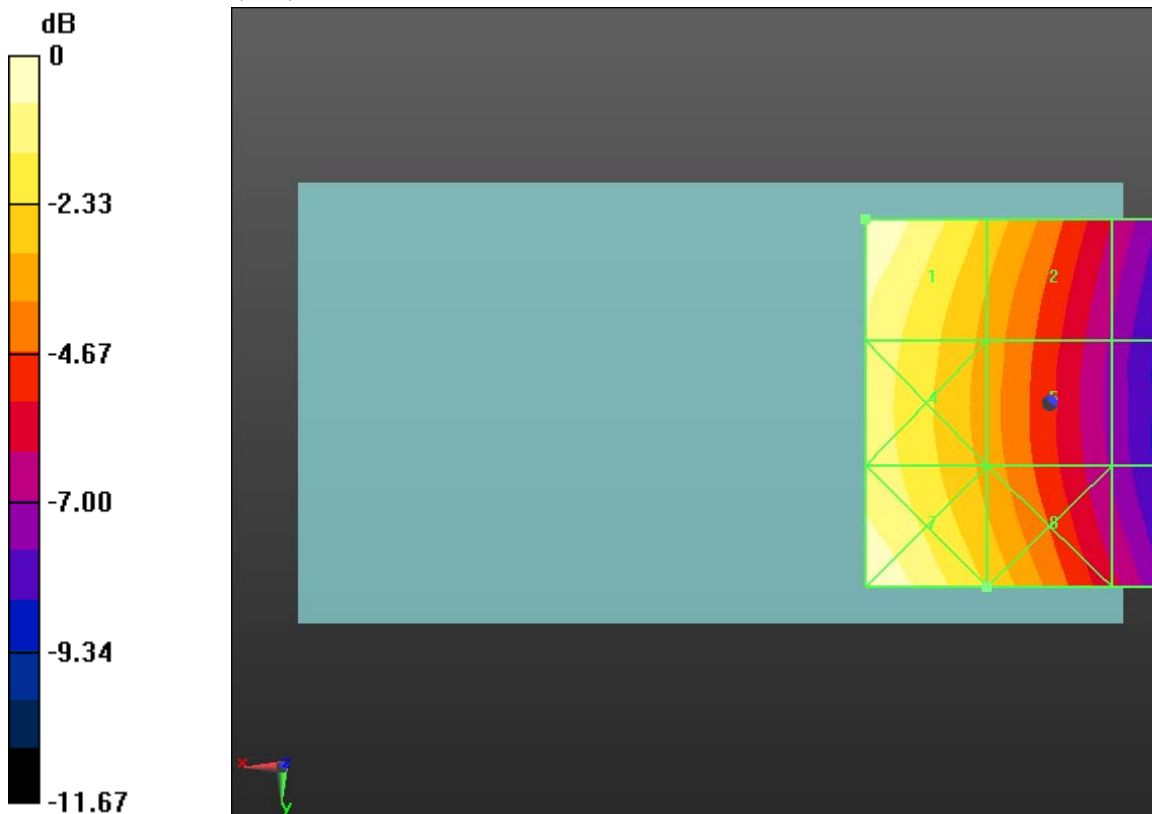
	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>177 (187)</b>
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Peak H-field in A/m


Grid 1 <b>0.120 M4</b>	Grid 2 <b>0.090 M4</b>	Grid 3 <b>0.059 M4</b>
Grid 4 <b>0.110 M4</b>	Grid 5 <b>0.081 M4</b>	Grid 6 <b>0.053 M4</b>
Grid 7 <b>0.120 M4</b>	Grid 8 <b>0.091 M4</b>	Grid 9 <b>0.061 M4</b>

**Cursor:**

Total = 0.120 A/m  
 H Category: M4  
 Location: 25, -25, 8.7 mm



0 dB = 0.120A/m

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Date/Time: 4/28/2011 8:26:50 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_UMTS\_band V\_high\_chan\_telecoil\_center**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD V; Frequency: 846.6 MHz; Communication System

PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.118 A/m

Probe Modulation Factor = 0.990

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.065 A/m; Power Drift = 0.10 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

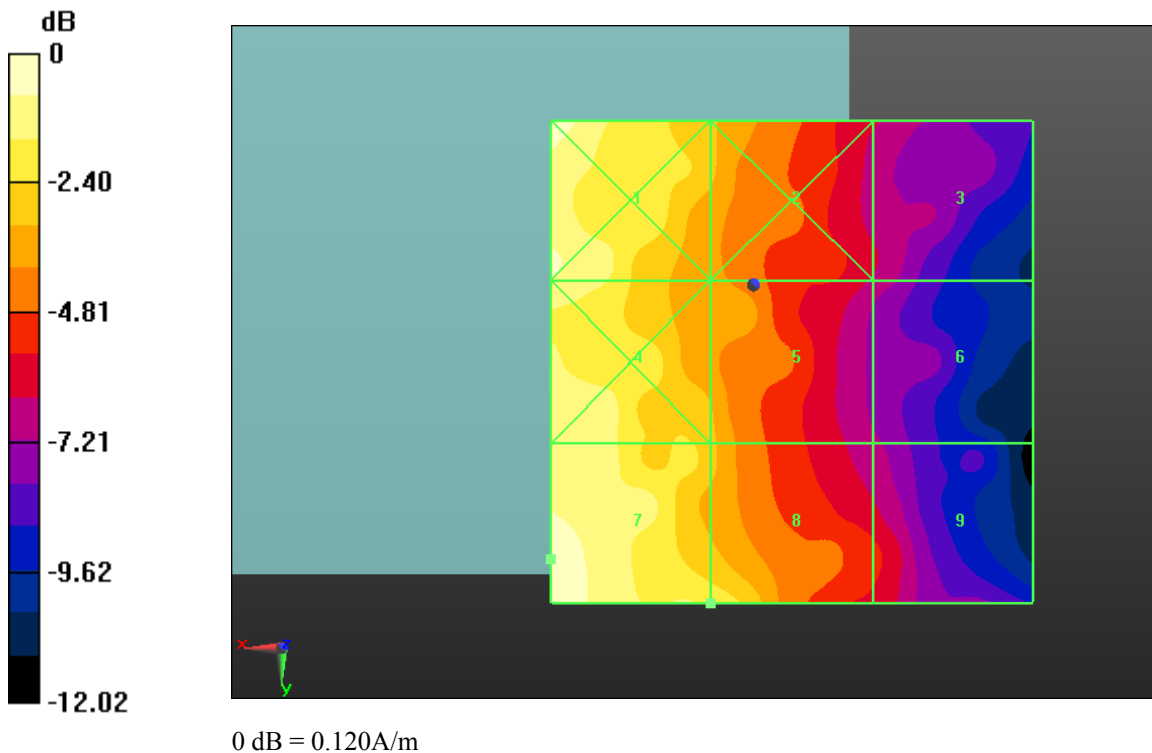
	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>179 (187)</b>
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Peak H-field in A/m

Grid 1 <b>0.118 M4</b>	Grid 2 <b>0.088 M4</b>	Grid 3 <b>0.056 M4</b>
Grid 4 <b>0.108 M4</b>	Grid 5 <b>0.081 M4</b>	Grid 6 <b>0.052 M4</b>
Grid 7 <b>0.108 M4</b>	Grid 8 <b>0.082 M4</b>	Grid 9 <b>0.053 M4</b>

**Cursor:**

Total = 0.118 A/m  
 H Category: M4  
 Location: 23, -31, 8.7 mm



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Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_UMTS\_band II\_low\_chan**

**DUT: BlackBerry Smartphone; Type: Sample ; S**

Communication System: WCDMA FDD II; ; Frequency: 1852.4 MHz; Communication System  
PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.080 A/m

Probe Modulation Factor = 1.120

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.068 A/m; Power Drift = 0.06 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

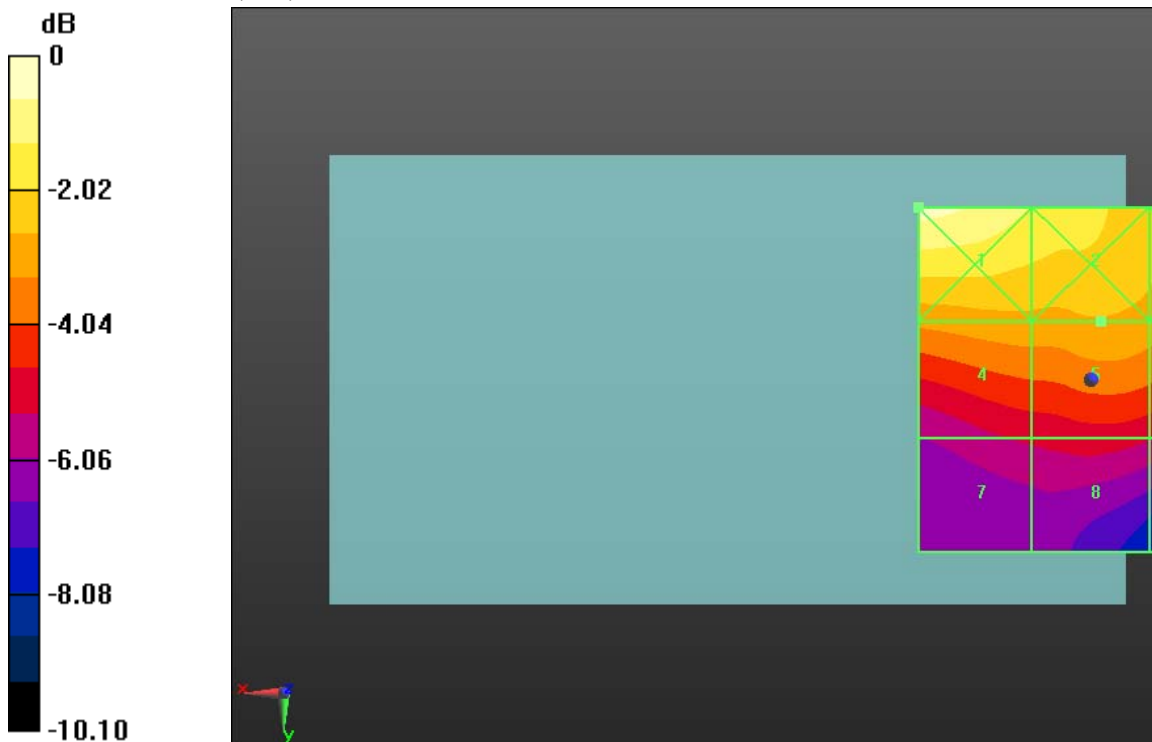
	Document <b>Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDU71CW/RDE71UW</b>		Page <b>181 (187)</b>
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Peak H-field in A/m


Grid 1 <b>0.105 M4</b>	Grid 2 <b>0.094 M4</b>	Grid 3 <b>0.082 M4</b>
Grid 4 <b>0.079 M4</b>	Grid 5 <b>0.080 M4</b>	Grid 6 <b>0.078 M4</b>
Grid 7 <b>0.060 M4</b>	Grid 8 <b>0.062 M4</b>	Grid 9 <b>0.060 M4</b>

**Cursor:**

Total = 0.105 A/m  
 H Category: M4  
 Location: 25, -25, 8.7 mm



0 dB = 0.110A/m

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Test Laboratory: RIM Testing Services

**HAC RF\_H-Field\_UMTS\_band II\_mid\_chan**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Communication System

PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASYS2, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

**Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):**

Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.088 A/m

Probe Modulation Factor = 1.120

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.076 A/m; Power Drift = 0.07 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

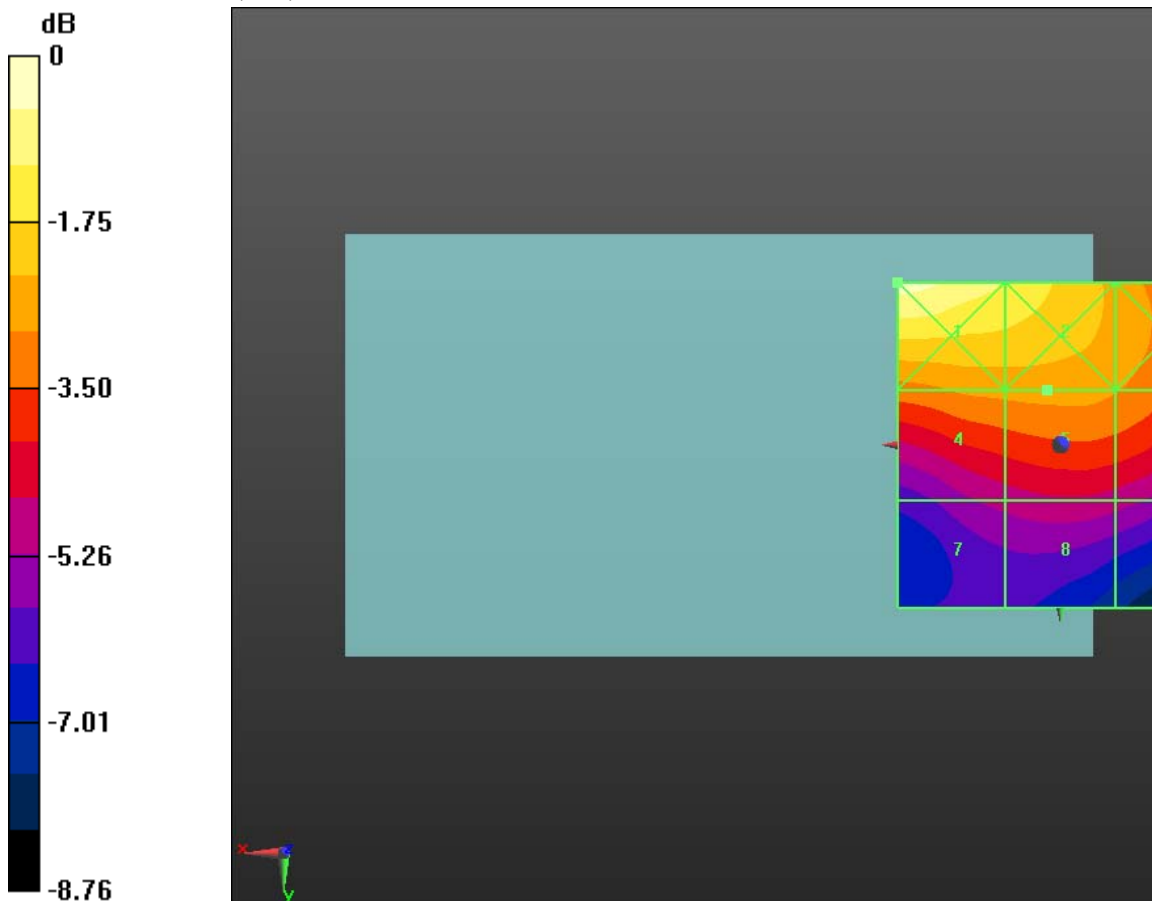
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Peak H-field in A/m


Grid 1 <b>0.116 M4</b>	Grid 2 <b>0.105 M4</b>	Grid 3 <b>0.090 M4</b>
Grid 4 <b>0.088 M4</b>	Grid 5 <b>0.088 M4</b>	Grid 6 <b>0.086 M4</b>
Grid 7 <b>0.068 M4</b>	Grid 8 <b>0.070 M4</b>	Grid 9 <b>0.068 M4</b>

**Cursor:**

Total = 0.116 A/m  
 H Category: M4  
 Location: 25, -25, 8.7 mm



0 dB = 0.120A/m

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Date/Time: 4/28/2011 7:55:02 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_UMTS\_band II\_high\_chan**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD II;; Frequency: 1907.6 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.091 A/m


Probe Modulation Factor = 1.120

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.079 A/m; Power Drift = 0.27 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**



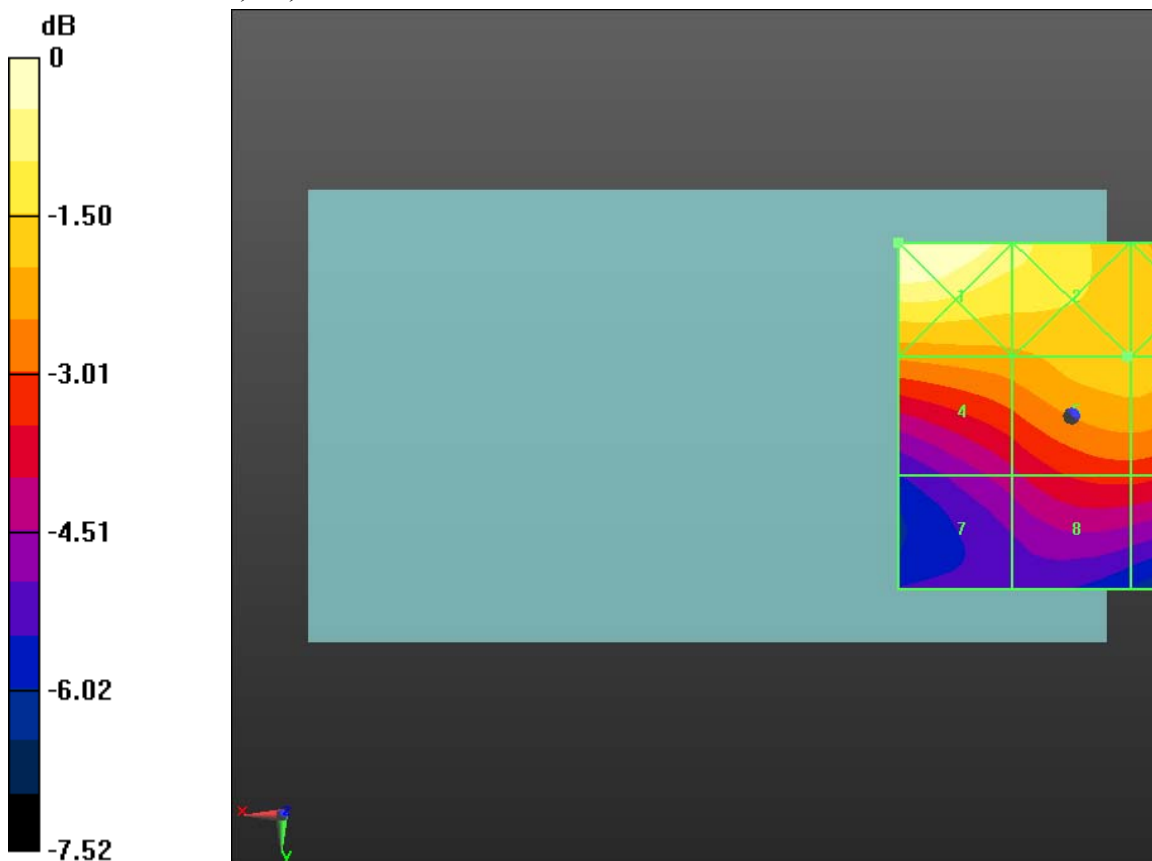
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Peak H-field in A/m


Grid 1 <b>0.115 M4</b>	Grid 2 <b>0.101 M4</b>	Grid 3 <b>0.092 M4</b>
Grid 4 <b>0.086 M4</b>	Grid 5 <b>0.091 M4</b>	Grid 6 <b>0.091 M4</b>
Grid 7 <b>0.068 M4</b>	Grid 8 <b>0.075 M4</b>	Grid 9 <b>0.075 M4</b>

**Cursor:**

Total = 0.115 A/m  
 H Category: M4  
 Location: 25, -25, 8.7 mm



0 dB = 0.110A/m

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Date/Time: 4/28/2011 8:31:37 PM

Test Laboratory: RIM Testing Services

### **HAC RF\_H-Field\_UMTS\_band II\_high\_chan\_telecoil\_center**

**DUT: BlackBerry Smartphone; Type: Sample**

Communication System: WCDMA FDD II; Frequency: 1907.6 MHz; Communication System PAR: 0 dB

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

### **Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test**

**(101x101x1):** Measurement grid: dx=5mm, dy=5mm


Maximum value of peak Total field = 0.093 A/m

Probe Modulation Factor = 1.120

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.079 A/m; Power Drift = 0.05 dB

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

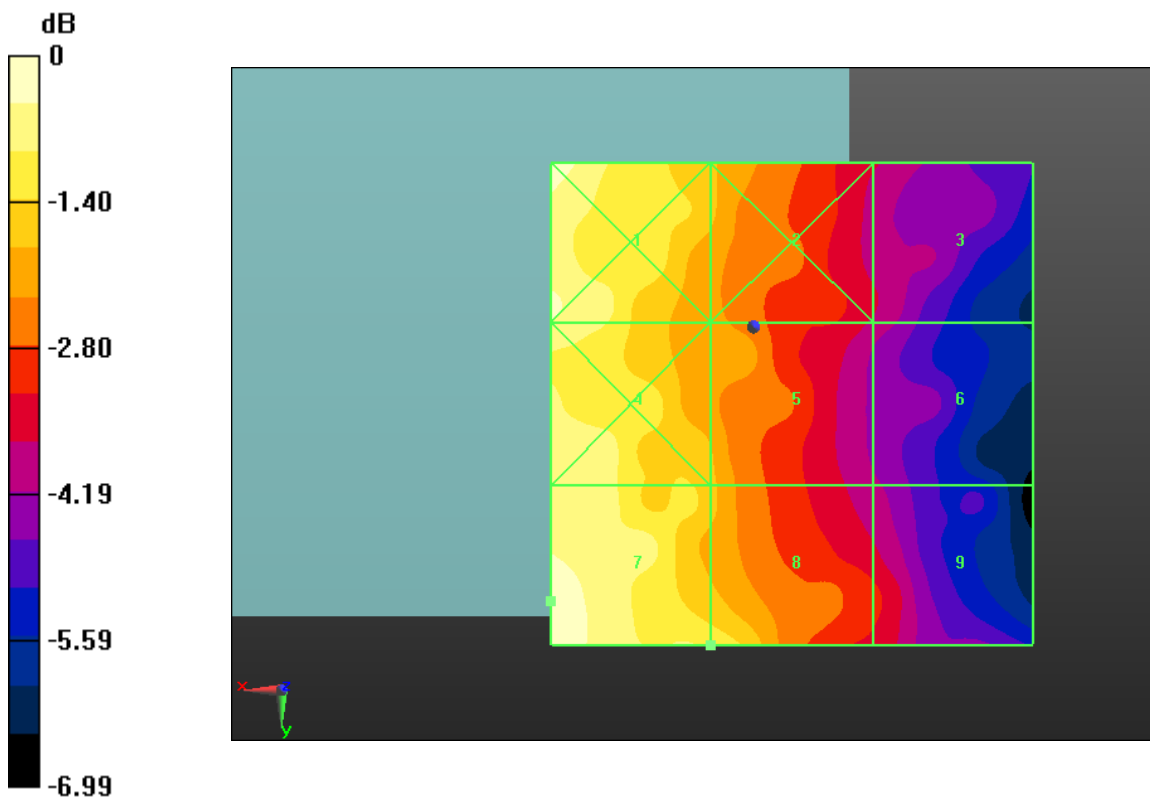
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Peak H-field in A/m

Grid 1 <b>0.122 M4</b>	Grid 2 <b>0.101 M4</b>	Grid 3 <b>0.089 M4</b>
Grid 4 <b>0.098 M4</b>	Grid 5 <b>0.093 M4</b>	Grid 6 <b>0.089 M4</b>
Grid 7 <b>0.076 M4</b>	Grid 8 <b>0.083 M4</b>	Grid 9 <b>0.082 M4</b>

**Cursor:**

Total = 0.122 A/m  
 H Category: M4  
 Location: 25, -33, 8.7 mm



0 dB = 0.120A/m